

Visualizing Electronic Structures of Quantum Materials

– By Angle Resolved Photoemission Spectroscopy (ARPES)

PART A: ARPES & Application

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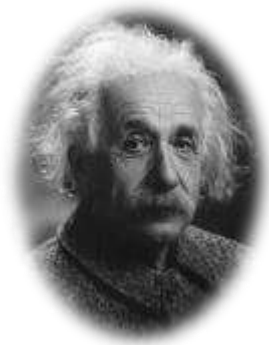


How to “see” band structures

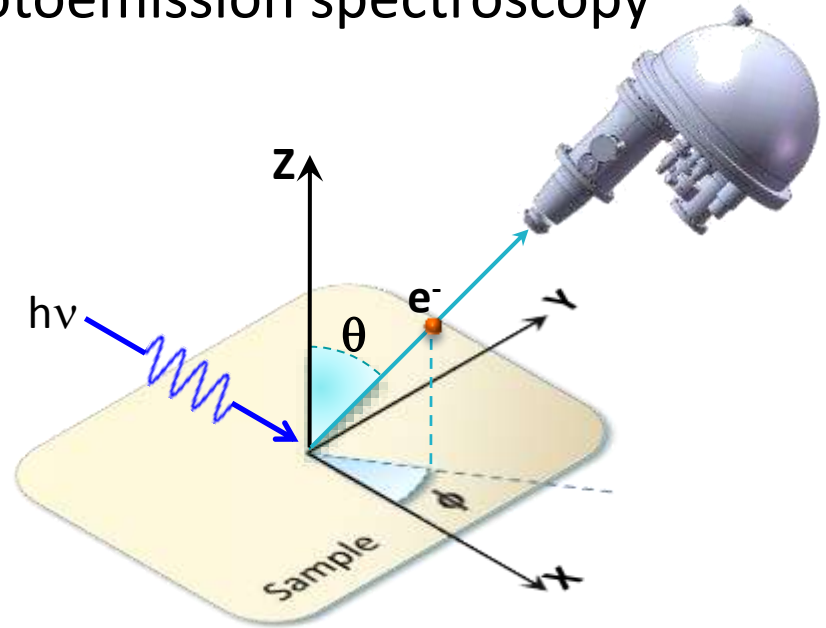
Basic principle of angle resolved photoemission spectroscopy



Heinrich Hertz



Albert Einstein



ARPES:
k-space Microscope

Energy Conservation

$$E_B = h\nu - E_{\text{kin}} - \Phi$$

Momentum Conservation

$$K_{\parallel} = k_{\parallel} + G_{\parallel}$$

Synchrotron Radiation

Synchrotrons around the world



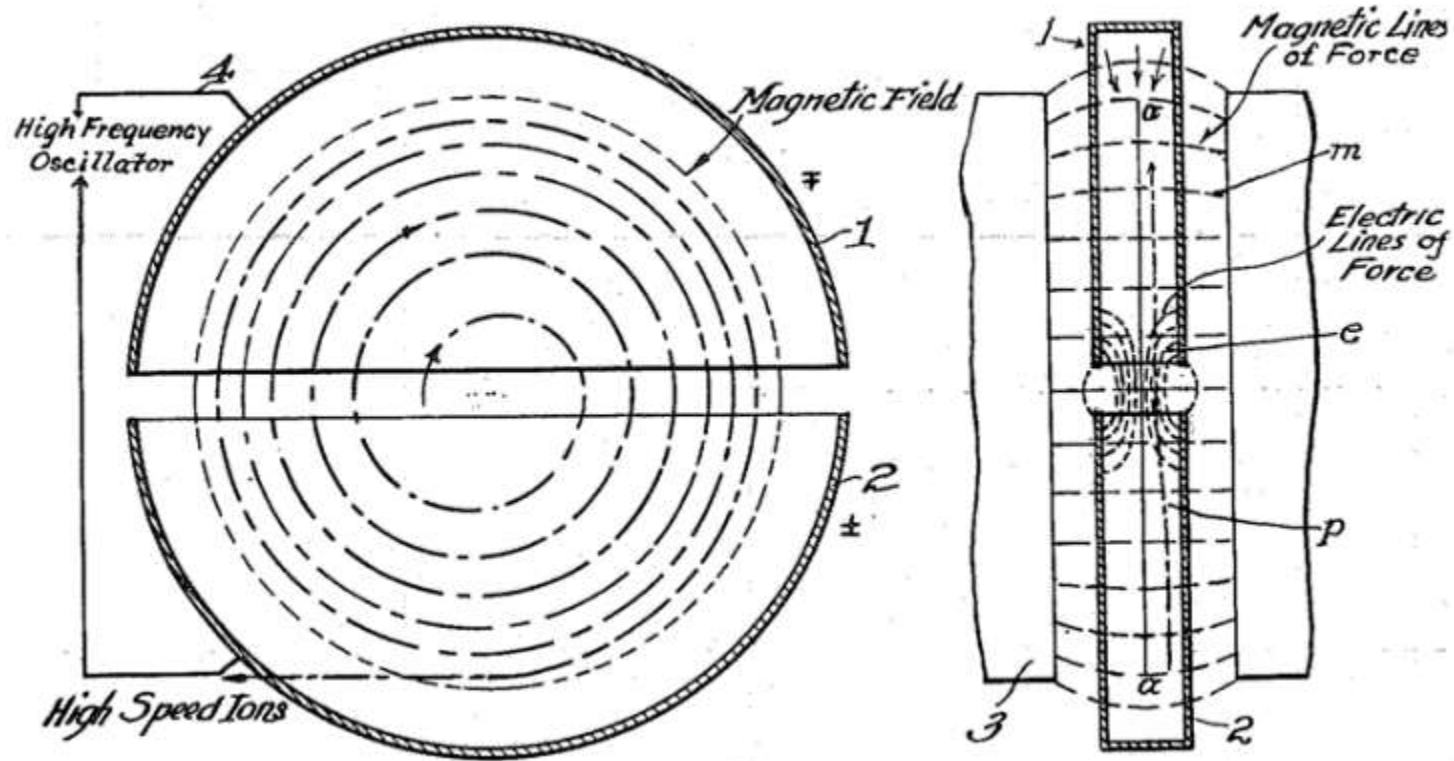
Synchrotron Radiation

Advantages

- ✓ **Broad Spectrum** (from microwaves to hard X-rays): the users can select the wavelength required for their experiment.
- ✓ **High Flux**: high intensity photon beam allows rapid experiments or use of weakly scattering crystals.
- ✓ **High Brilliance**: highly collimated photon beam generated by a small divergence and small size source (spatial coherence)
- ✓ **High Stability**: submicron source stability
- ✓ **Polarization**: both linear and circular
- ✓ **Pulsed Time Structure**: pulsed length down to tens of picoseconds allows the resolution of process on the same time scale.

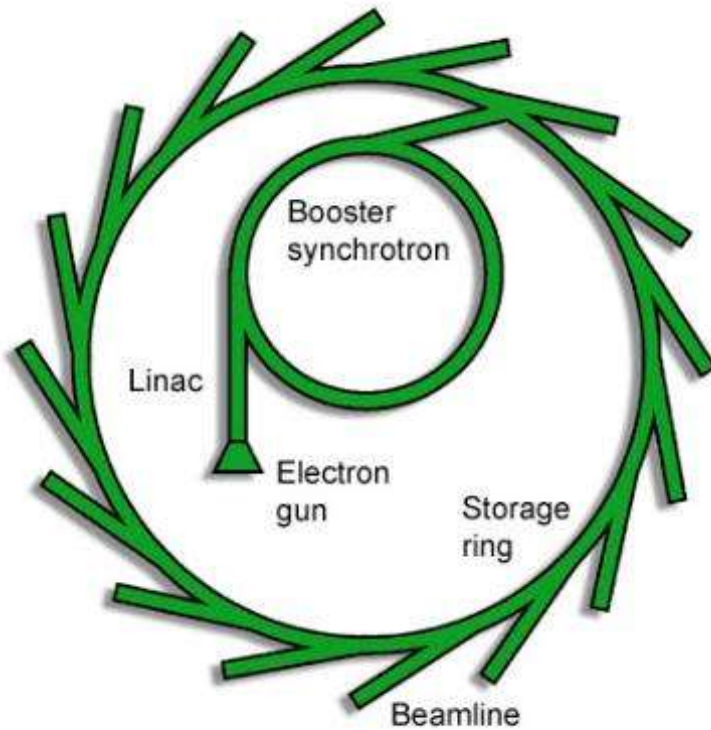
Synchrotron Radiation

Developments of the Cyclotron



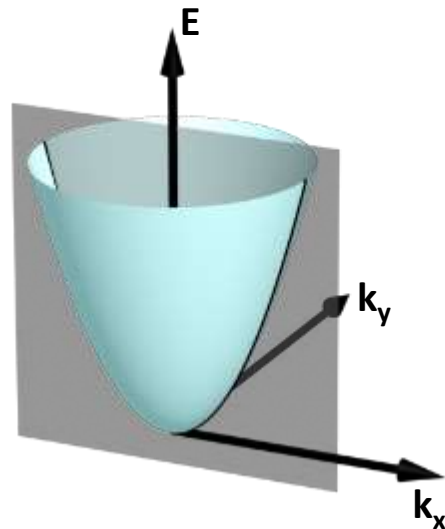
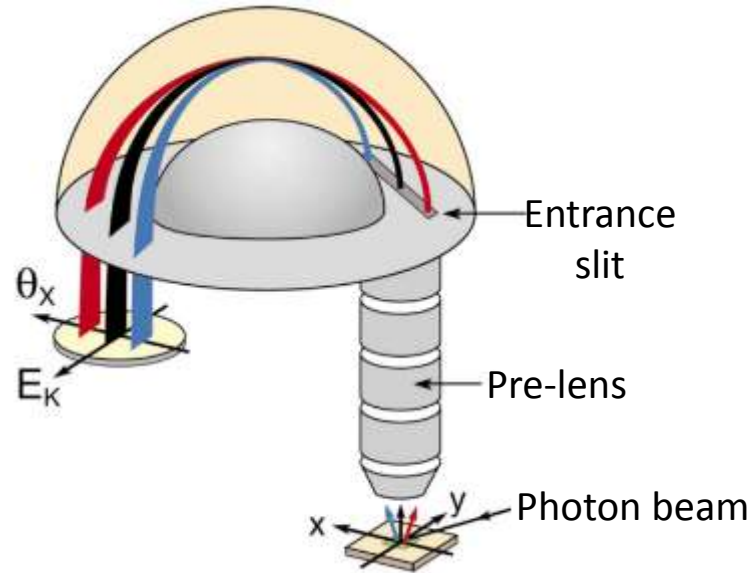
Synchrotron Radiation

Cartoon

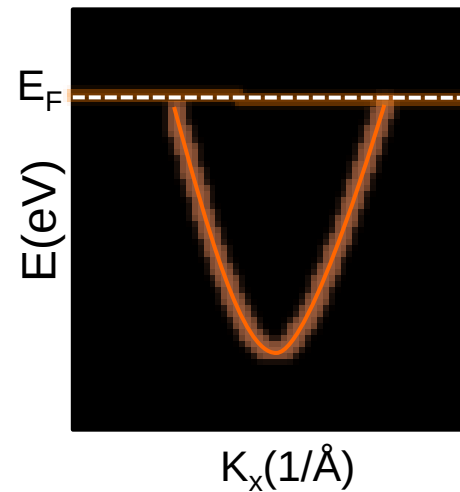


ARPES system

SDA Electron Analyzers

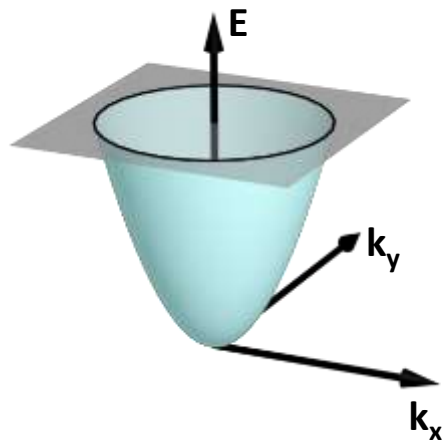
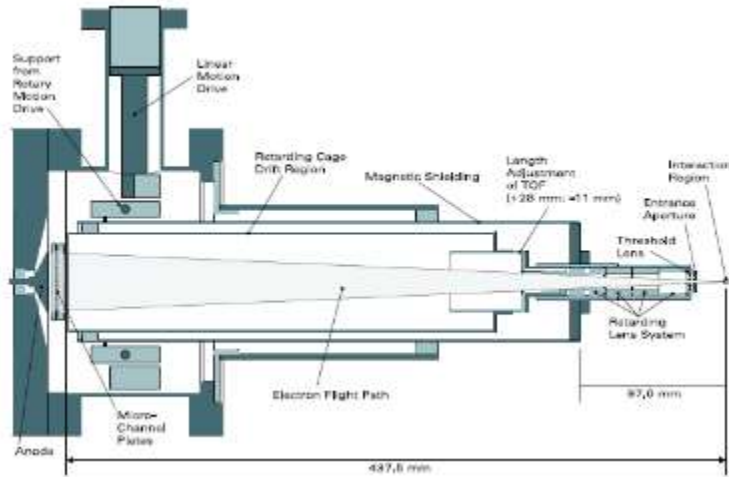


Band dispersion cut

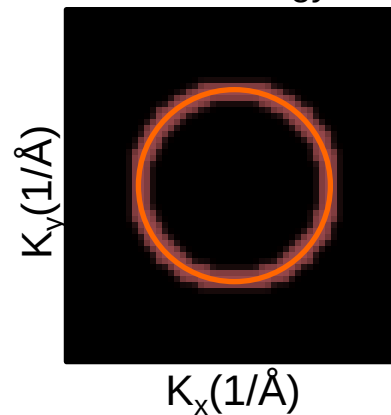


ARPES system

TOF electron Analyzers

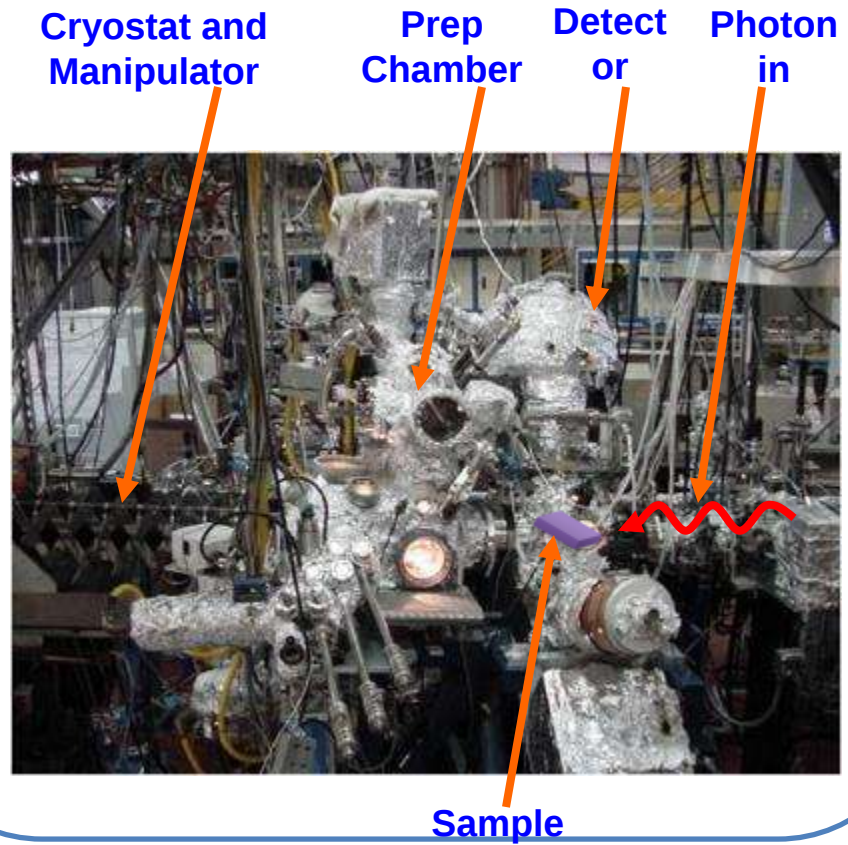


Constant energy cut



ARPES system

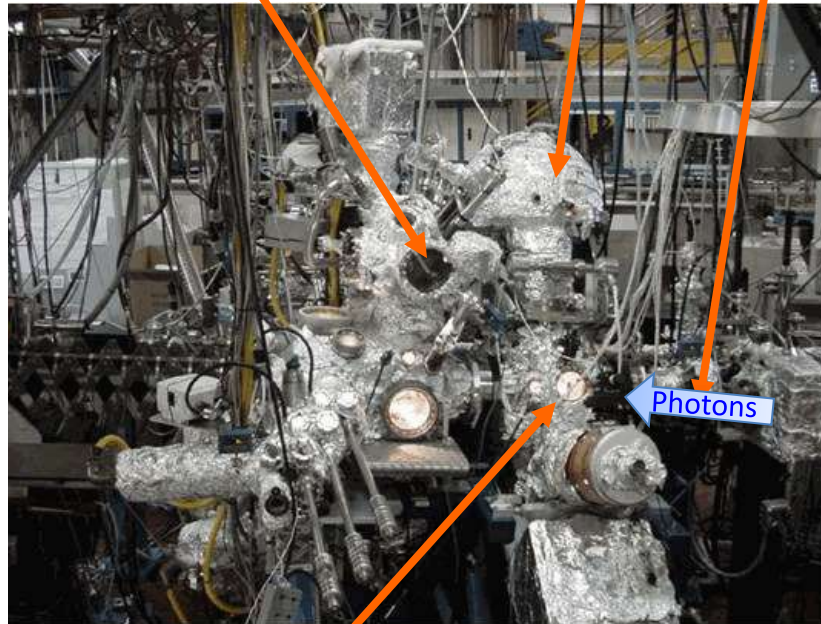
HERS endstation at ALS



Modern ARPES data taking

Experimental setup

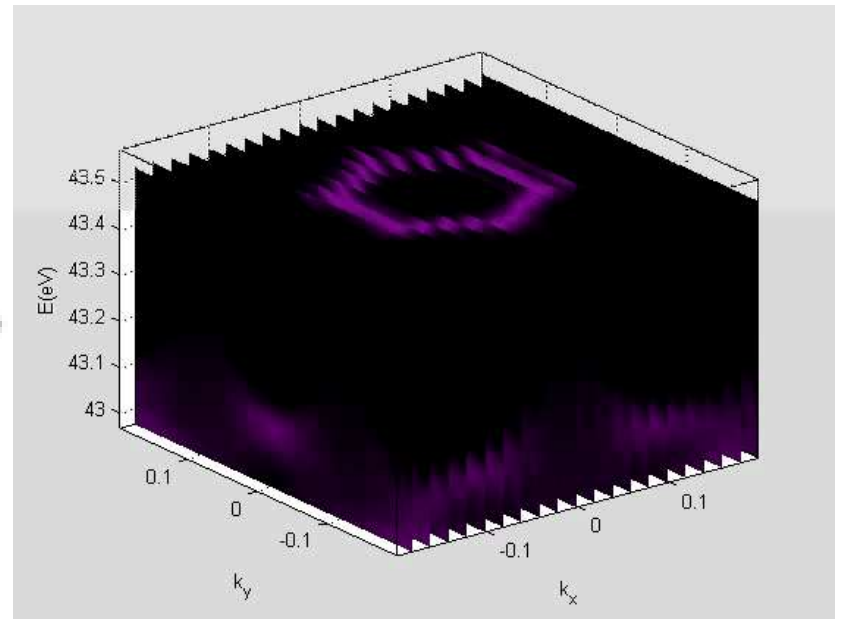
Experiment Chamber 2D Electron Photon analyzer in



ALS Beamline 10

Sample

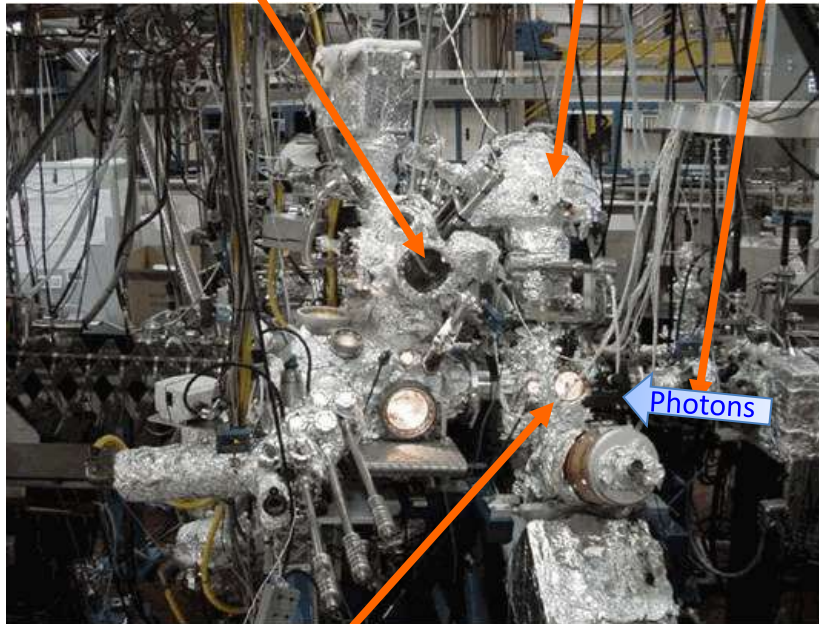
Data acquired



Modern ARPES data taking

Experimental setup

Experiment Chamber 2D Electron Photon analyzer in



ALS Beamline 10

Sample

Data acquired



Some of our works on TQMs



PHYSICAL
REVIEW

PHYSICAL
REVIEW

Frontiers of
Physics

ISSN 2553-0962
Volume 6 Number 1
December 2010

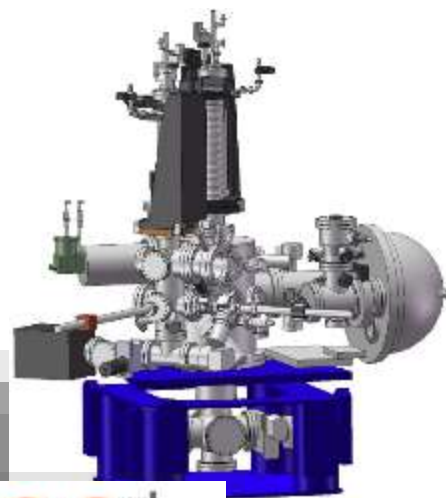
physica
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rrl
rapid research letters

1-2
2013

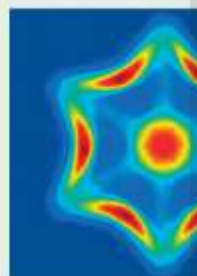
Focus Issue
Topological Insulators - Part I
Editors: Claudia Felser, Shou

Observing electronic structure
in a 2D green topological insulator
Min Han
S. H. Han, B. Zhou, M. H. Lu,
Z. K. Liu, Y. B. Chen, J. G. Analytis,
C. Selim, W. H. Duan, S. K. Mo,
Z. S. Mao, L. H. Puhos,
L. W. Madsen, B. J. Peng,
S. Saito, and T. L. Chen

WILEY-VCH



Me

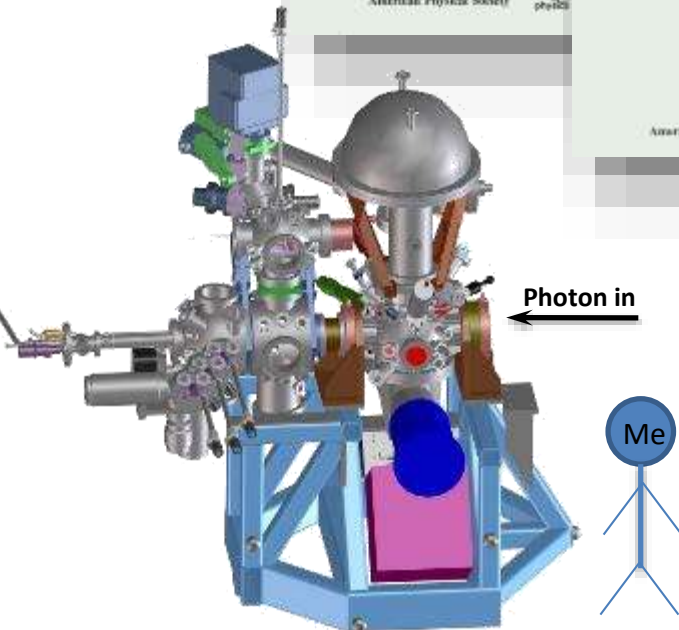


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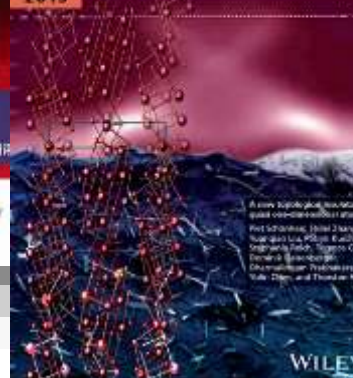


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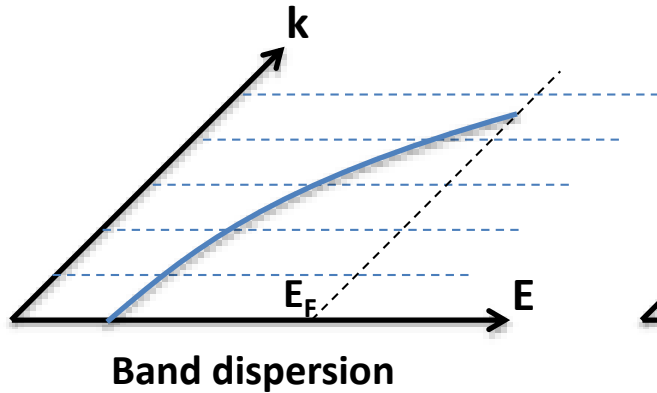
2
2015



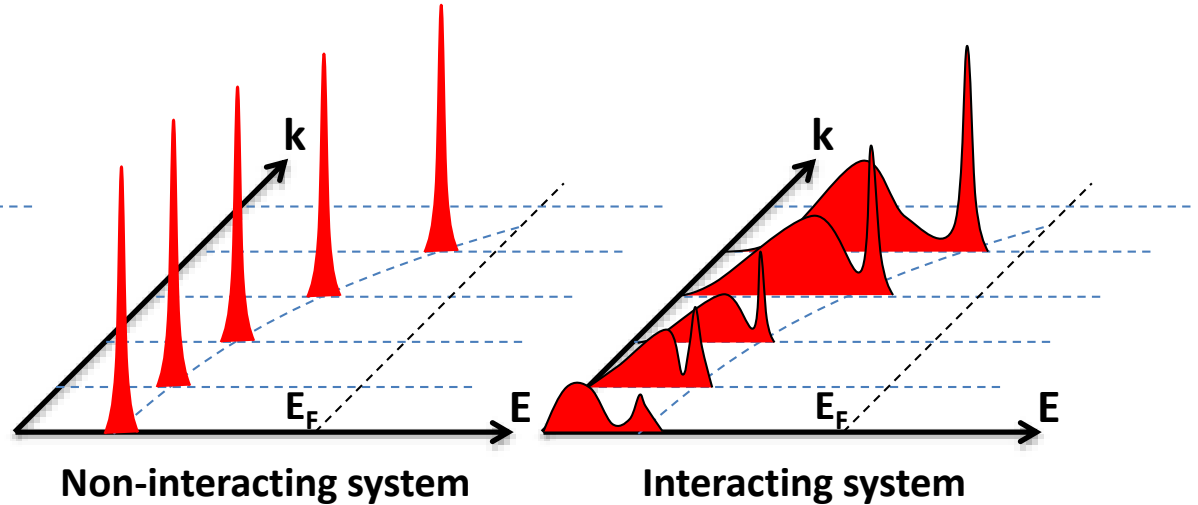
WILEY-VCH

General principle

Electron band



ARPES Spectra



$$I_{PES} \propto F_{(T)} \cdot \delta_{(E_f - E_i - \hbar\omega)} \cdot |\langle \psi_{f,N} | H_{int} | \psi_{i,N} \rangle|^2 +$$

$$\begin{aligned} |\psi_{i,N}\rangle &= |\phi_{i,k}\rangle |\psi_{i^{k(N-1)}}\rangle \\ |\psi_{f,N}\rangle &= |\phi_{f,E_k}\rangle |\psi_{f^{k(N-1)}}\rangle \end{aligned}$$

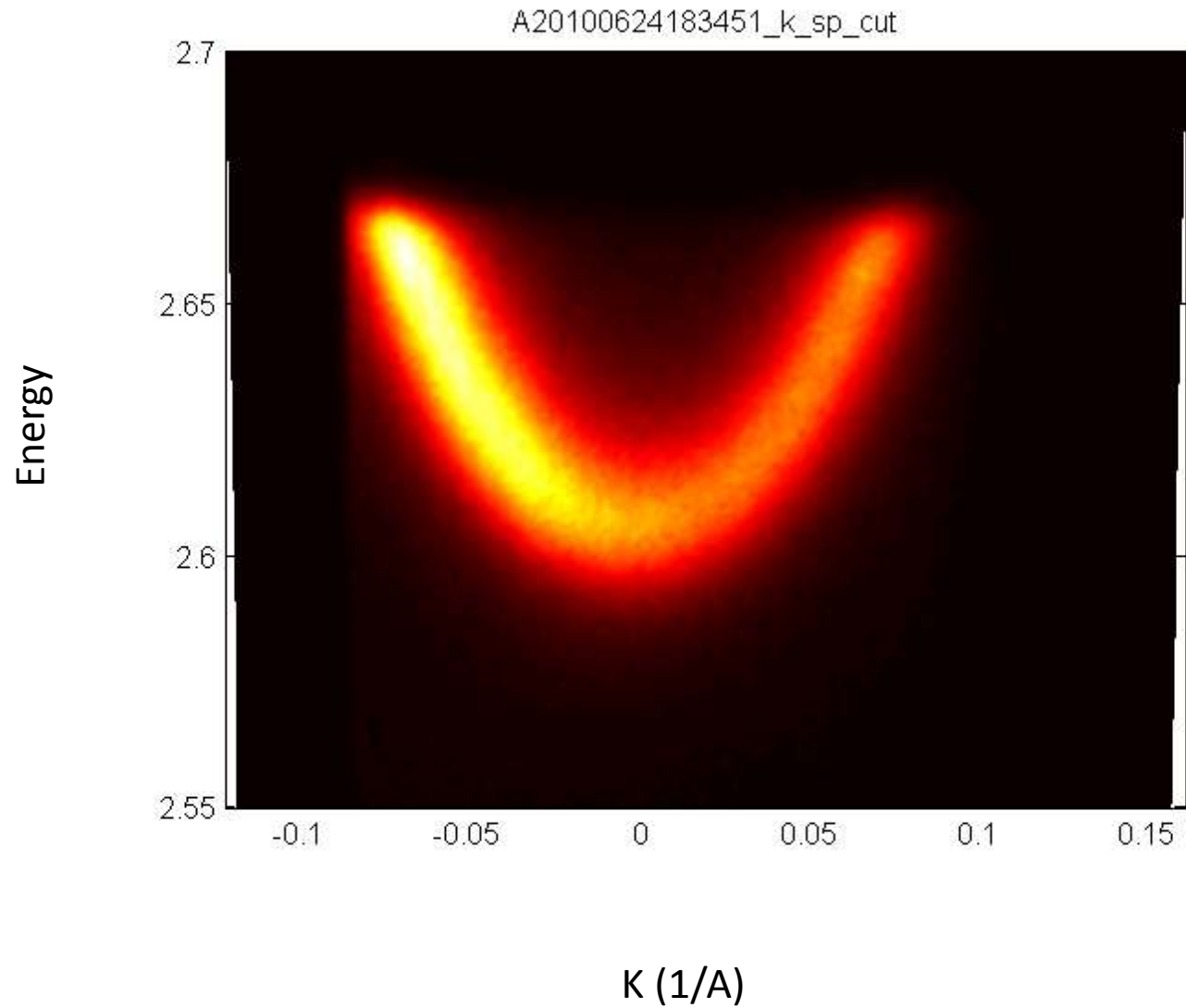
Remaining N-1 Electron state

One electron state

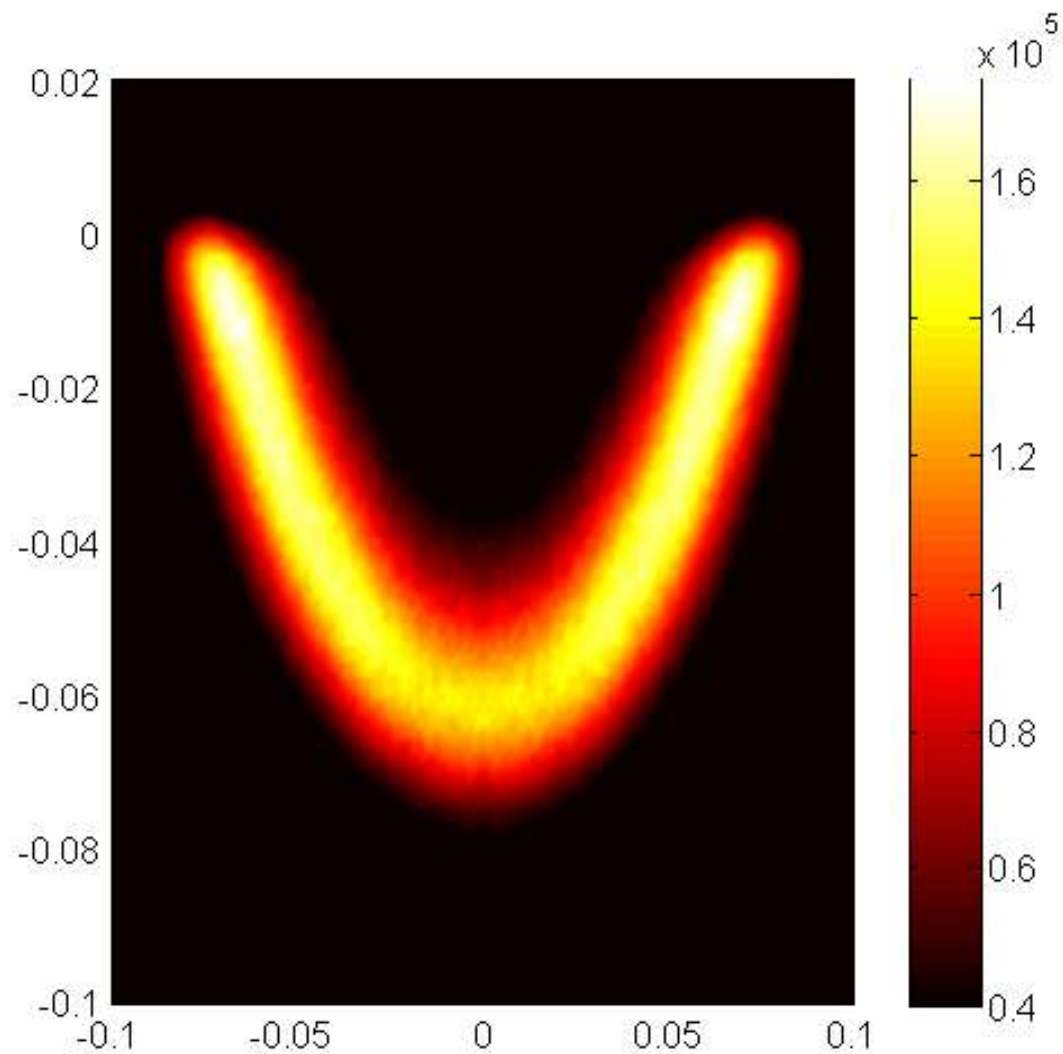
$$= F_{(T)} \cdot \delta_{(E_f - E_i - \hbar\omega)} \cdot |\langle \phi_{f,E_k} | H_{int} | \phi_{i,k} \rangle \langle \psi_{f^{k(N-1)}} | \psi_{i^{k(N-1)}} \rangle|^2 + (\text{Sudden approximation})$$

$$= \begin{cases} F_{(T)} \cdot \delta_{(E_f - E_i - \hbar\omega)} \cdot |\langle \phi_{f,E_k} | H_{int} | \phi_{i,k} \rangle|^2 & (\text{Non-interacting system}) \\ F_{(T)} \cdot |\langle \phi_{f,E_k} | H_{int} | \phi_{i,k} \rangle|^2 \sum_S |\langle \psi_{f^{kS(N-1)}} | \psi_{i^{k(N-1)}} \rangle|^2 \delta_{(E_{f,E_k} + E_{S(N-1)} - E_i - \hbar\omega)} & \end{cases}$$

ARPES observation

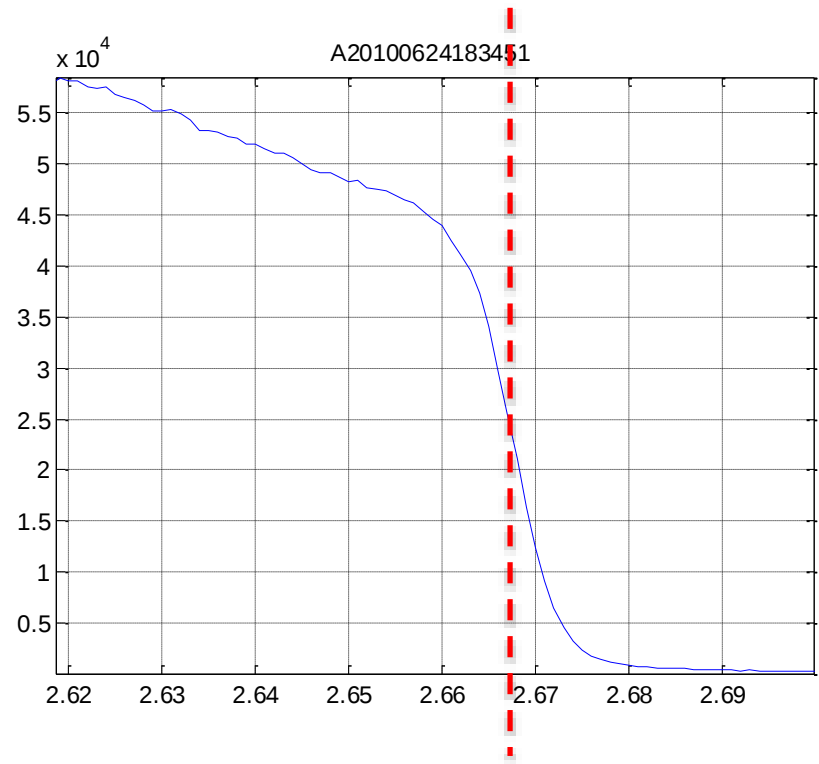
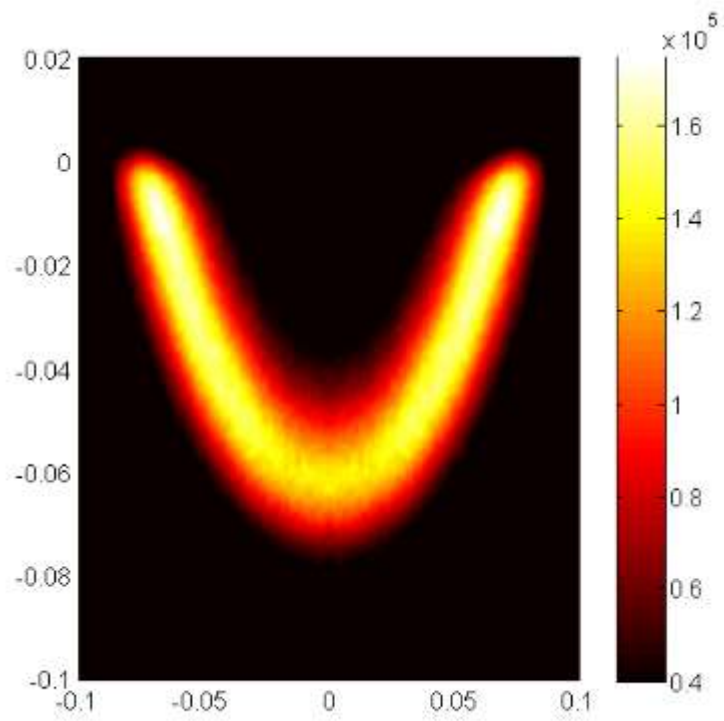


ARPES observation



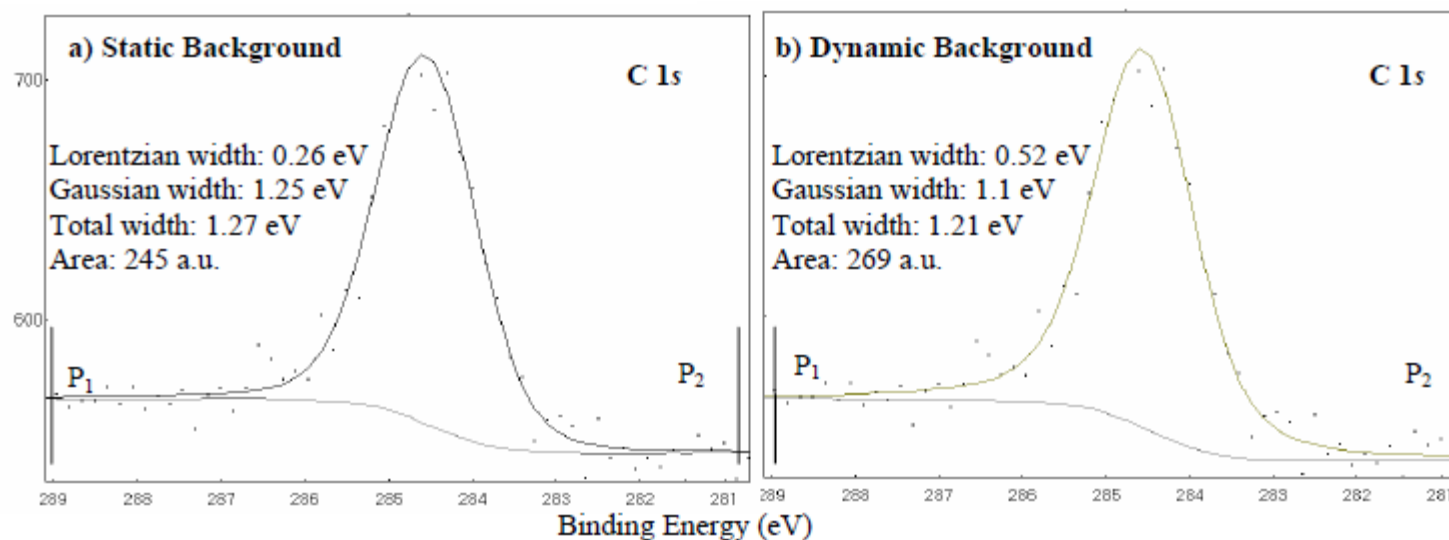
ARPES observation

E_F location



ARPES observation

Background subtraction



$$B_1(E) = k_1 \int_E^{E_{\text{right}}} dE' [I(E') - I_{\text{right}}],$$

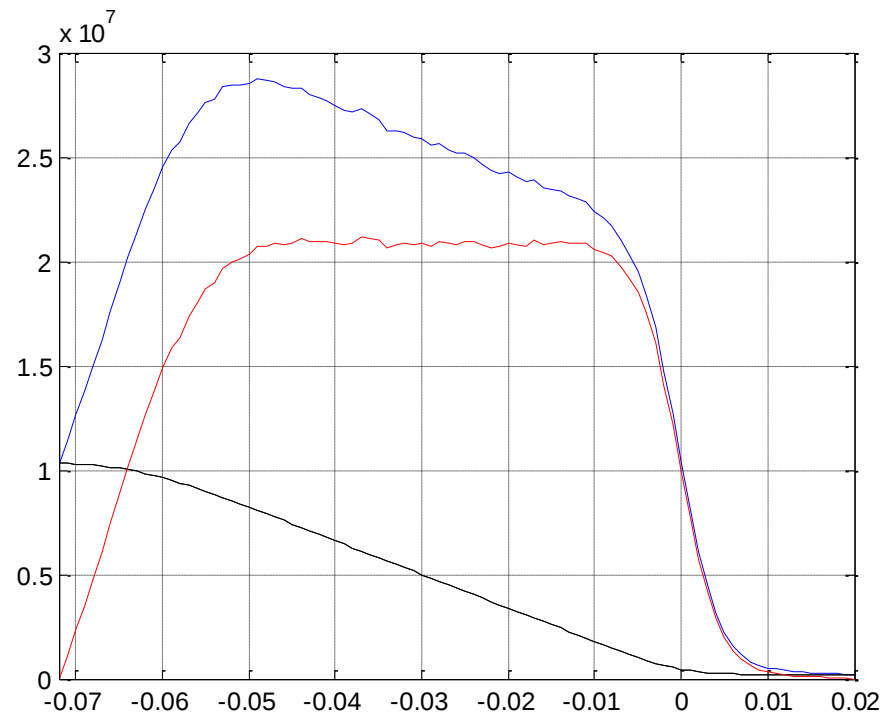
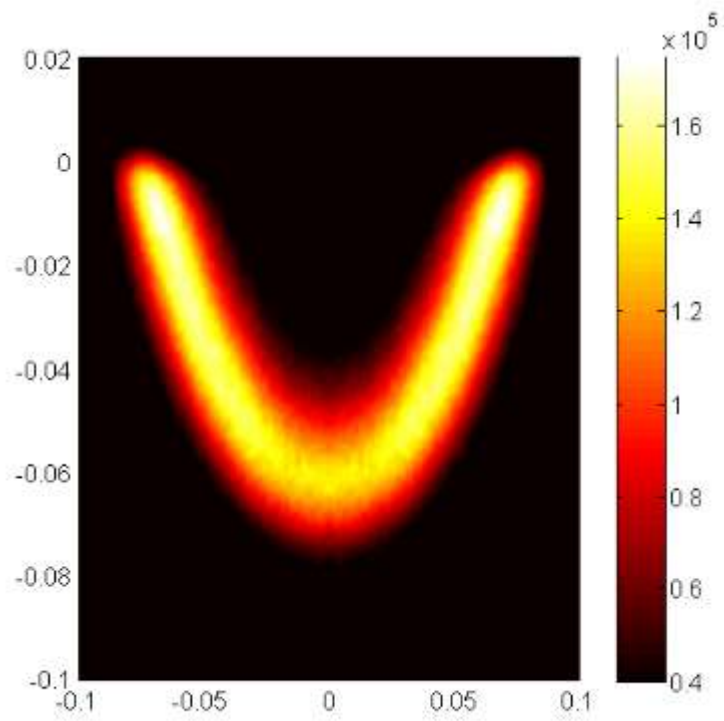
$$B_2(E) = k_2 \int_E^{E_{\text{right}}} dE' [I(E') - I_{\text{right}} - B_1(E')],$$

...

$$B_n(E) = k_n \int_E^{E_{\text{right}}} dE' [I(E') - I_{\text{right}} - B_{n-1}(E')],$$

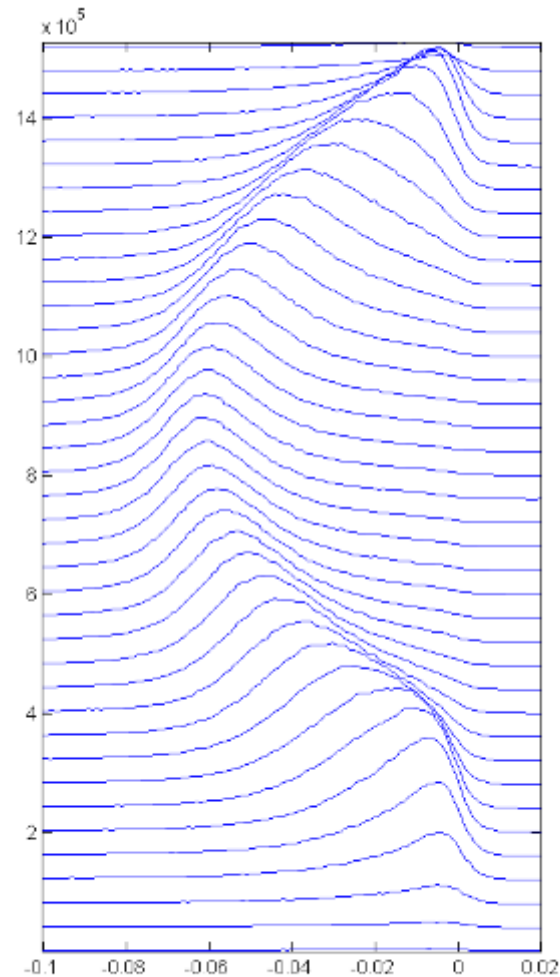
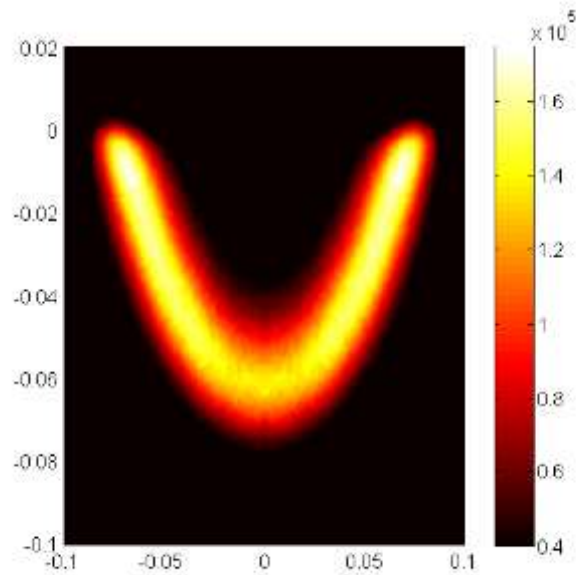
ARPES observation

Background subtraction



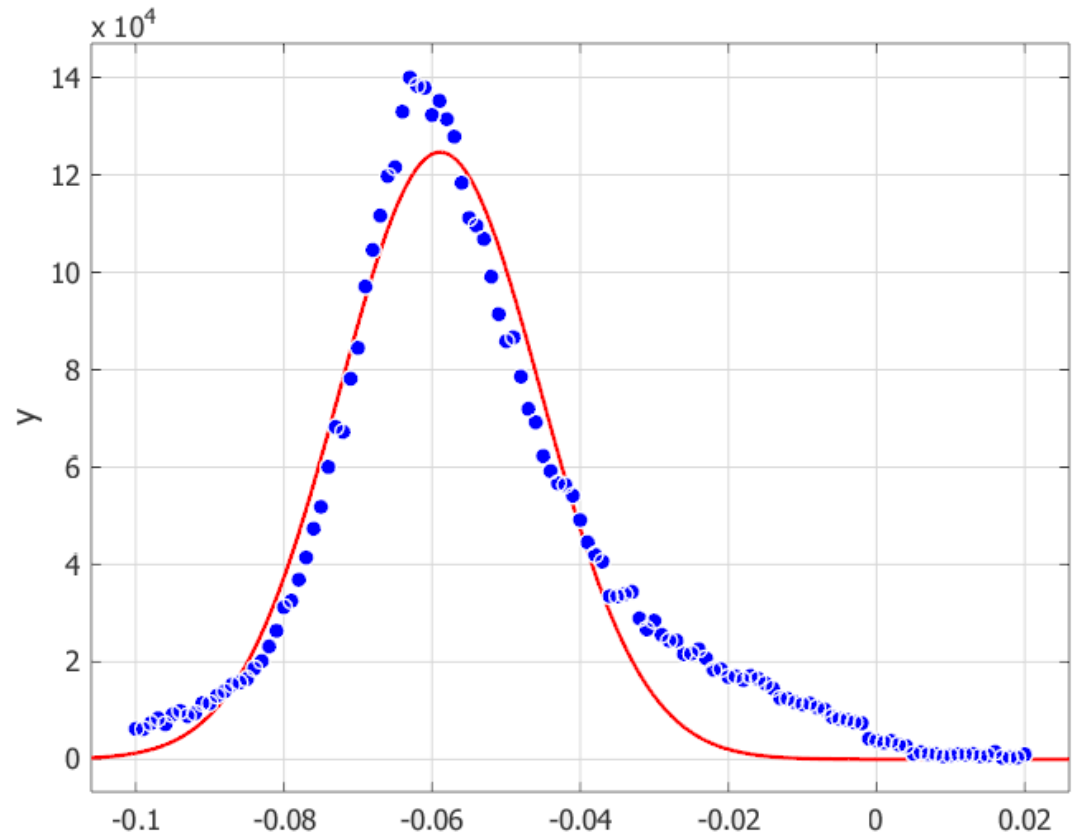
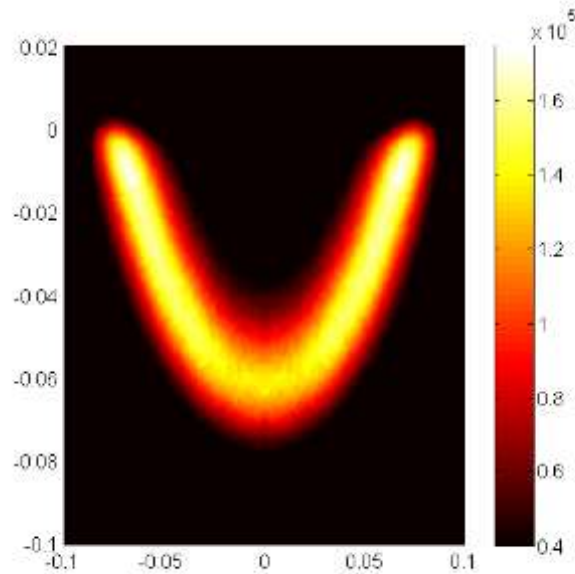
ARPES observation

Energy distribution curves



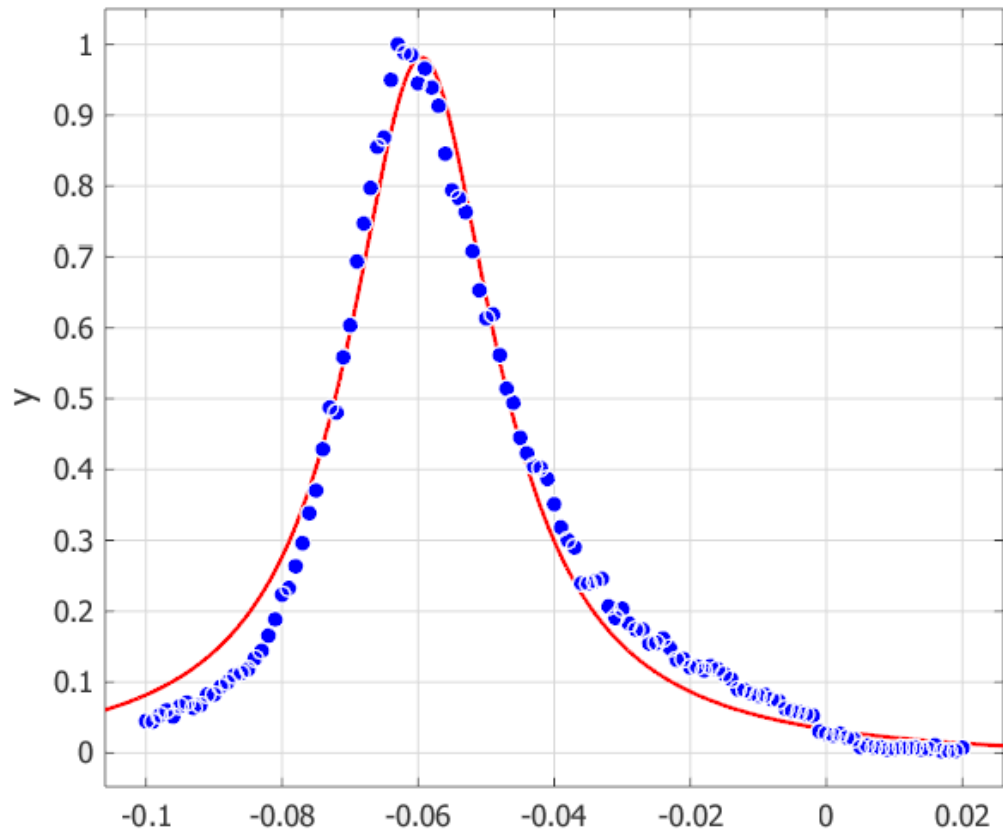
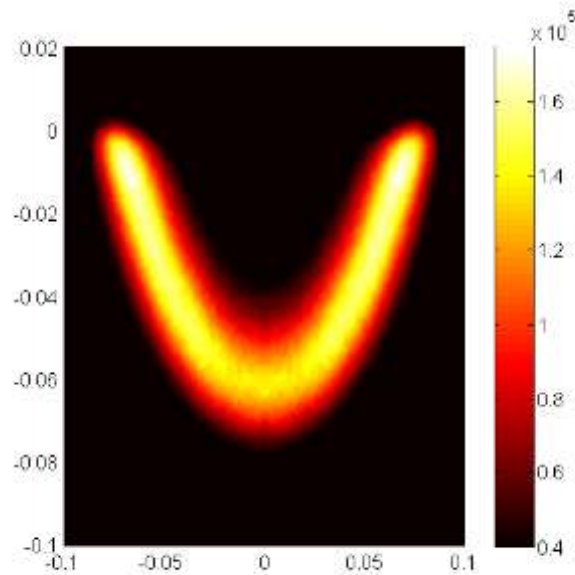
ARPES observation

Energy distribution curves



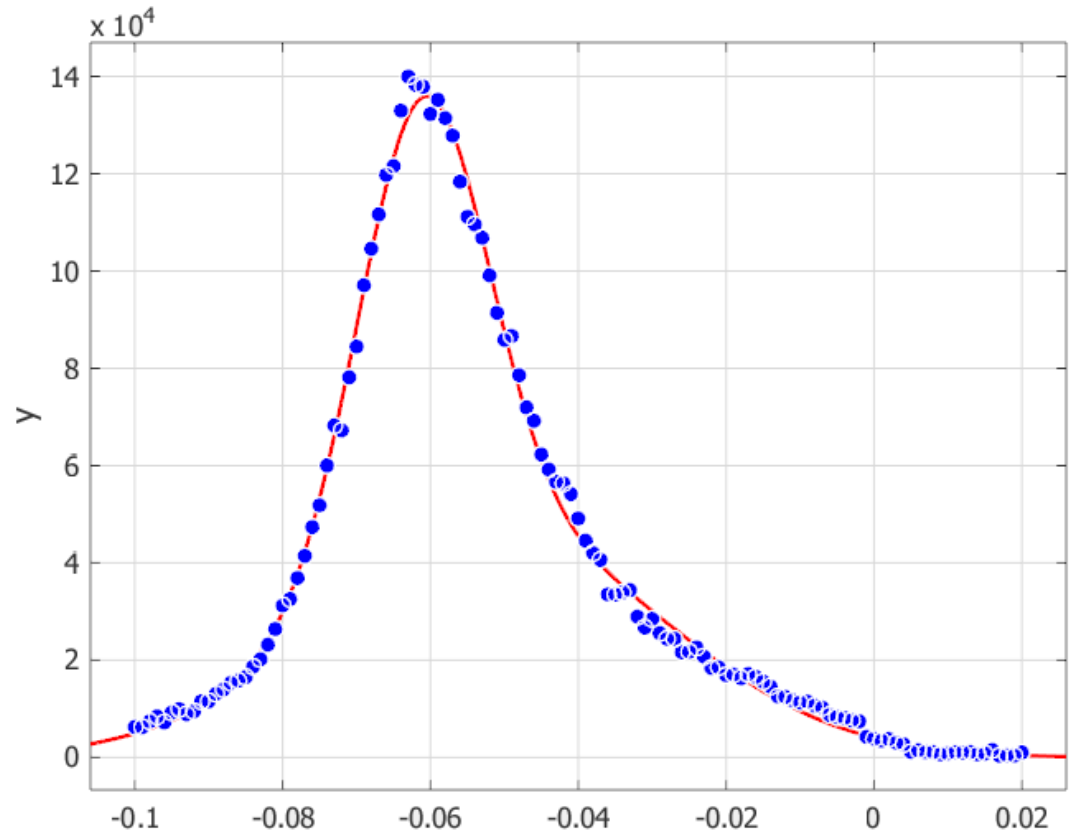
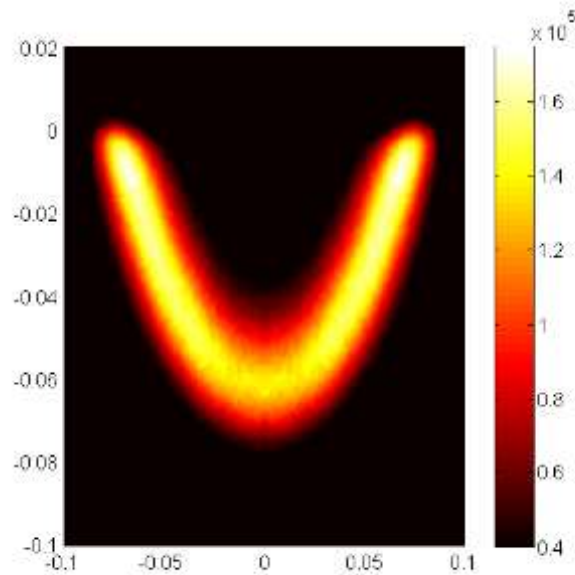
ARPES observation

Energy distribution curves



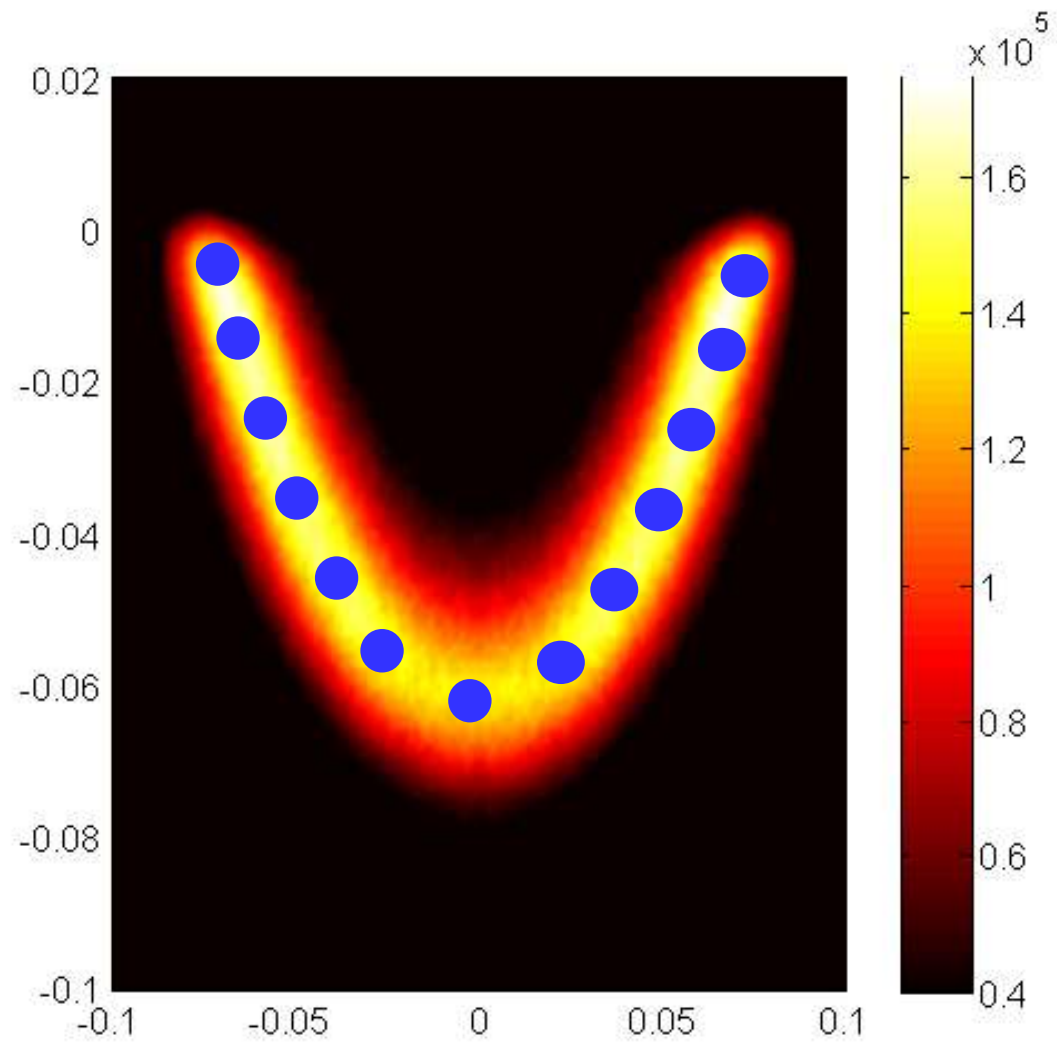
ARPES observation

Energy distribution curves



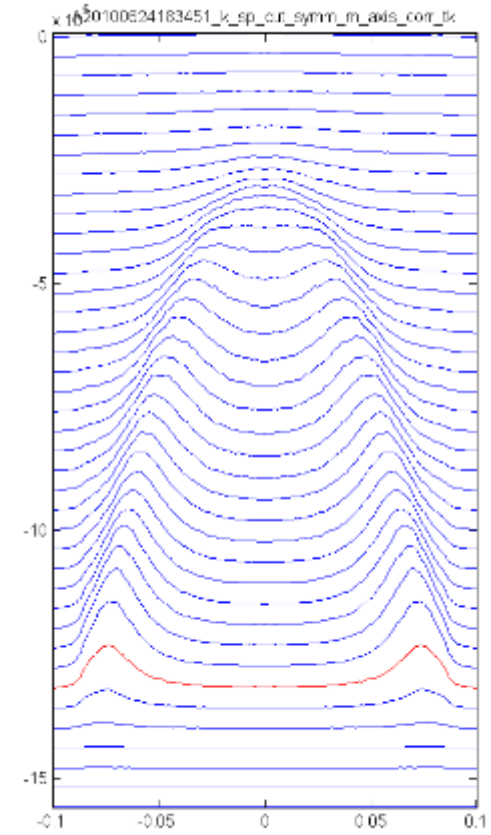
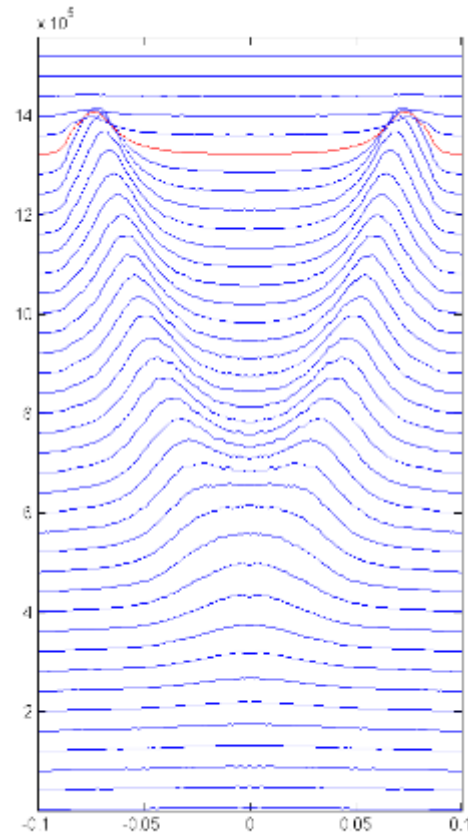
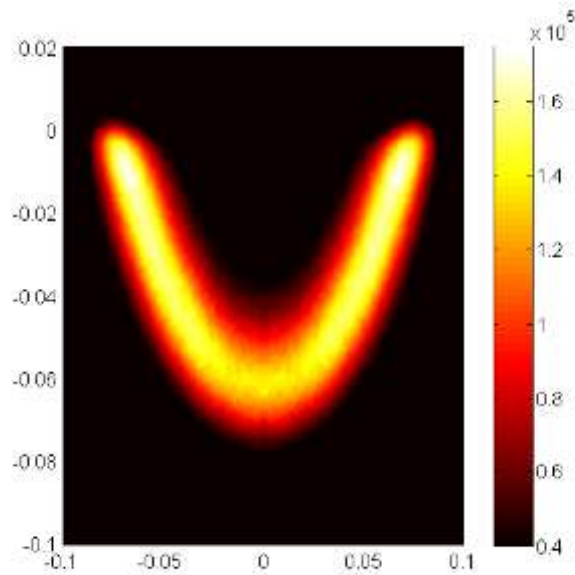
Line shape analysis

EDC



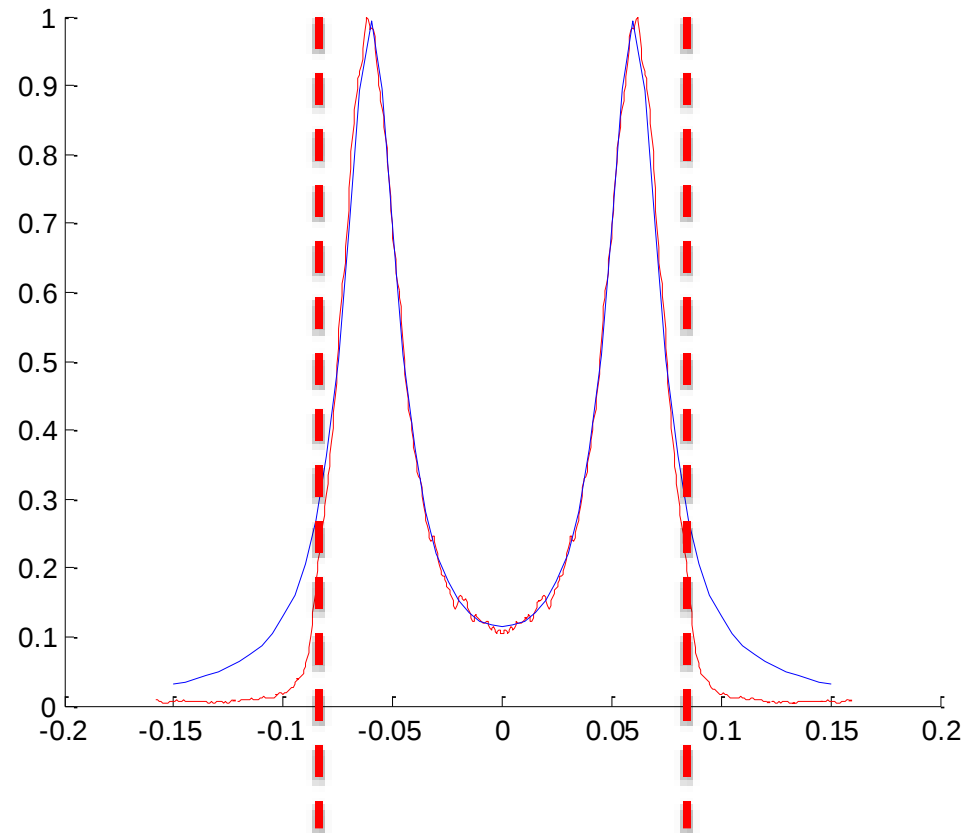
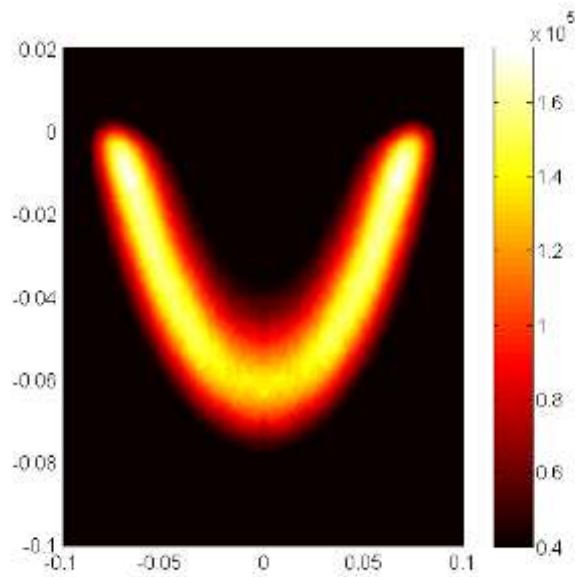
ARPES observation

Momentum distribution curves



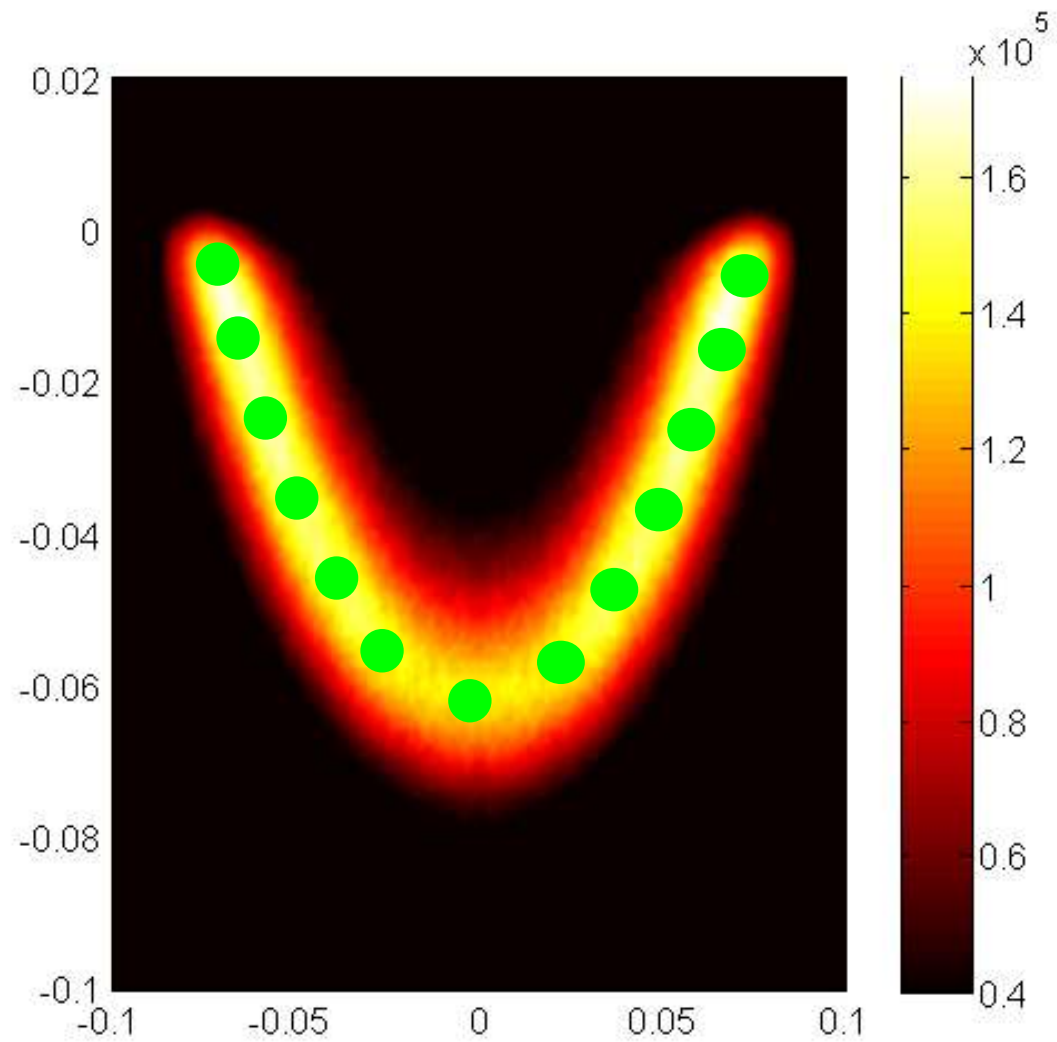
ARPES observation

Momentum distribution curves



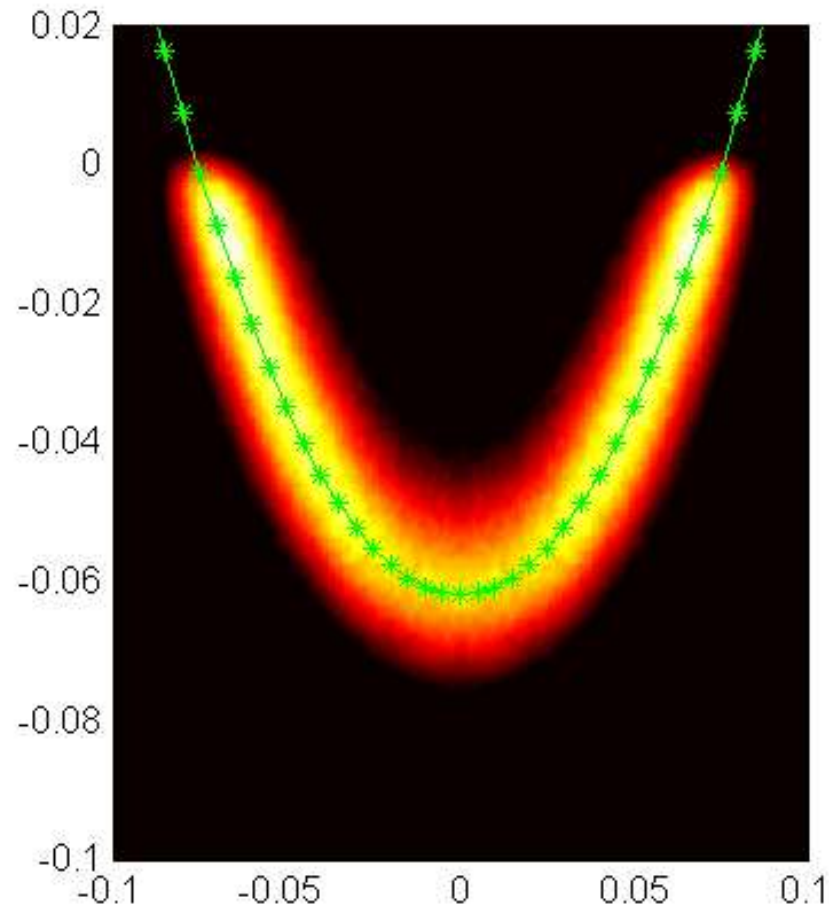
Line shape analysis

EDC



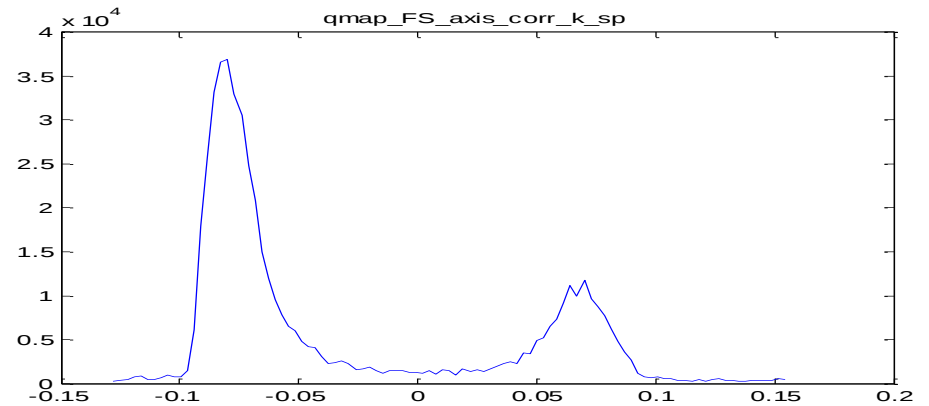
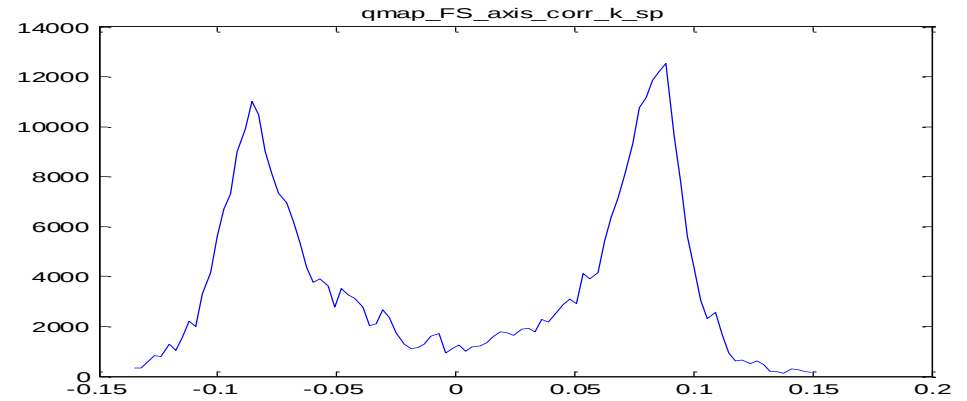
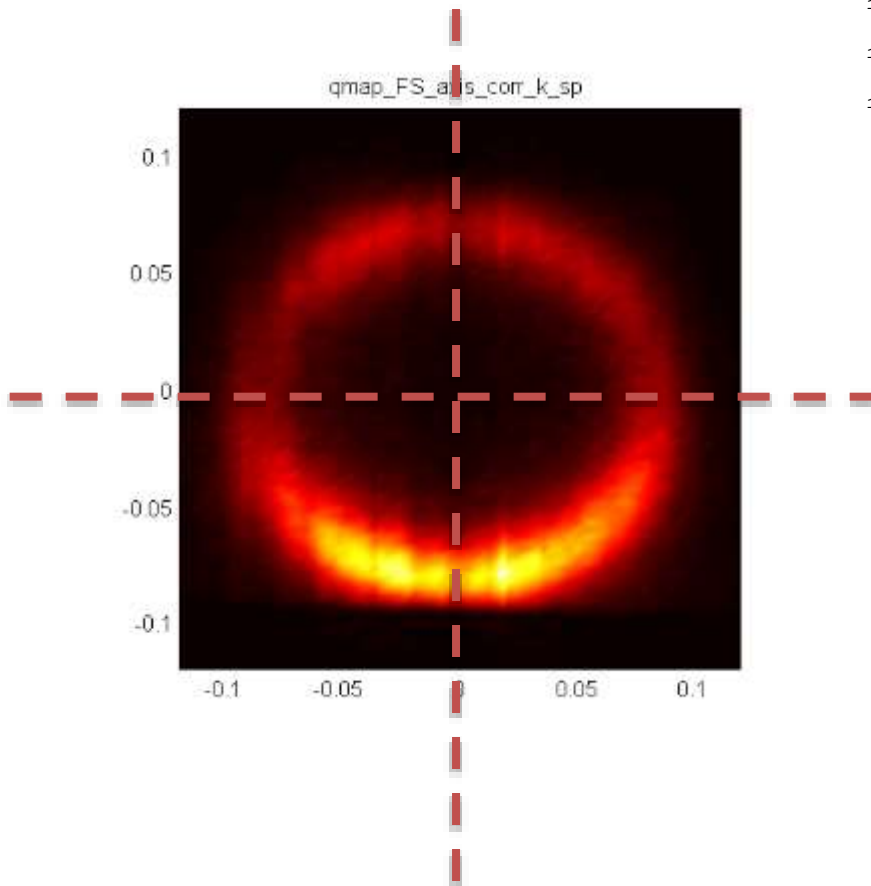
Line shape analysis

Difference EDC & MDC ?

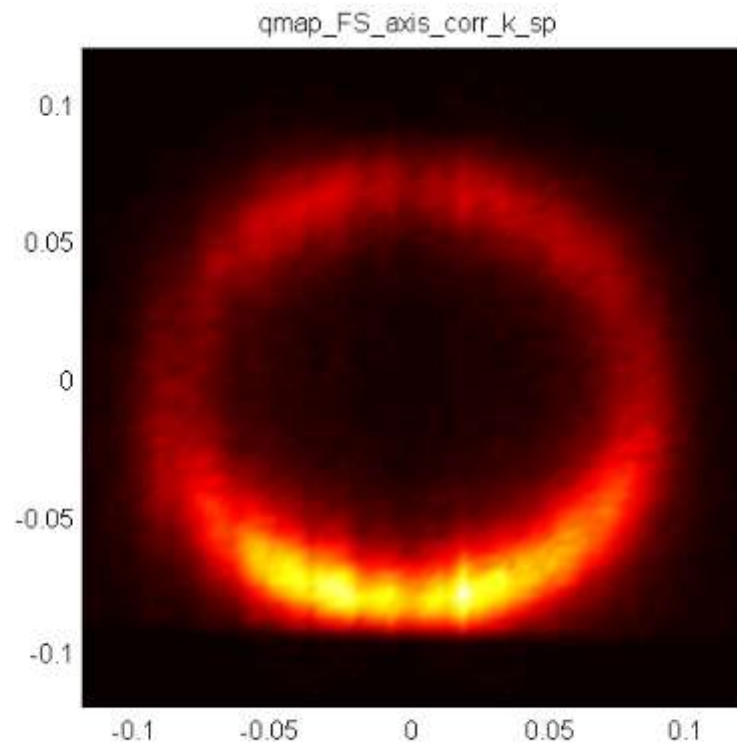


$$m_e = 0.35m_0$$

Line shape analysis



Line shape analysis



Carrier density
 $\sim 4 \times 10^{12} / \text{cm}^2$

Application of ARPES to Topological quantum materials

Classification of matter

Time



Topological insulators
Topological order

2005

Topological insulator



Topological invariant:
“ Z_2 number”

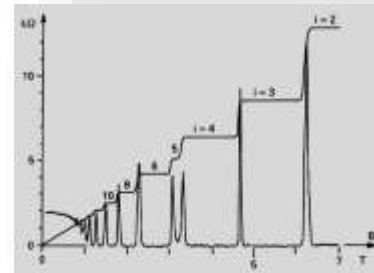
Quantum Hall system
Topological order

1980

Klaus Von Klitzing



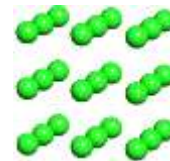
Integer quantum Hall effect



Topological invariant:
“Chern number”

Regular matter:
Spontaneously
Broken symmetry

Lev Landau



Translational
symmetry



Rotational
symmetry

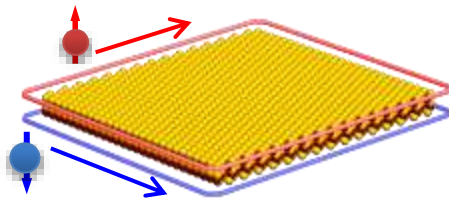


Gauge
symmetry

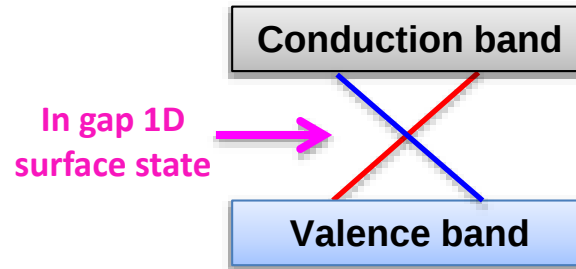
What is a topological insulator (TI)

An Insulator that conducts

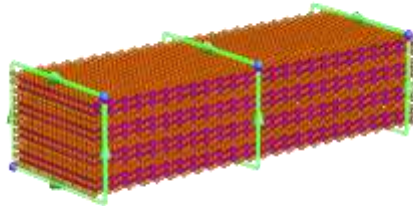
2D real space



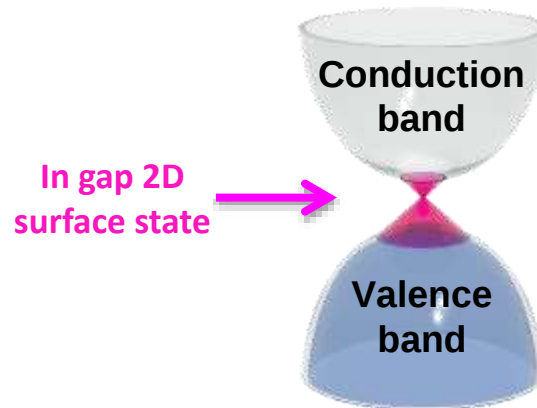
Band structure



3D real space



Band structure



We also live on the surface...



Why “topological”

Topologically distinct objects



Regular insulator



Topological insulator



Sphere



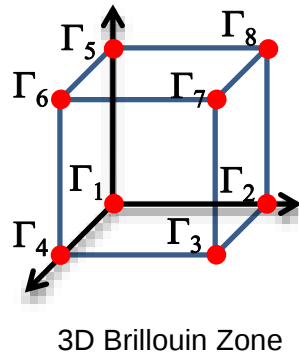
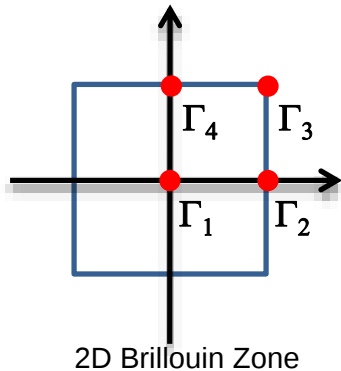
Torus



Characterization of TIs

Z_2 topological invariant

Band theory [Fu, Kane & Mele (2007) Moore & Balents (2007), Roy (2007)]



$$\delta_i = \frac{\sqrt{\det[B(\Gamma_i)]}}{Pf[B(\Gamma_i)]} \quad B_{mn}(k) = \langle -k, m | T | k, n \rangle$$

$$(-1)^v = \prod_i \delta_i = \pm 1$$

$$v = \begin{cases} 1: \text{Topological insulators} \\ 0: \text{Regular insulators} \end{cases}$$

With inversion symmetry: v represents the *Parity of occupied Bloch states*

Field theory [Qi, Zhang, et. al., (2008, 2009), Wilczek, (1987,2009)]

$$S_\theta = \frac{\theta\alpha}{4\pi^2} \int d^3x dt E \cdot B$$

+

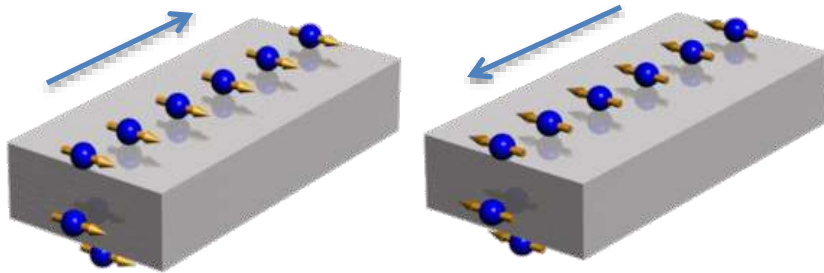
Time reversal symmetry



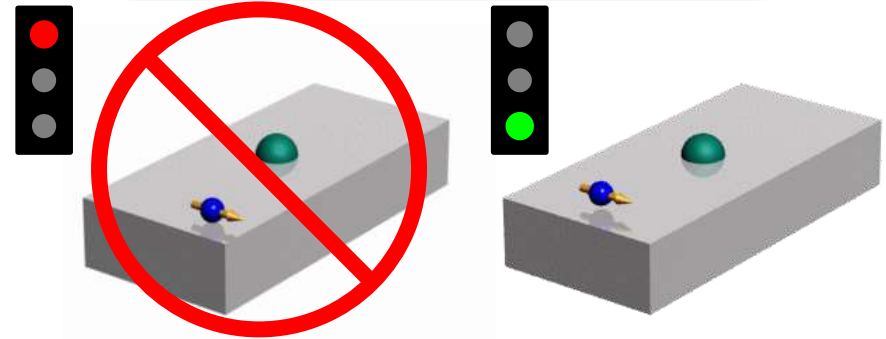
$$\theta = \begin{cases} \pi: \text{Topological insulators} \\ 0: \text{Regular insulators} \end{cases}$$

Unique surface state properties of TIs

"Locking" between current & spin

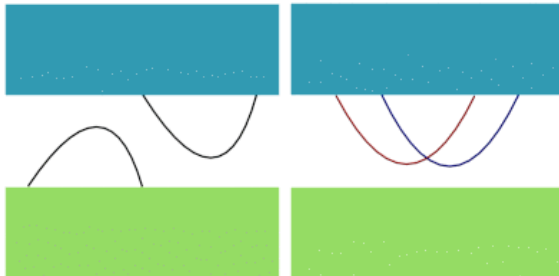


No back-scattering rule
(by non-magnetic impurities)

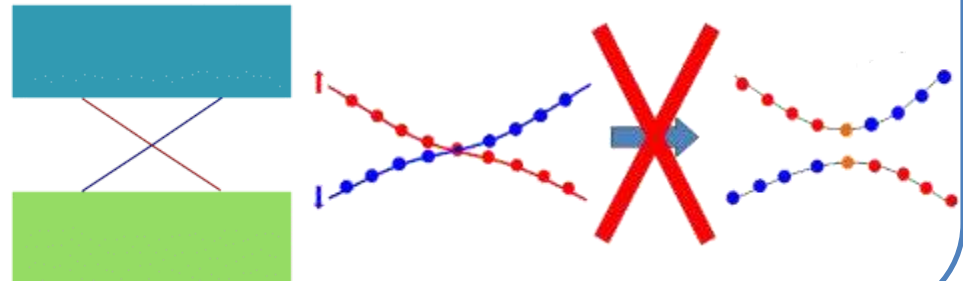


Robustness of the topological surface state

Surface state in regular insulator
vulnerable



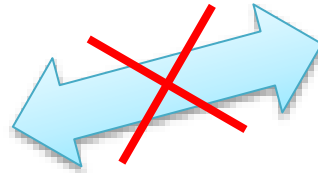
Surface state in topological insulator
robust



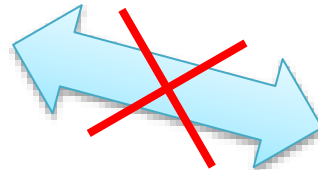
How to find TIs

Search for the unique band structure

Topological insulator



Regular conductor

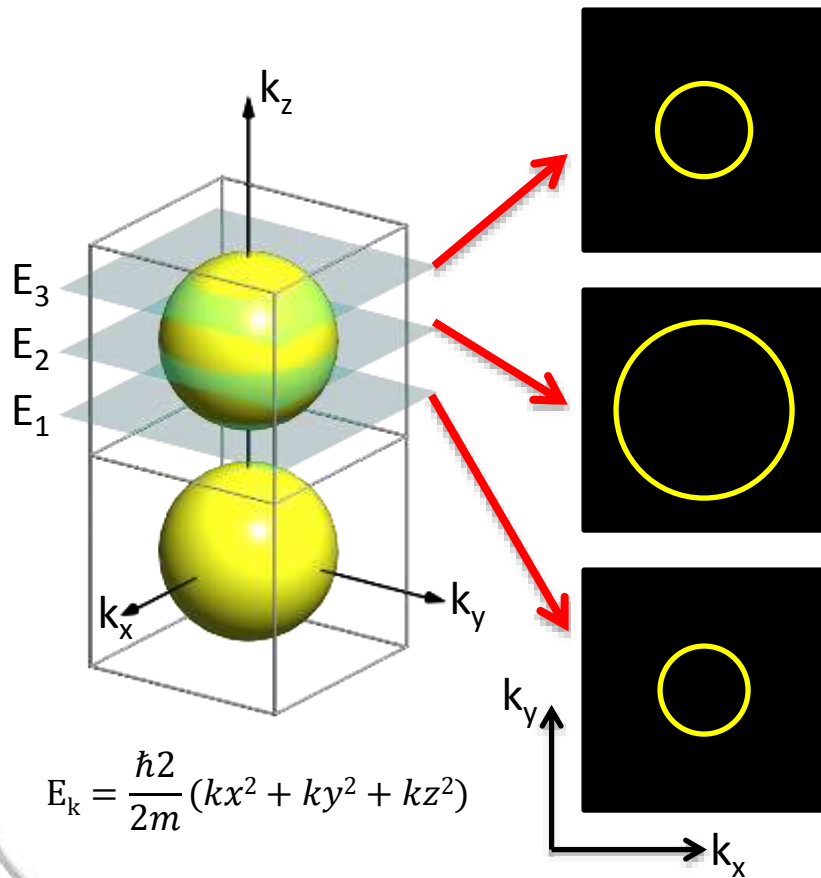


Regular insulator

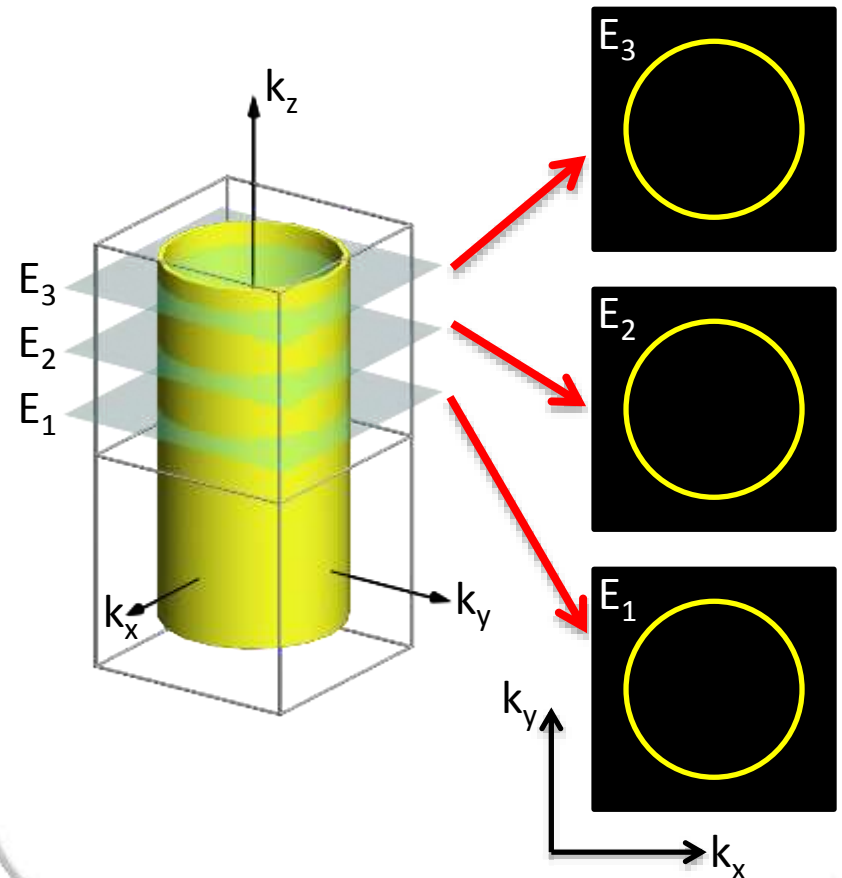


How to discriminate bulk & surface?

3D FS (e.g. FS from bulk state)



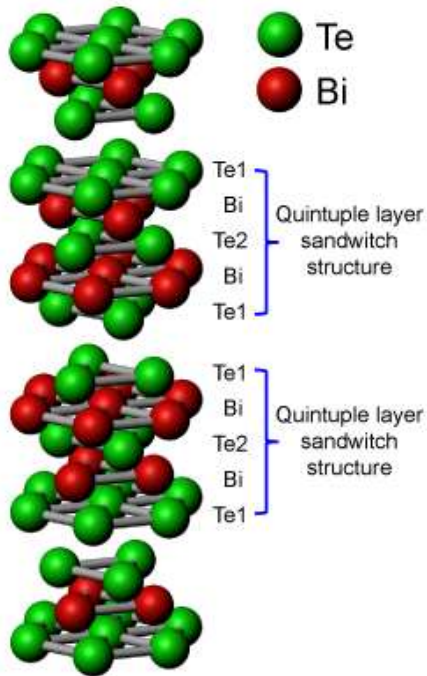
2D FS (e.g. FS from surface state)



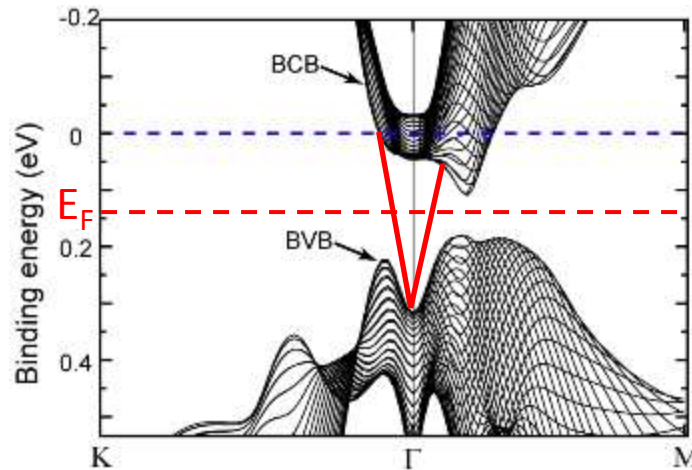
Realization of TI state in Bi_2Te_3

Y. L. Chen, *et. al.*, *Science* 325, 178 (2009)

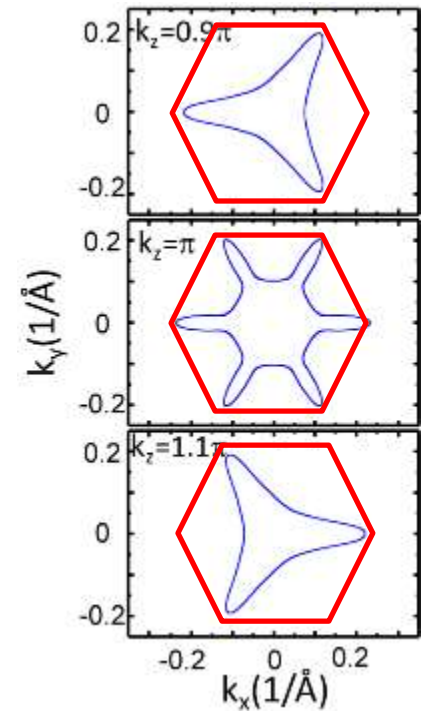
Crystal Structure



Bulk band structure



Bulk Fermi surface (n-type)



TI Checklist:

1. There exist Dirac surface states
2. There are odd number of Dirac fermions in a Brillouin Zone
3. The E_F is in the gap

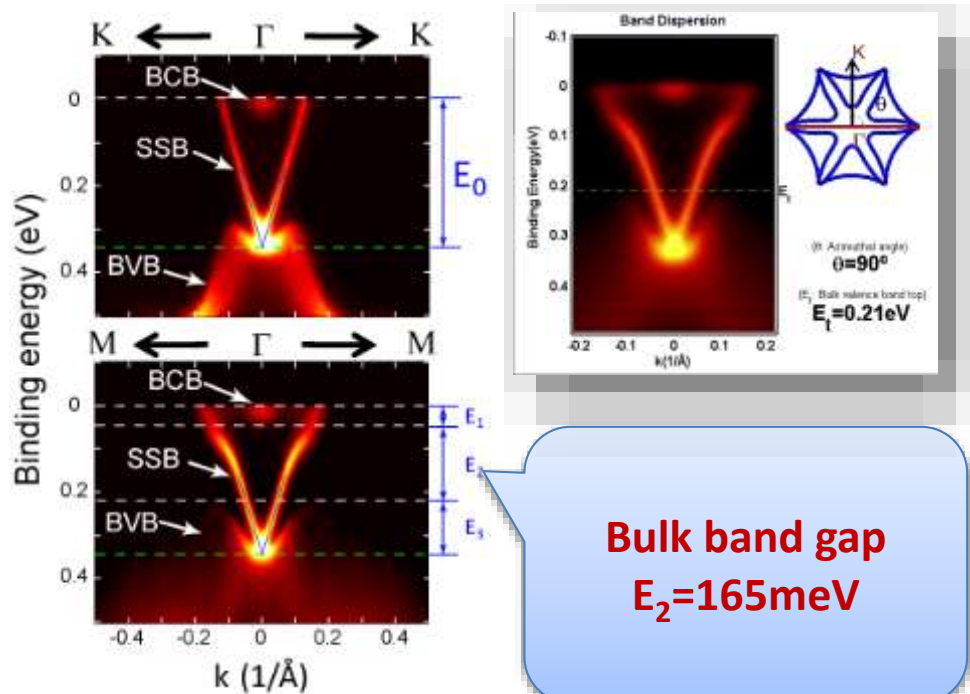
Realization of TI state in Bi_2Te_3

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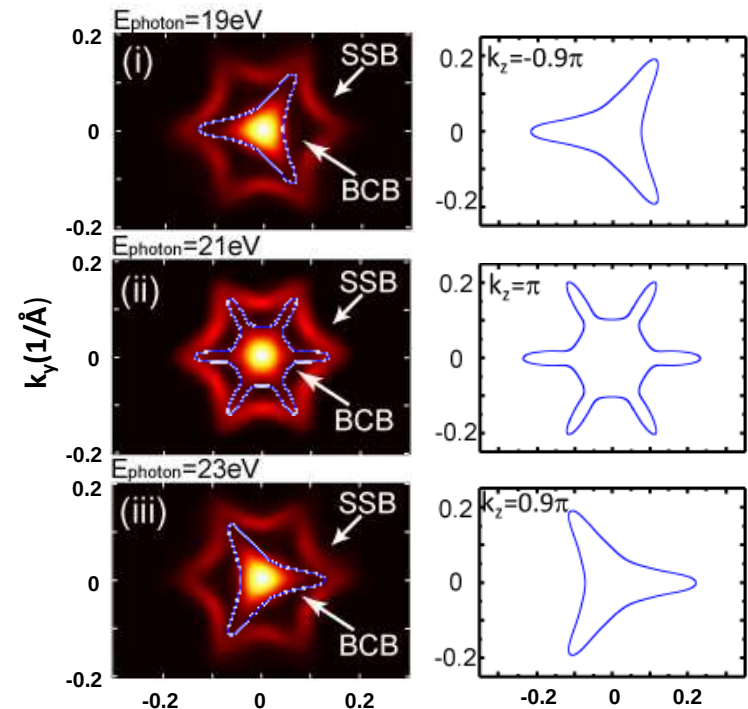
TI Checklist:

1. There exist Dirac surface states
2. There are odd number of Dirac fermions in a Brillouin Zone
3. The E_F is in the gap

Dirac fermion



Dirac Fermion's Surface nature



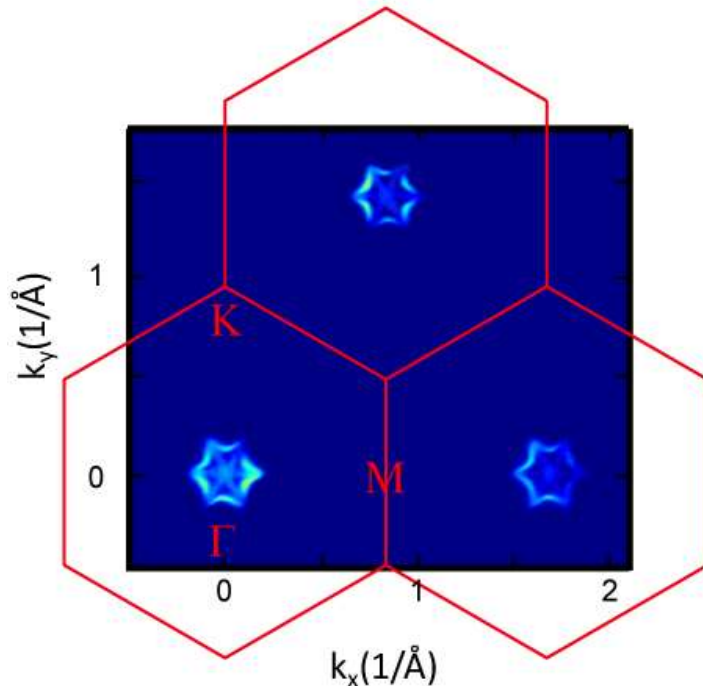
Realization of TI state in Bi_2Te_3

Y. L. Chen, *et. al.*, *Science* 325, 178 (2009)

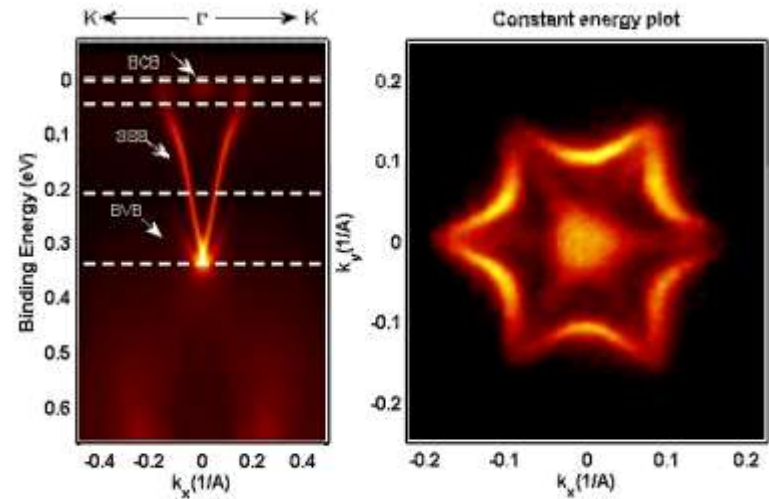
TI Checklist:

- ✓ 1. There exist Dirac surface states
- ✓ 2. There are odd number of Dirac fermions in a Brillouin Zone
3. The E_F is in the gap

Single Dirac fermion in each BZ



Evolution of the Band

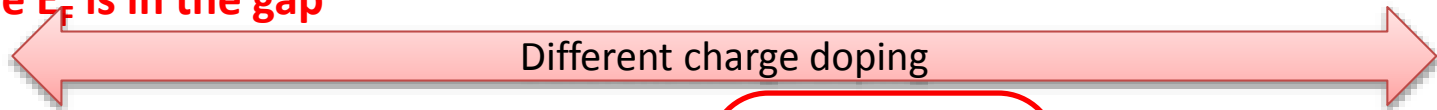


Realization of TI state in Bi_2Te_3

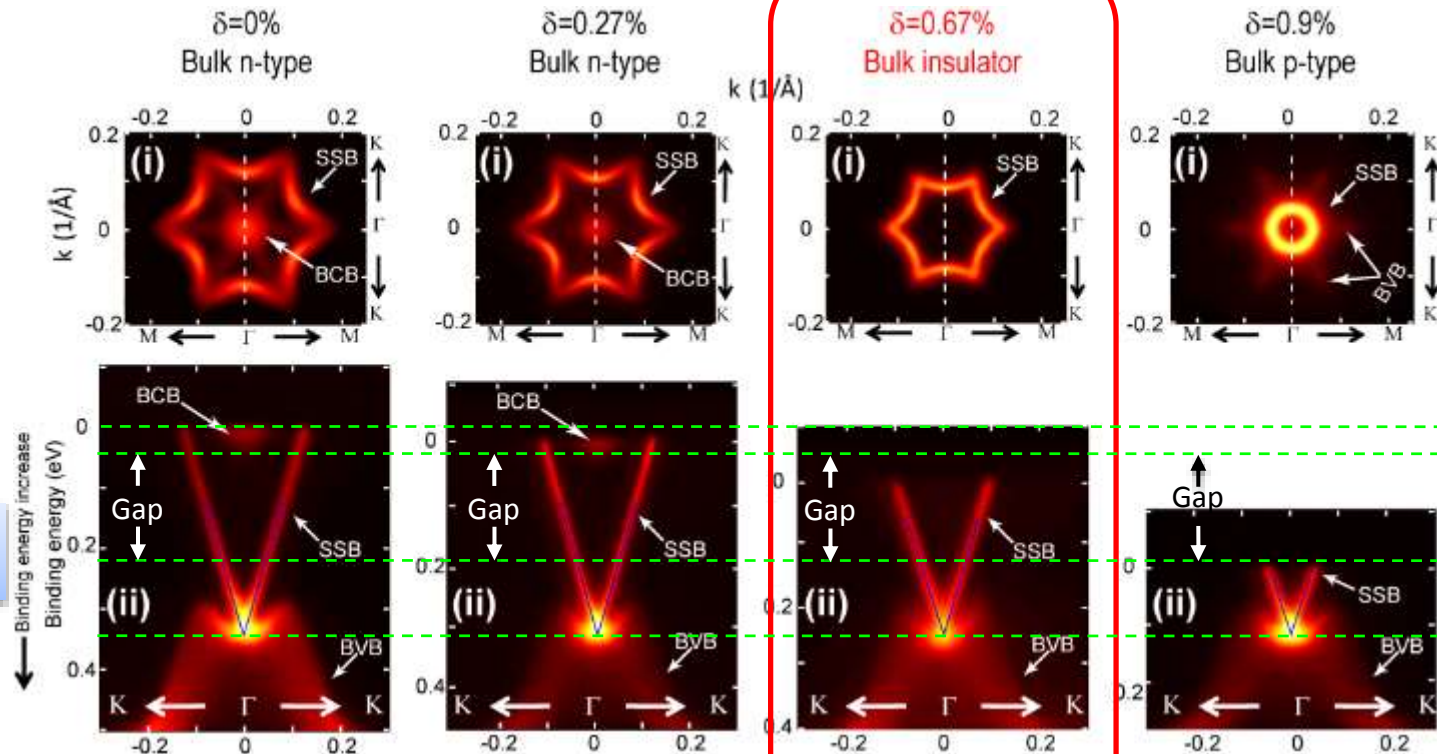
Y. L. Chen, *et. al.*, *Science* 325, 178 (2009)

TI Checklist:

- ✓ 1. There exist Dirac surface states
- ✓ 2. There are odd number of Dirac fermions in a Brillouin Zone
- ✓ 3. The E_F is in the gap



Fermi-Surface



Band Dispersion

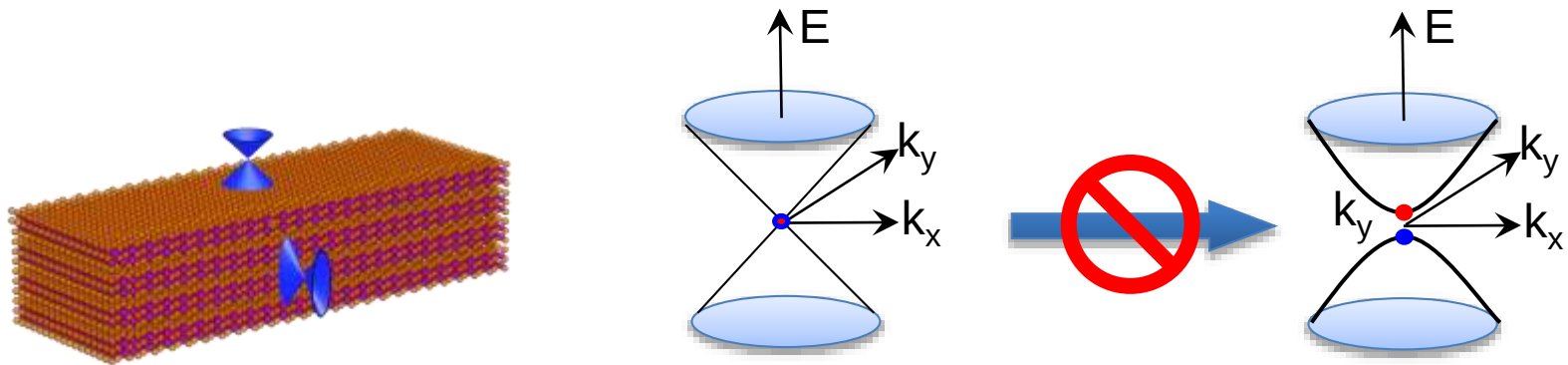
E_F (undoped)
BCB bottom

BVB top

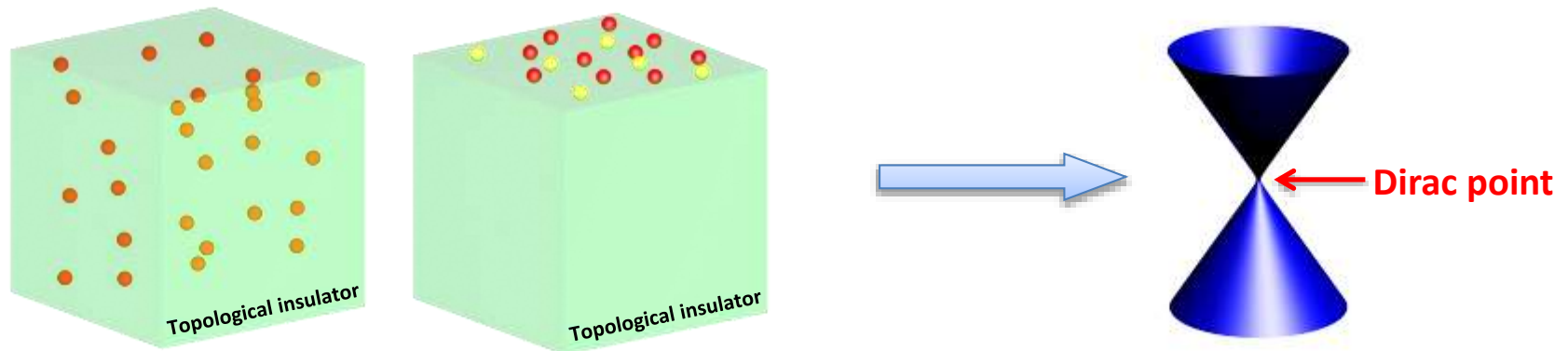
Dirac point
position

Protection of the time reversal symmetry

Massless Dirac fermion is protected by time reversal symmetry
(Kramers' theorem)



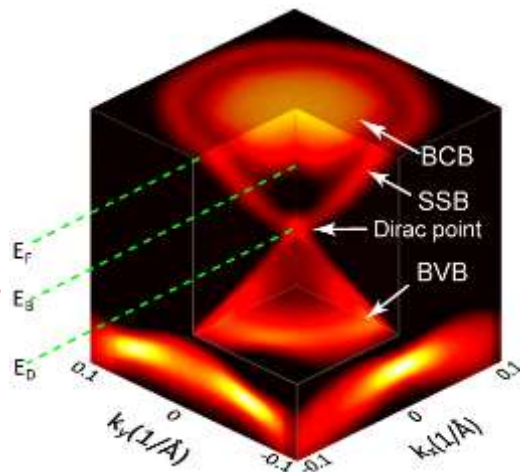
Non-magnetic bulk & surface doing



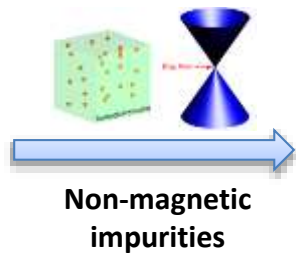
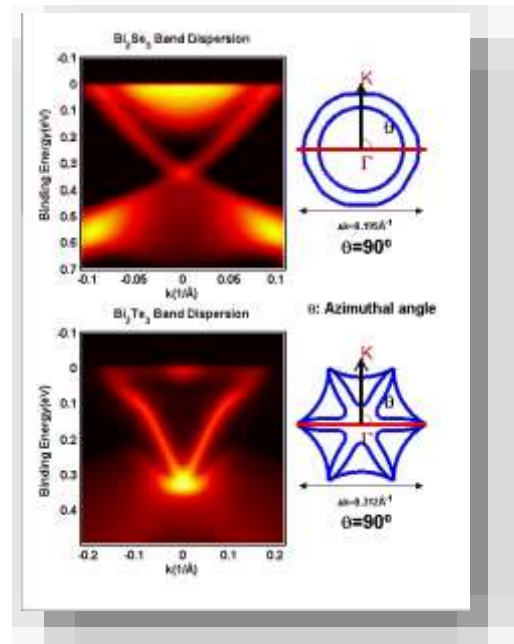
TRS protection – bulk doping

Y. L. Chen, *et. al.*, *Science* 329, 659 (2010)

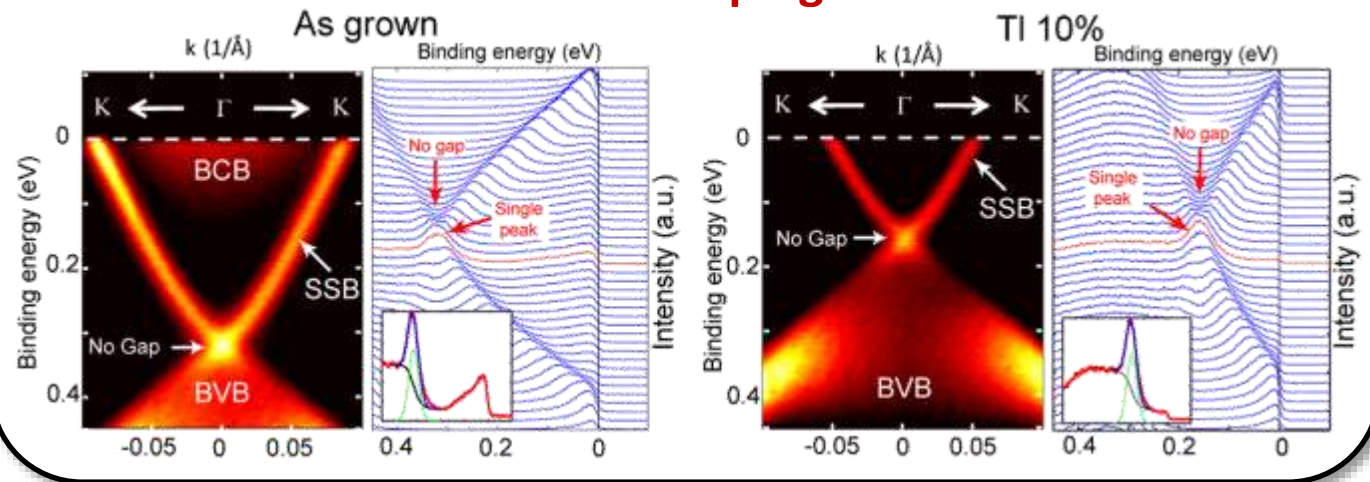
In gap Dirac
point of Bi_2Se_3



Compare
to Bi_2Te_3



Bulk doping



TRS protection – surface doping

Y. L. Chen, *et. al.*, *Science* 329, 659 (2010)

Surface doping

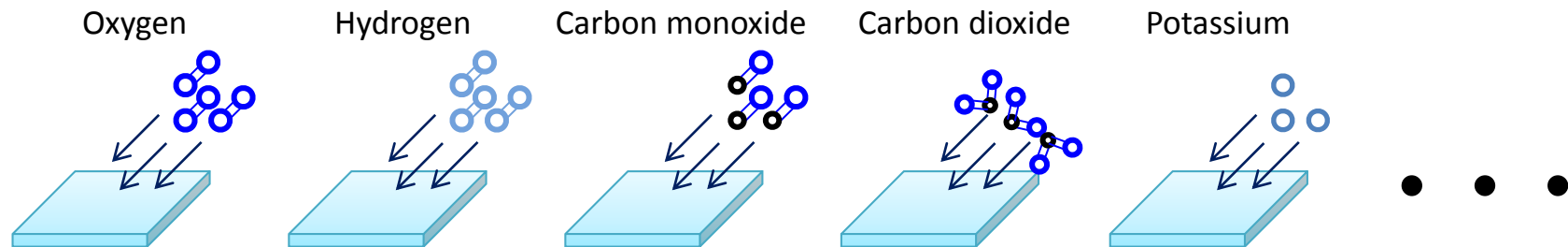
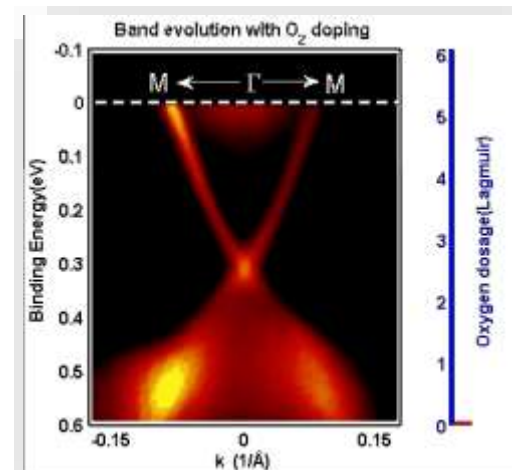
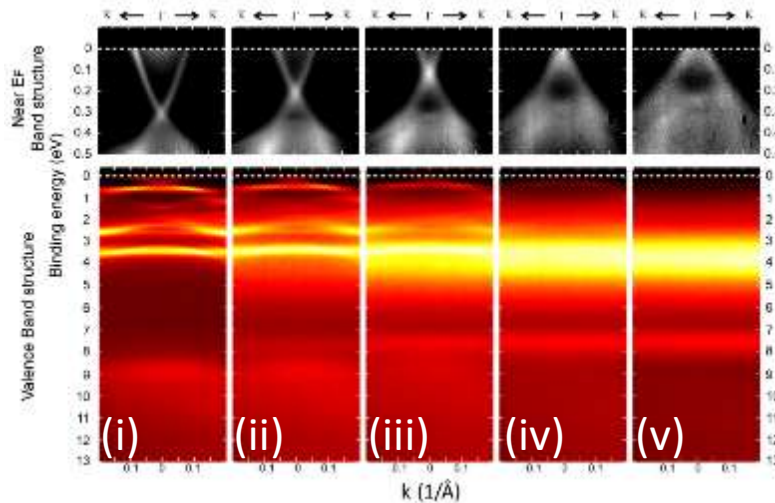
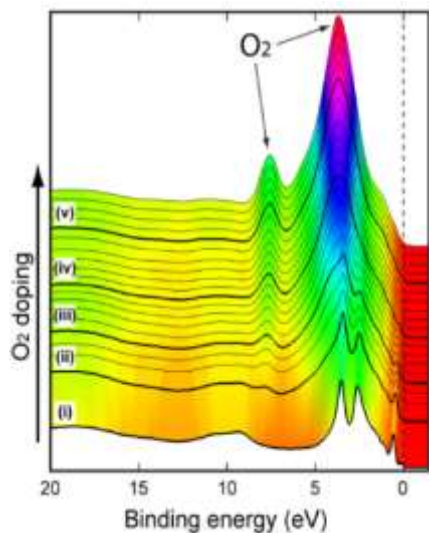


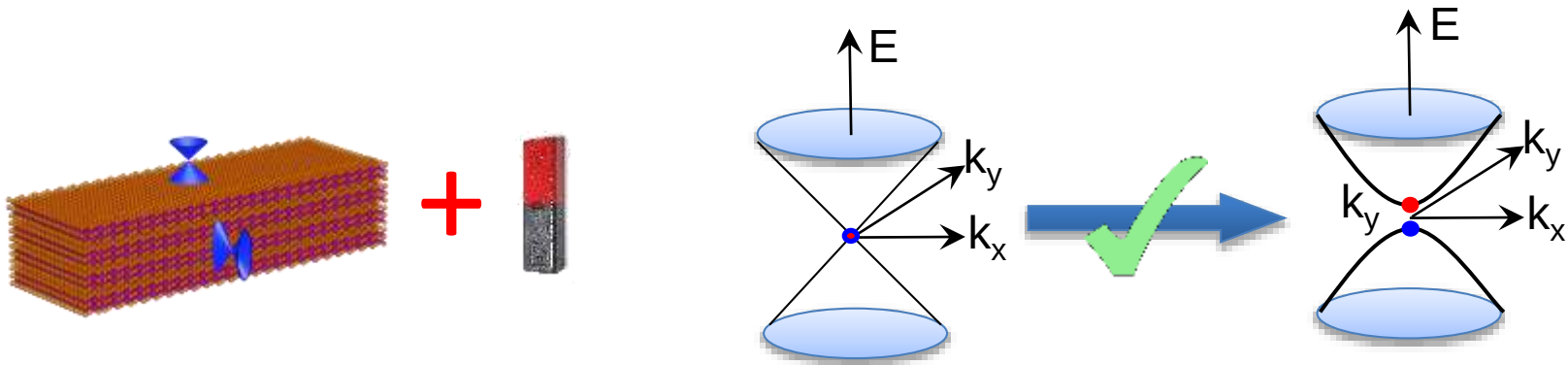
Photo assisted surface Oxygen doping



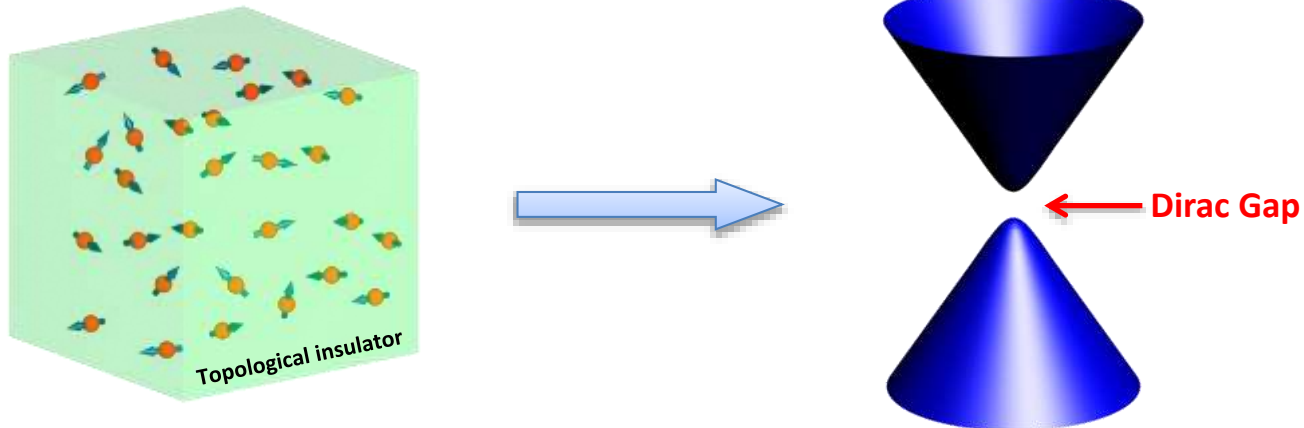
What if TRS is broken?

Y. L. Chen, *et. al.*, *Science* 329, 659 (2010)

Formation of massive Dirac fermion if TRS is broken

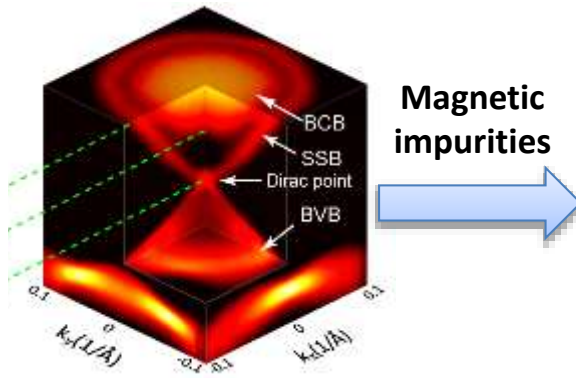


Magnetic doing

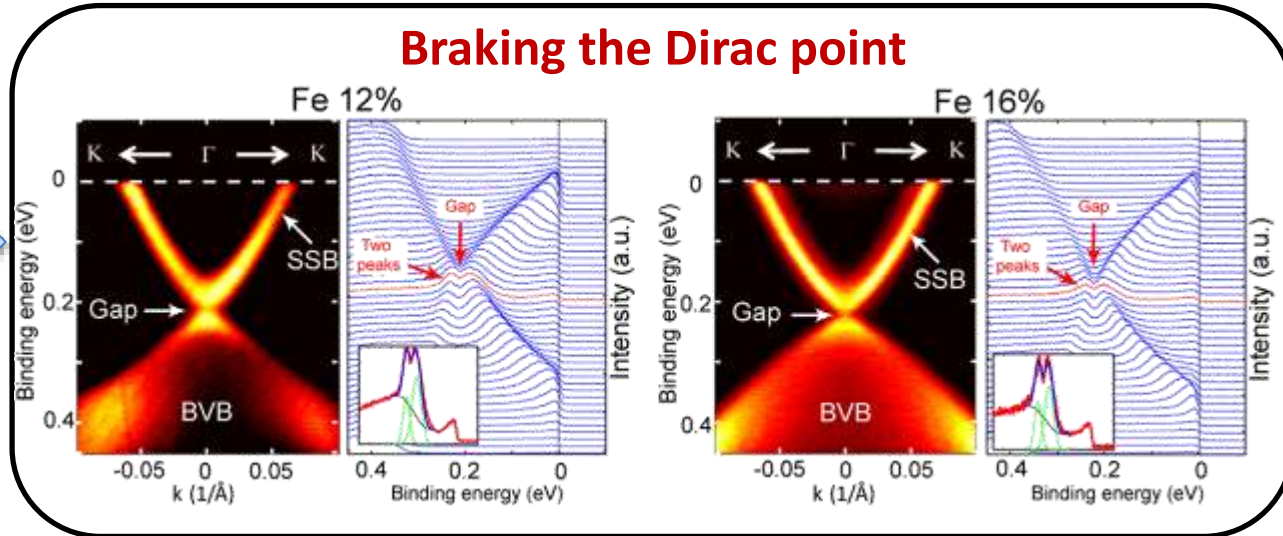


Dirac fermion becomes massive

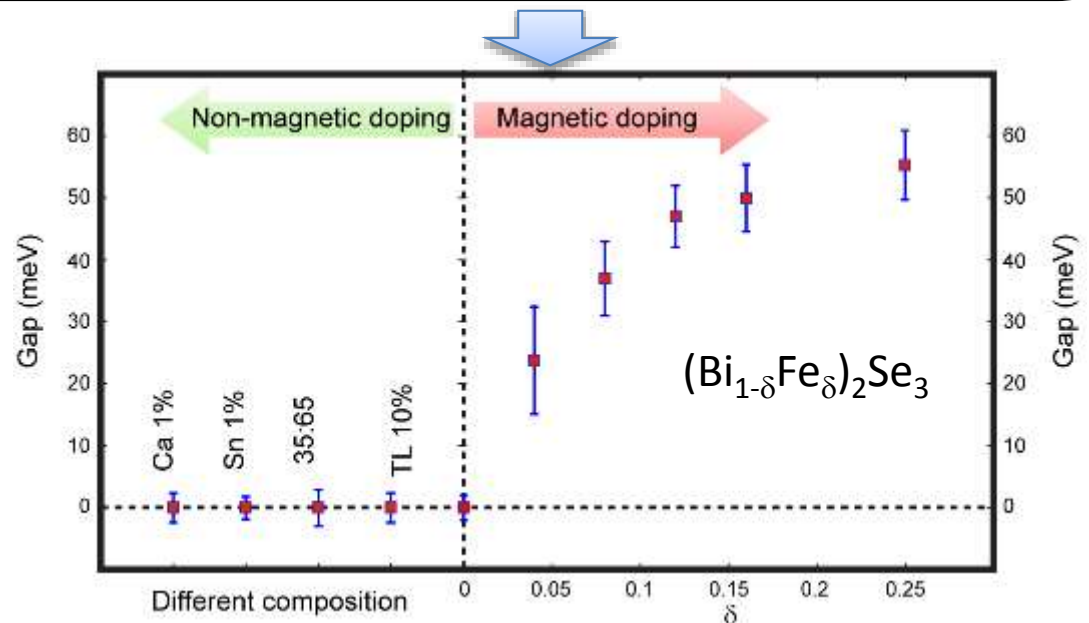
Y. L. Chen, *et. al.*, *Science* 329, 659 (2010)



Braking the Dirac point

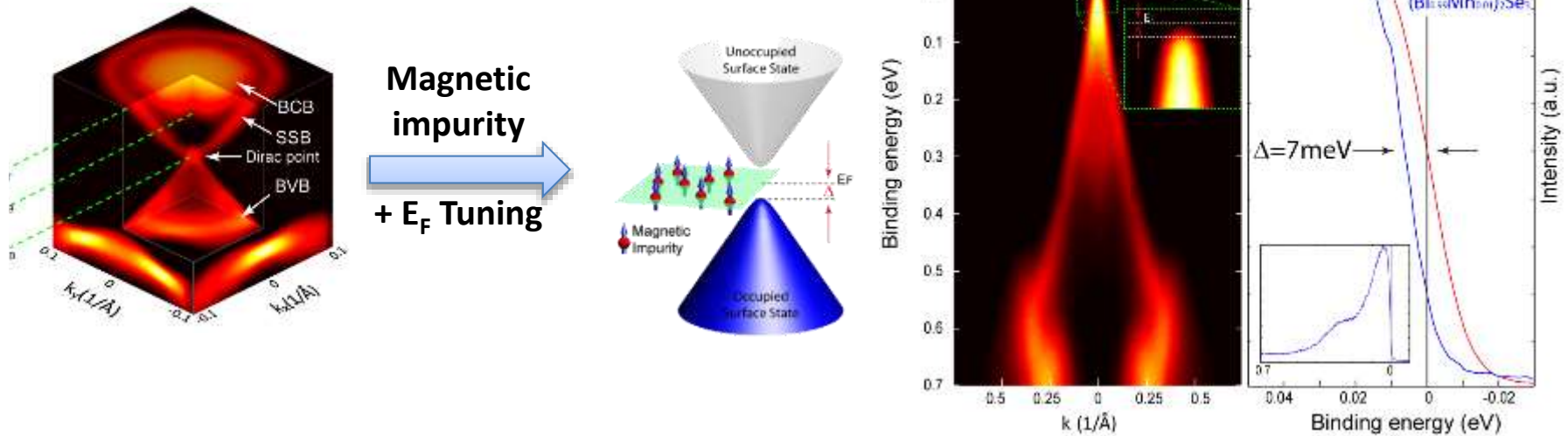


Summary of different doping effects



Realize insulating massive Dirac fermion state

Y. L. Chen, *et. al.*, *Science* 329, 659 (2010)



Why insulating massive Dirac fermion state?

Realize new phenomena

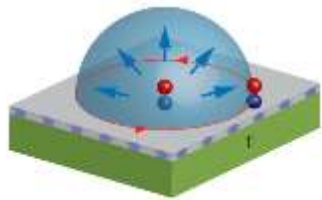
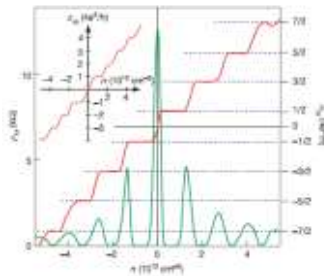
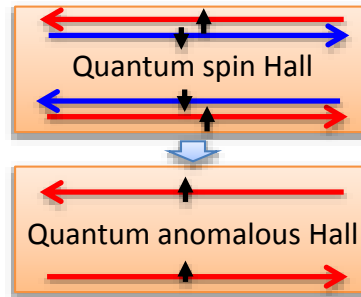


Image
Surface Monopole

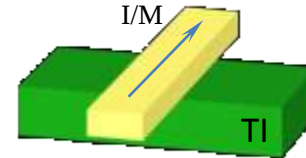


Half Hall
conductance $\sigma_H = e^2/2h$

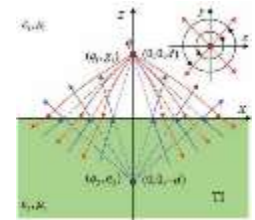


2D quantum
anomalous Hall state

Provide control for applications



Turn off
surface conduction

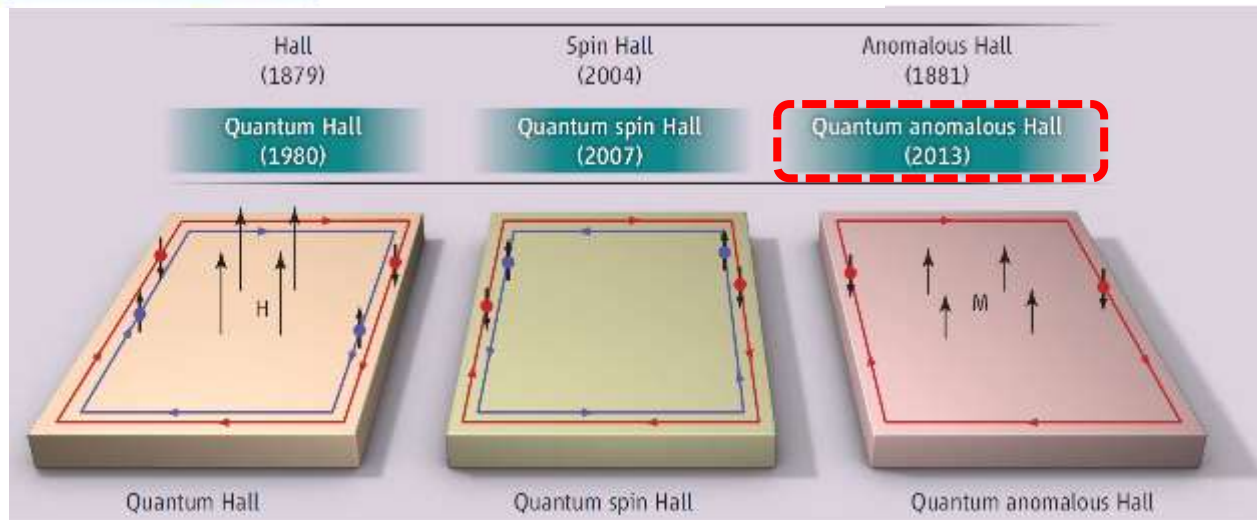


All electric
magnetic writing

Completing the table of Hall effects



The Complete Quantum Hall Trio
 Seongshik Oh
Science **340**, 153 (2013);
 DOI: 10.1126/science.1237215



Realize new phenomena

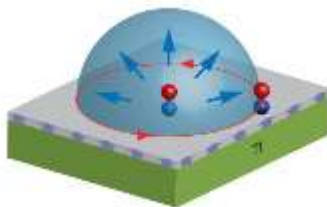
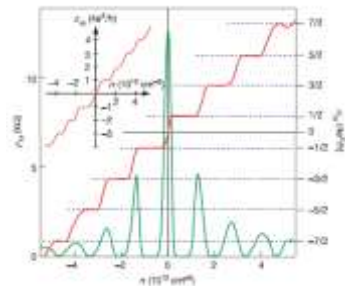
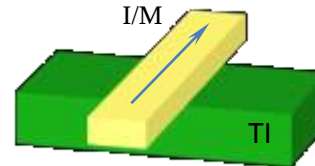


Image
 Surface Monopole

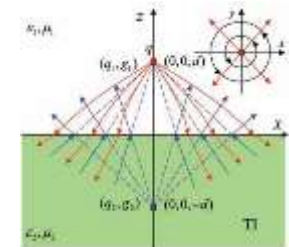


Half Hall
 conductance $\sigma_H = e^2/2h$

Provide control for applications



Turn off
 surface conduction

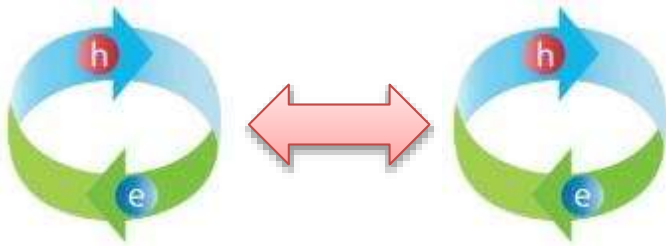


All electric
 magnetic writing

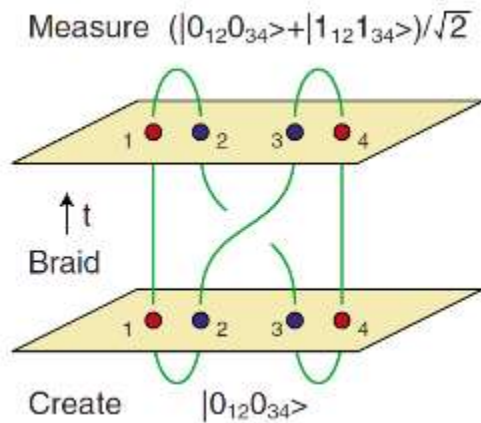
New topological states

Search for topological superconductors

Majorana fermion



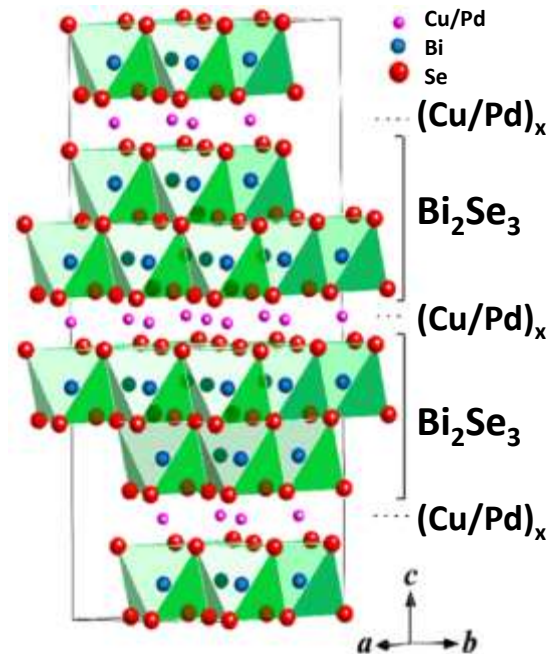
Quantum computation



Fu, Kane (2008)
Hasan, Kane (2010)
Qi, Zhang (2010)

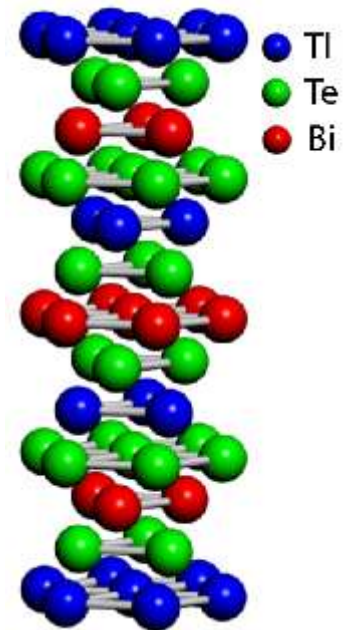
Some candidates

$\text{Cu}_x\text{Bi}_2\text{Se}_3$, $\text{Pd}_x\text{Bi}_2\text{Te}_3$



Hor, et. al., (2010)
Fu, Berg, (2010)
Wray, et.al., (2010)

TlBiTe_2

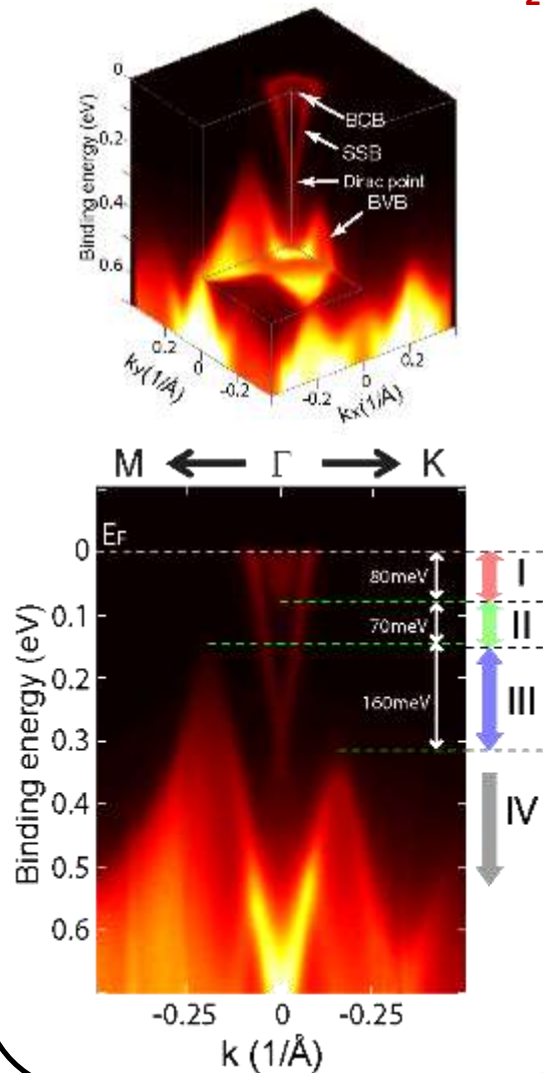


Hein/Swiggard, (1970)
Yan, et. al., (2010)
Chen, et. al., (2010)

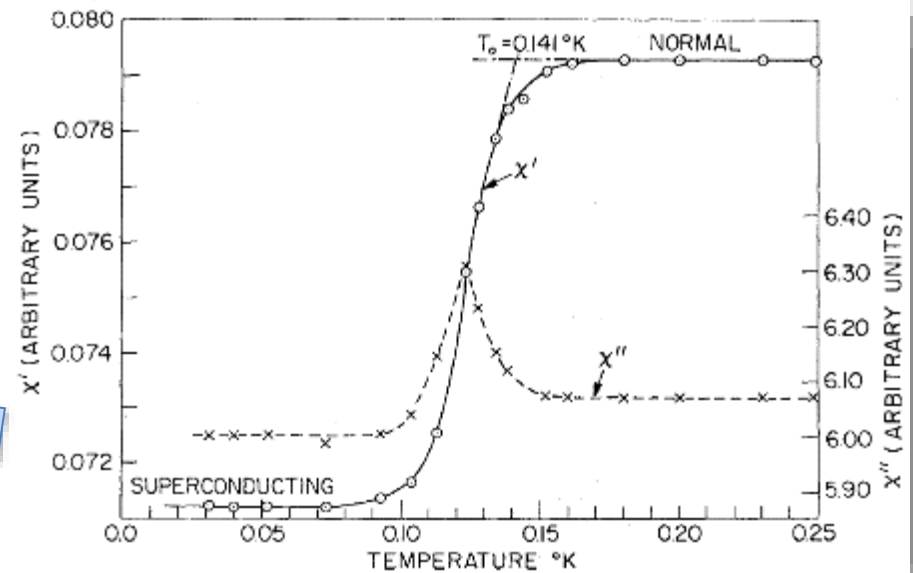
A candidate for topological superconductors

Y. L. Chen *et al.*, *Phys. Rev. Lett.* 105, 266401 (2010)

Band structure of TlBiTe_2



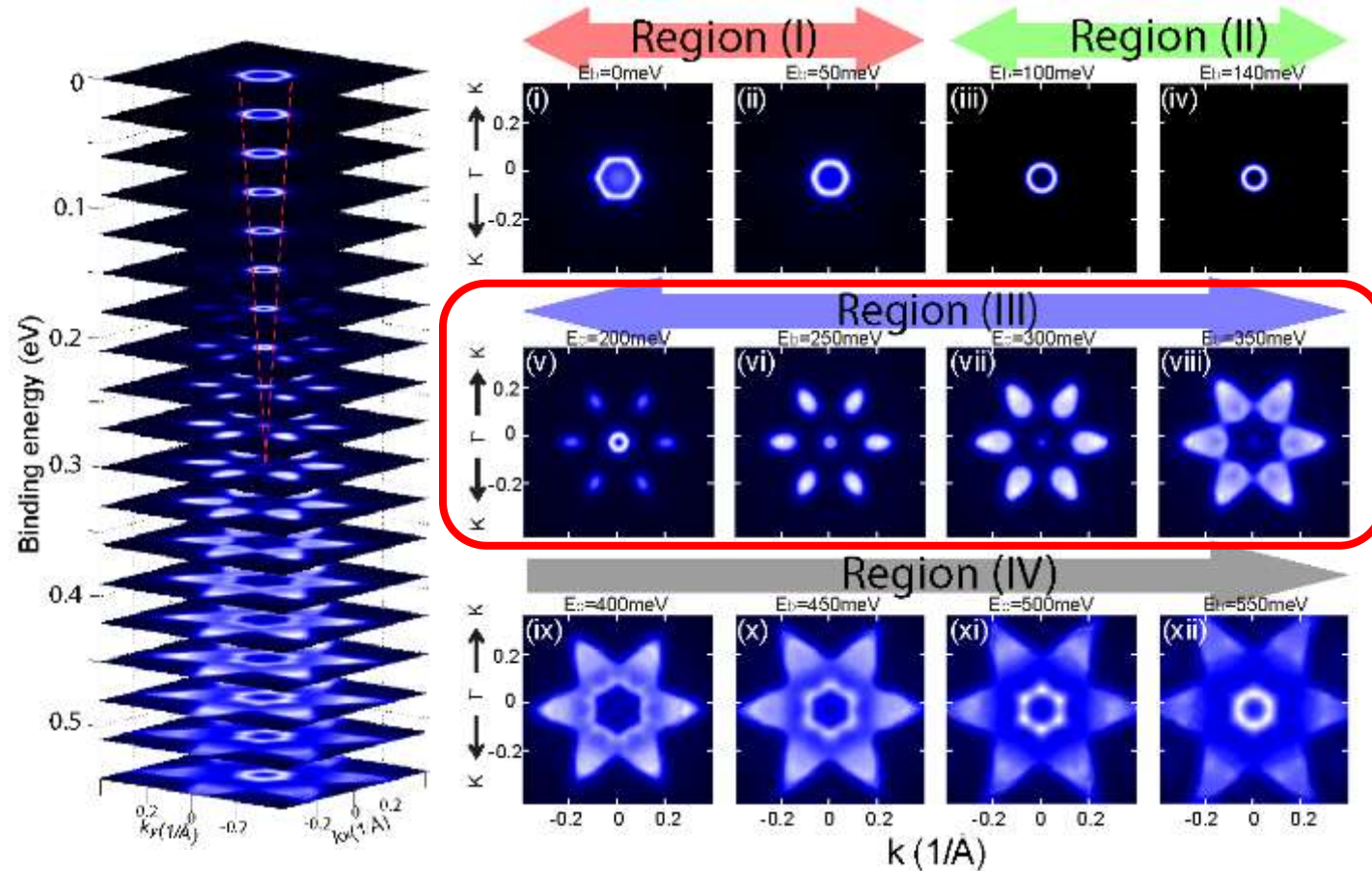
Superconducting transition



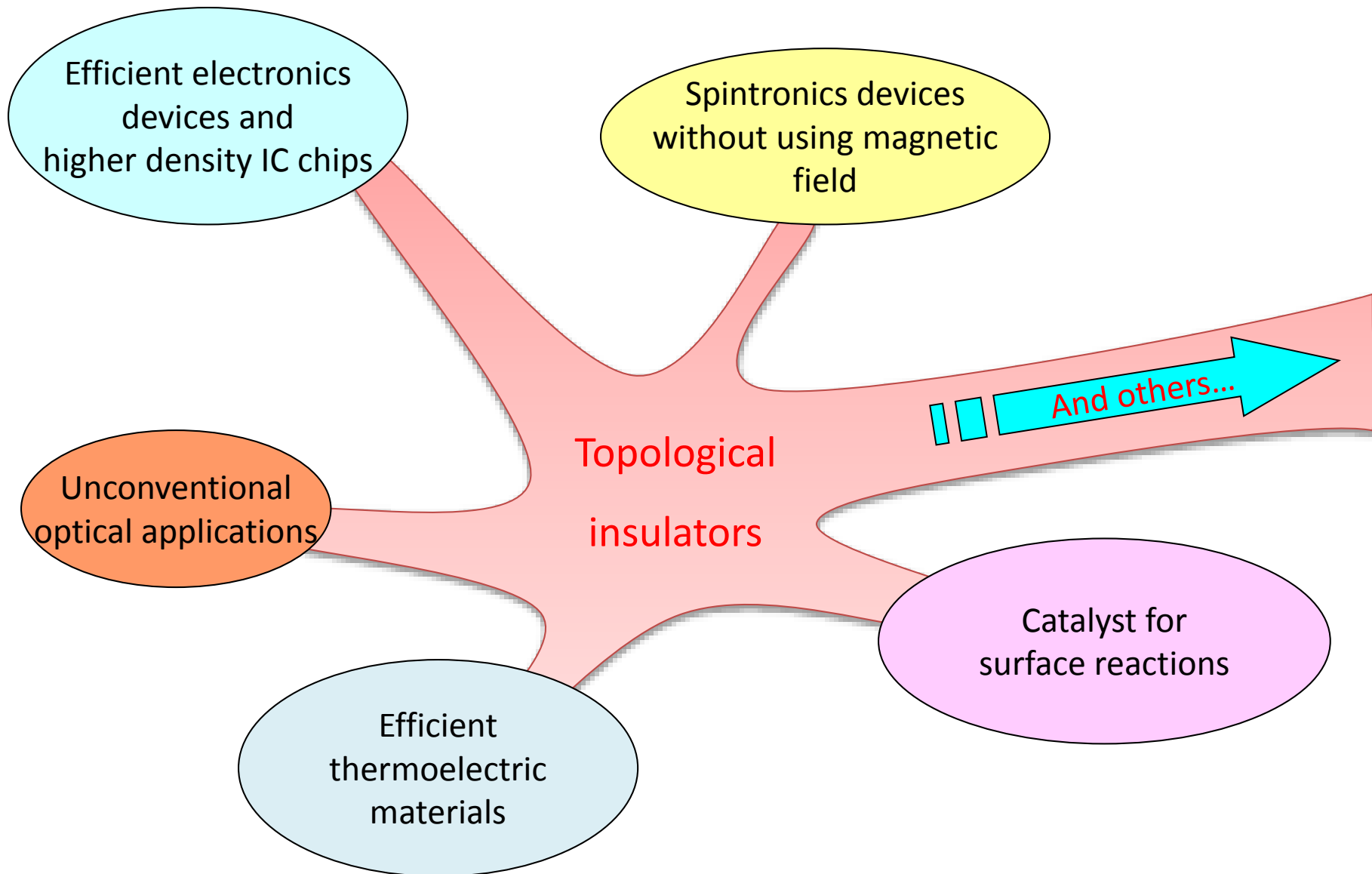
Hein & Swiggard *Phys. Rev. Lett.* 24, 53 (1970)

A candidate for topological superconductors

Y. L. Chen *et al.*, *Phys. Rev. Lett.* 105, 266401 (2010)



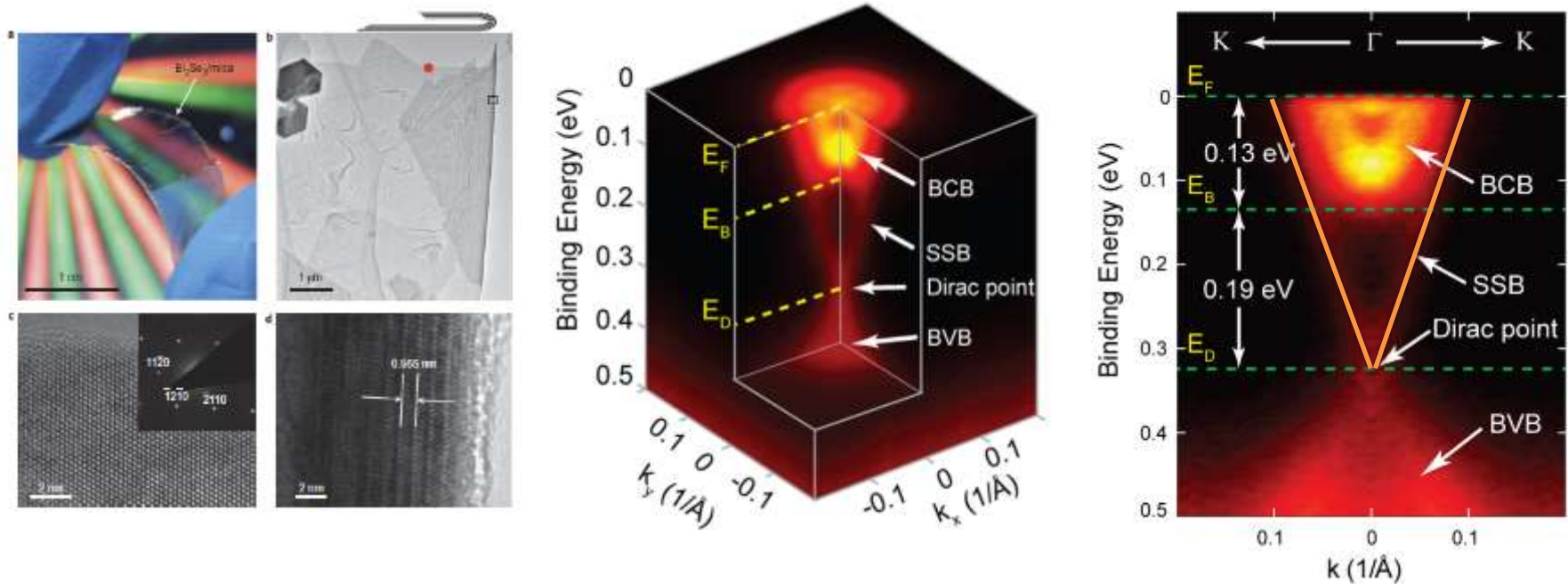
What can TI be used in real life



Flexible transparent electrodes – band structure

H. L. Peng, et. al., *Nature Chemistry*, 4, 281 (2012)

Electronic structure of a 10nm Bi_2Se_3 film



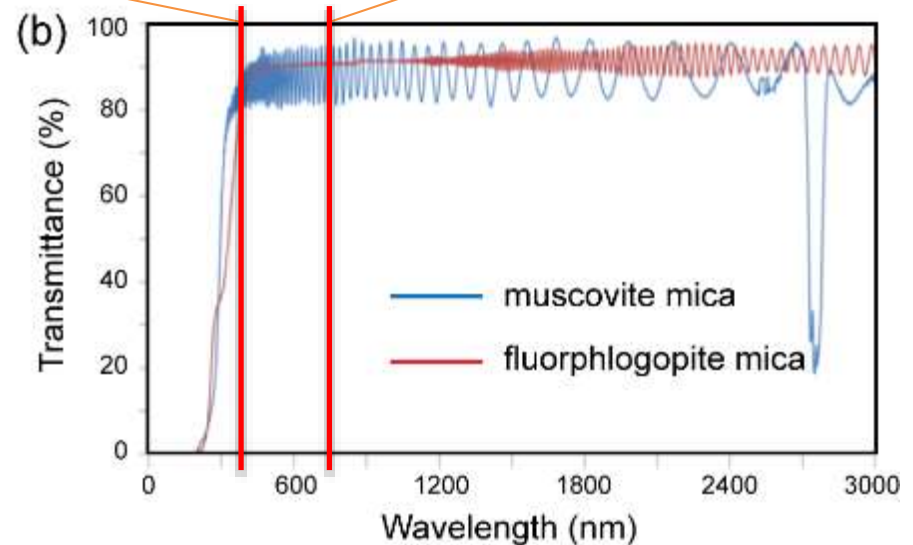
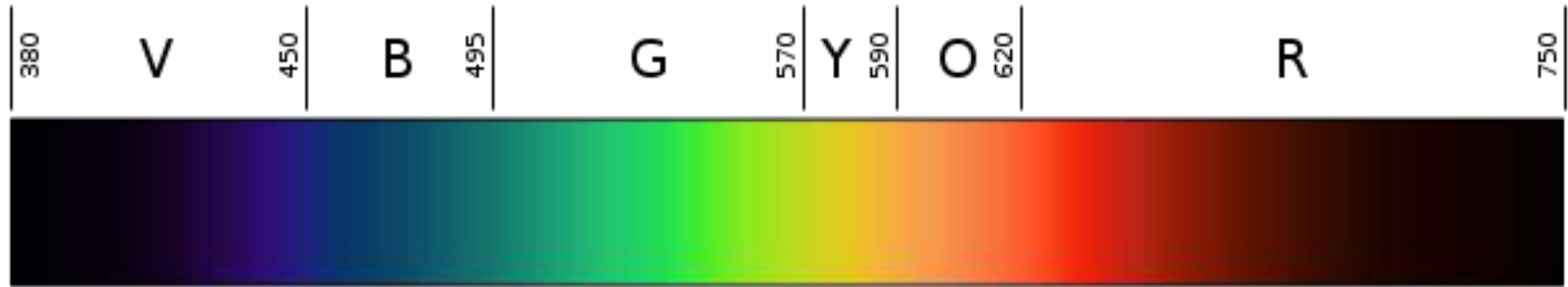
Estimate surface states Carrier density (up and down surfaces):

$$2 \times \pi \times k_f^2 / (2 \times \pi)^2 = 0.0016 \text{ \AA}^{-2} = \underline{1.6 \times 10^{13} \text{ cm}^{-2}}$$

Effective 2D density of bulk carrier for a 10nm film is roughly:

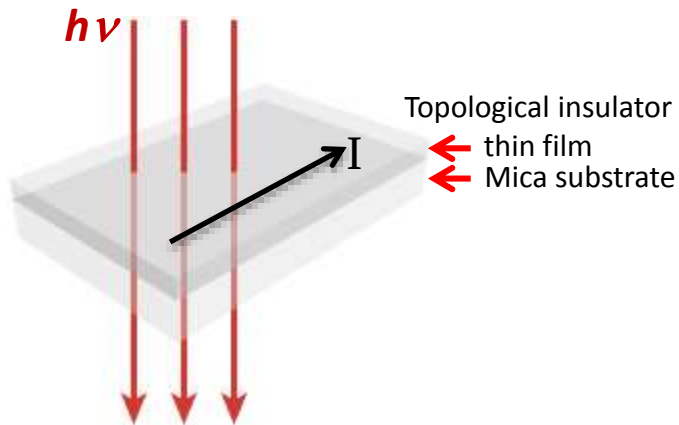
$$(4/3 \times \pi \times k_f^3 \times (10 \text{ nm})) / (2 \times \pi)^3 = 0.0017 \text{ \AA}^{-2} = \underline{1.7 \times 10^{13} \text{ cm}^{-2}}$$

Transparent electrode for IR application

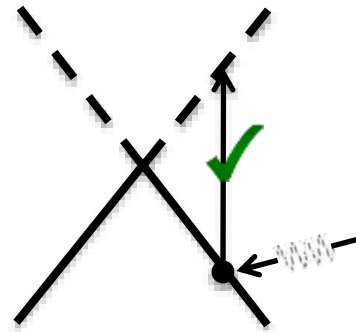


Flexible transparent electrodes - Transmittance

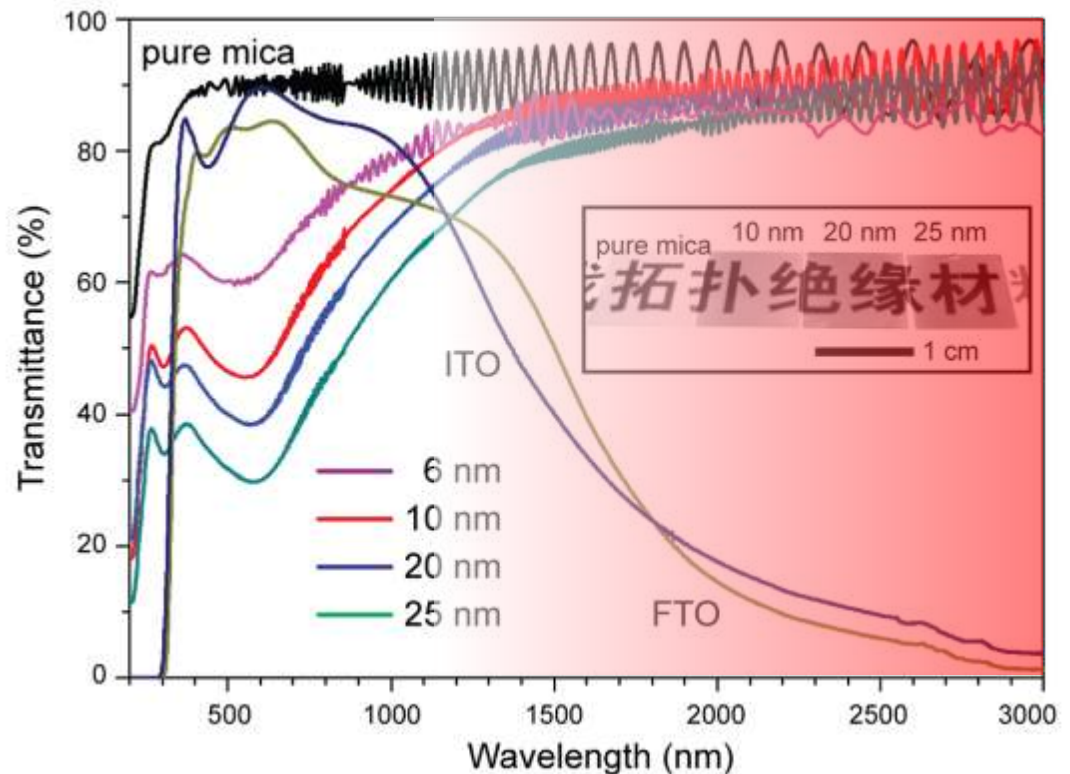
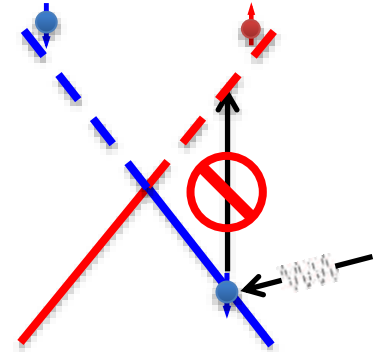
H. L. Peng, *et. al.*, *Nature Chemistry*, 4, 281 (2012)



Regular Dirac fermion



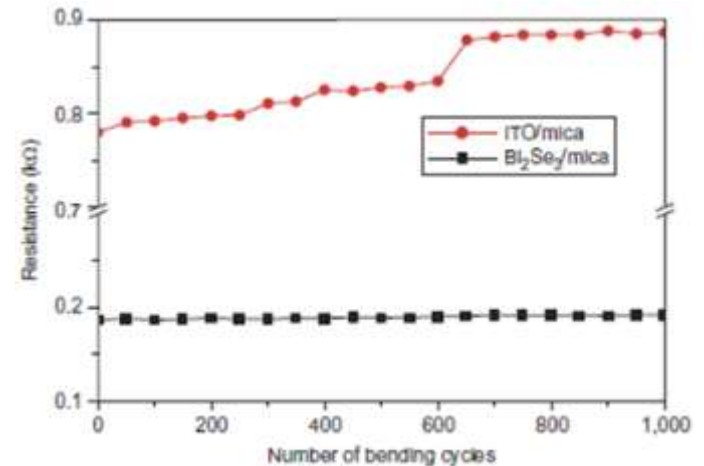
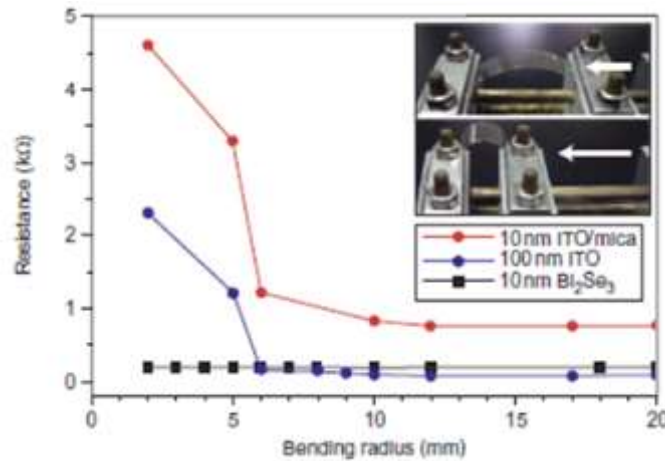
Helical Dirac fermion in TI



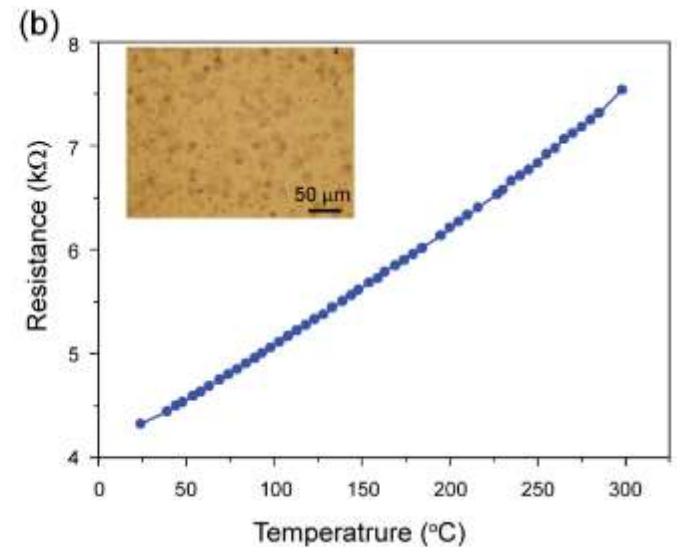
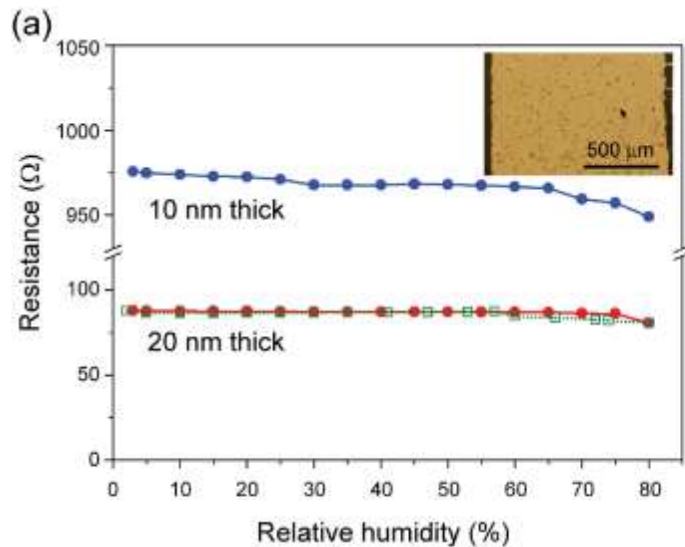
Flexible transparent electrodes - Durability

H. L. Peng, *et. al.*, *Nature Chemistry*, 4, 281 (2012)

Bending test



Humidity and Heating test



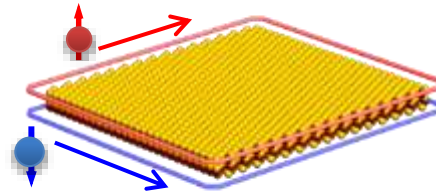
Flexible transparent electrodes

Flexibility and durability test

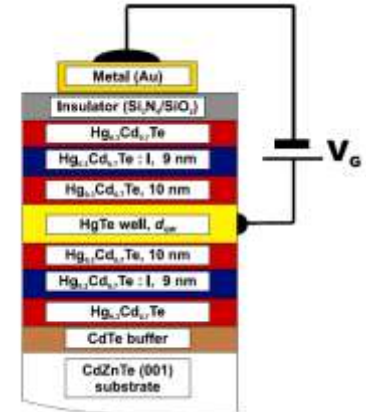
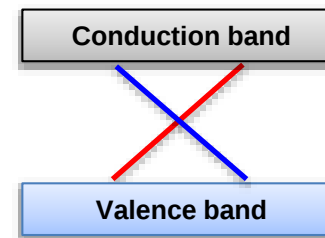
Flexibility Test

Dirac electron systems

1D Dirac fermions

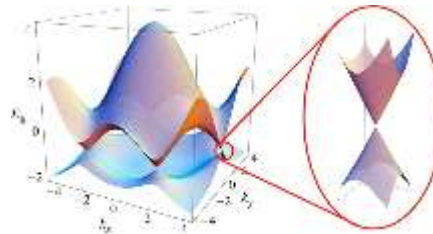
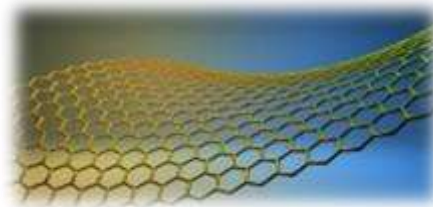


Quantum spin Hall edge state

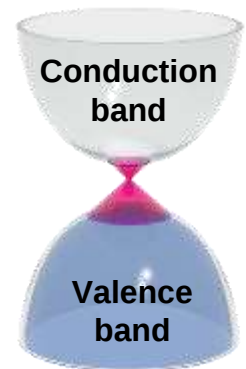
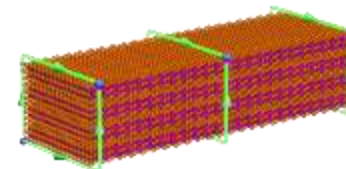


2D Dirac fermions

Graphene



3D TI surface state



Can we find other topological matter?

Insulator



Topological Insulator

Semimetal



Topological Semimetal

Superconductor



Topological Superconductor

• • • • •

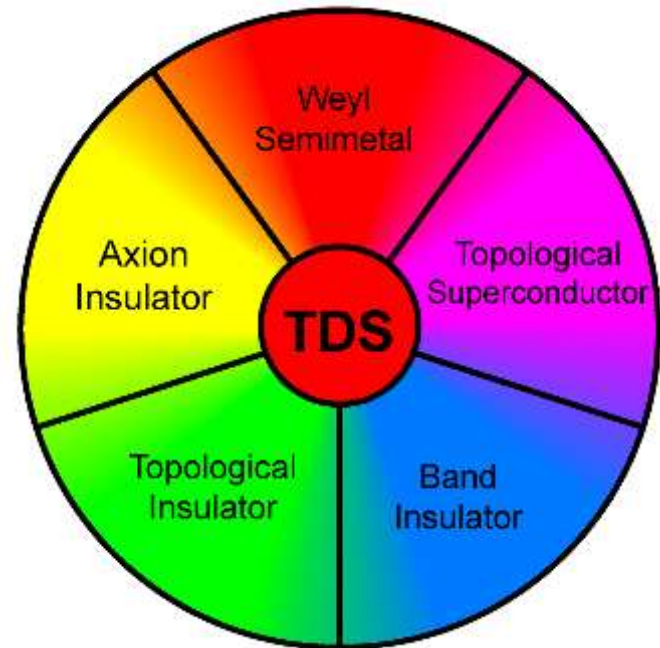
3D Topological Dirac Semi-metal (TDS)

Z. K. Liu. *et. al.*, Science, 343, 864 (2014)

Interesting phenomena

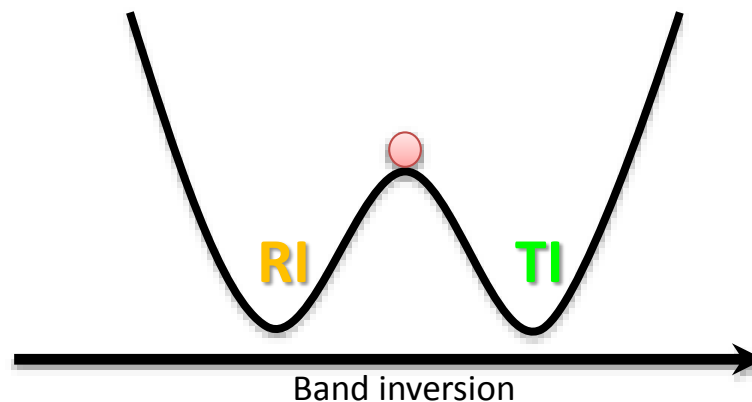
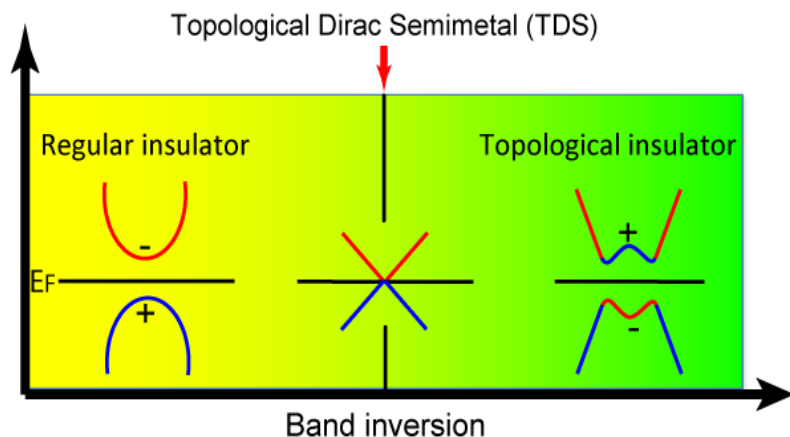
- Giant diamagnetism
E. Röber, *et. al.*, *Phys. Status Solidi B*, **93**, K99 (1979)
M. Koshino, *et. al.*, *Phys. Rev. B*, **81**, 195431 (2010)
- Linear quantum magnetoresistance in bulk
A. A. Abrikosov, *Phys. Rev. B*, **58**, 2788 (1998)
W. Zhang *et al.*, *Phys. Rev. Lett.*, **106**, 156808 (2011)
- Oscillating QSH effect in quantum well
W. Zhang *et al.*, *Phys. Rev. Lett.*, **106**, 156808 (2011).
Z. Wang *et al.*, *Phys. Rev. B* **85**, 195320 (2012)

A platform for rich novel states



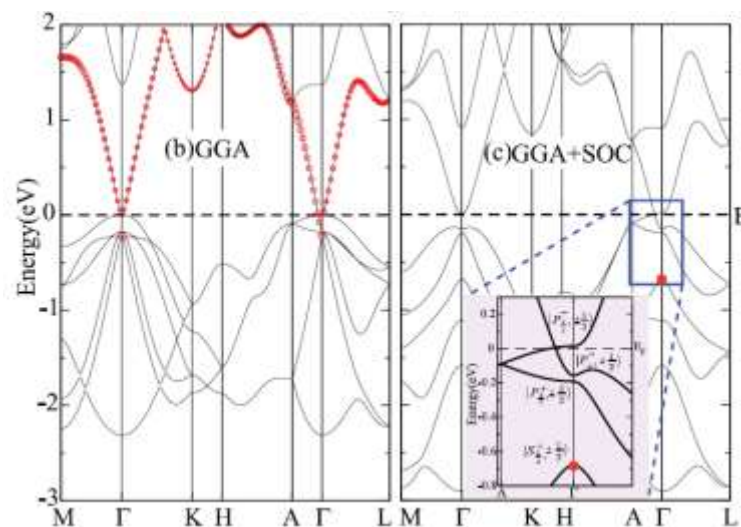
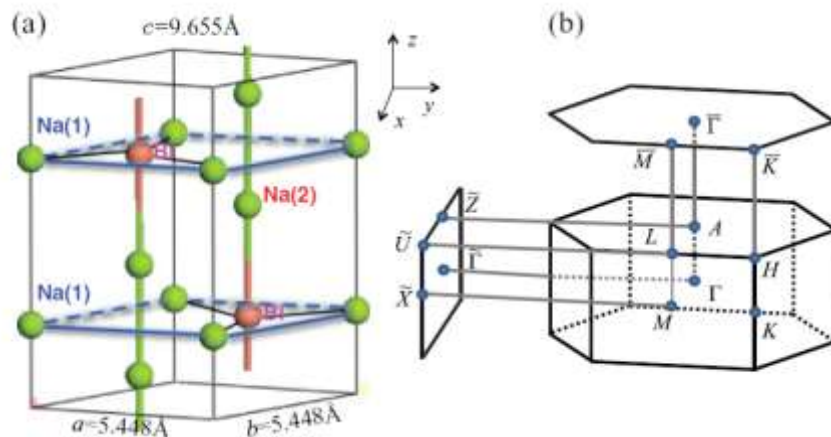
3D Topological Dirac Semi-metal (TDS)

Realize 3D TDS state through topological phase transition



A better candidate: Na_3Bi

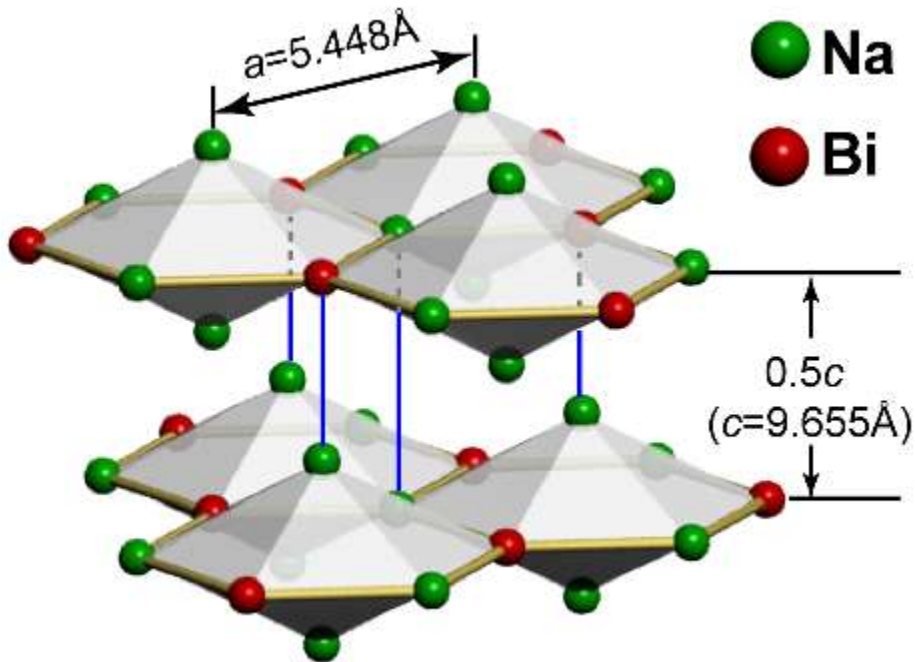
Phys. Rev. B **85**, 195320 (2012)



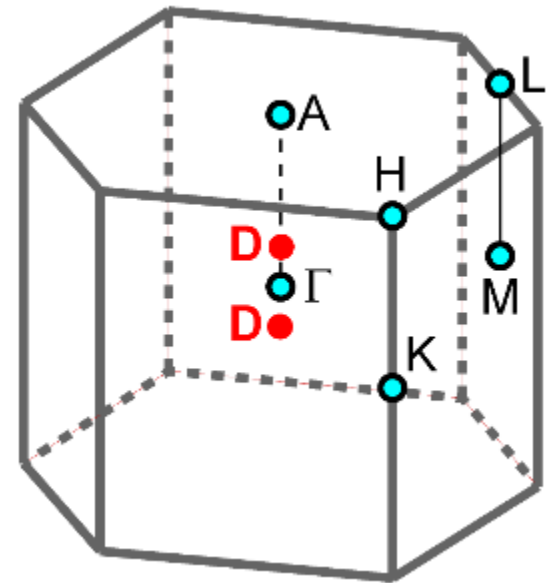
3D Topological Dirac Semi-metal (TDS)

Z. K. Liu. *et. al.*, Science, 343, 864 (2014)

Crystal structure



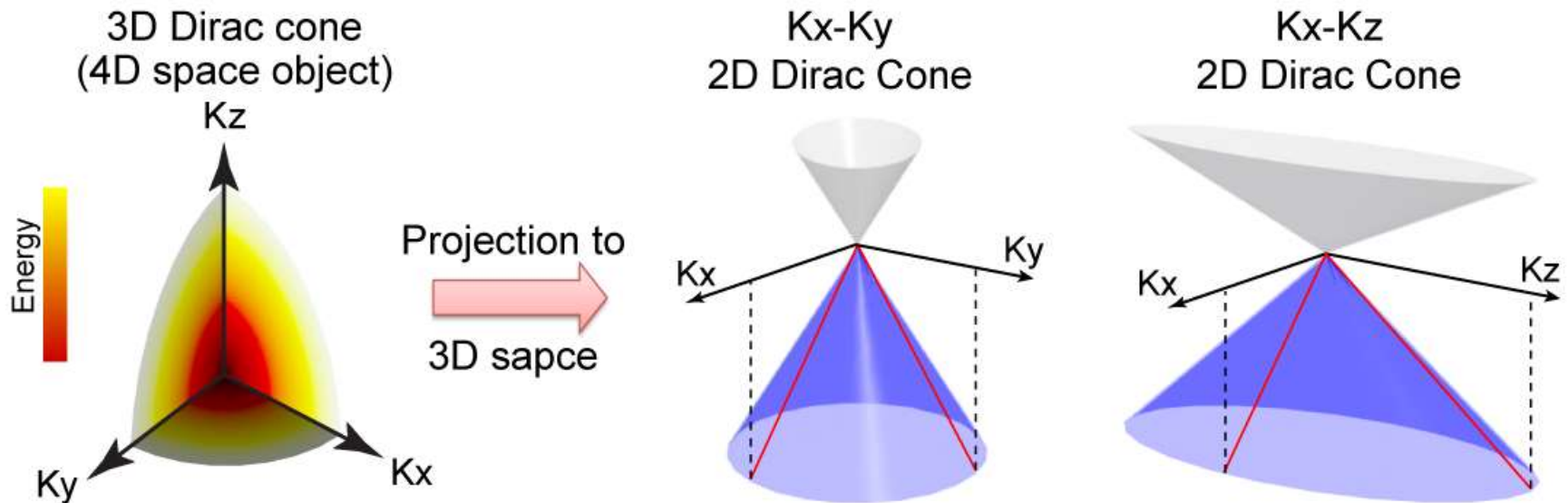
Brillouin Zone



How to identify a 3D TDS?

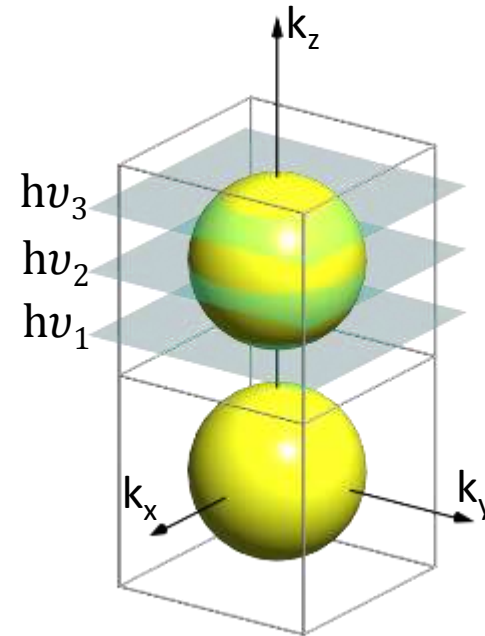
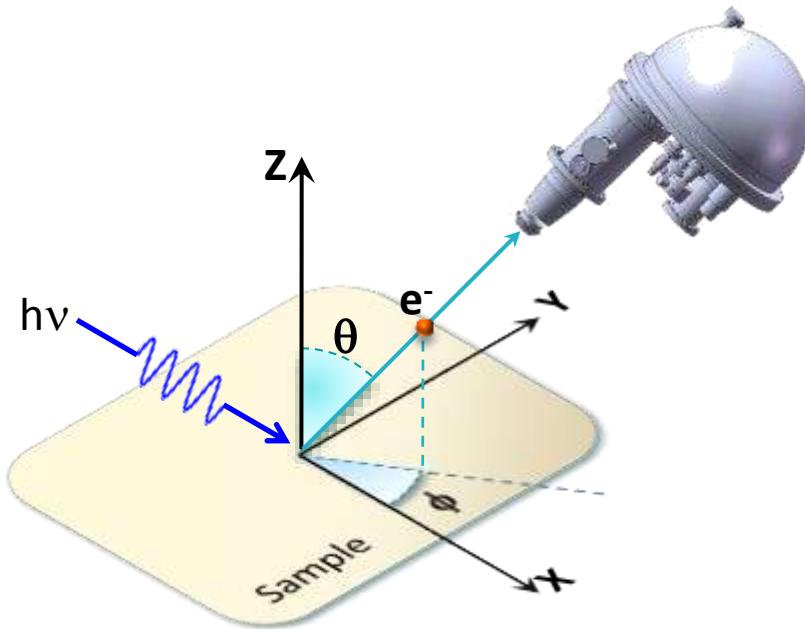
The 3D counterpart of graphene

Identify the band structure



How to determine k_z ?

Photon energy dependent ARPES measurement



$$E_k = h\nu - w - E_B$$

In vacuum:

$$k_x^V = \frac{\sqrt{2m_e E_k}}{\hbar} \sin(\theta) \cos(\Phi)$$

$$k_y^V = \frac{\sqrt{2m_e E_k}}{\hbar} \sin(\theta) \sin(\Phi)$$

$$k_z^V = \frac{\sqrt{2m_e E_k}}{\hbar} \cos(\theta)$$

In crystal:

$$k_x = \frac{\sqrt{2m_e E_k}}{\hbar} \sin(\theta) \cos(\Phi) = k_x^V$$

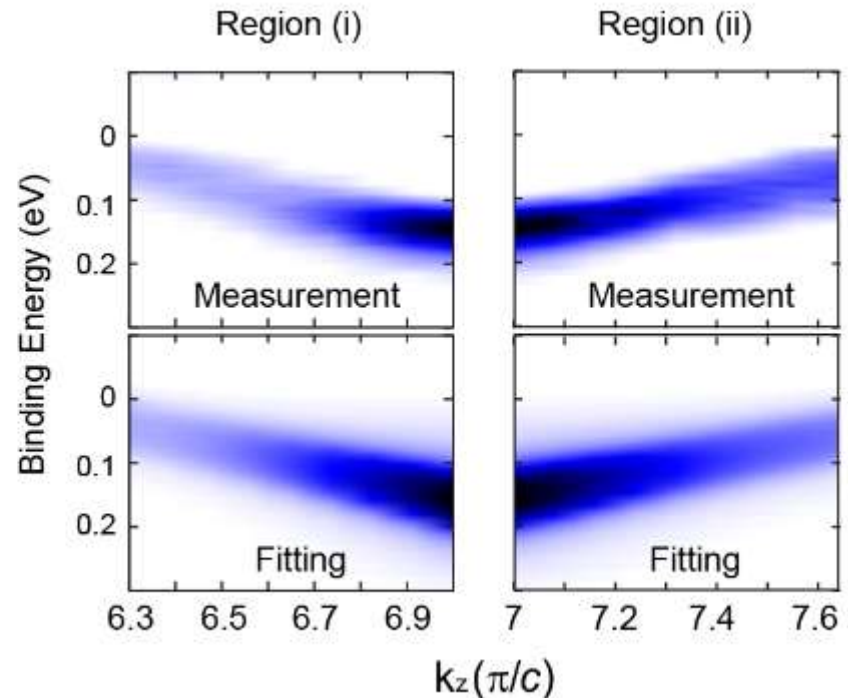
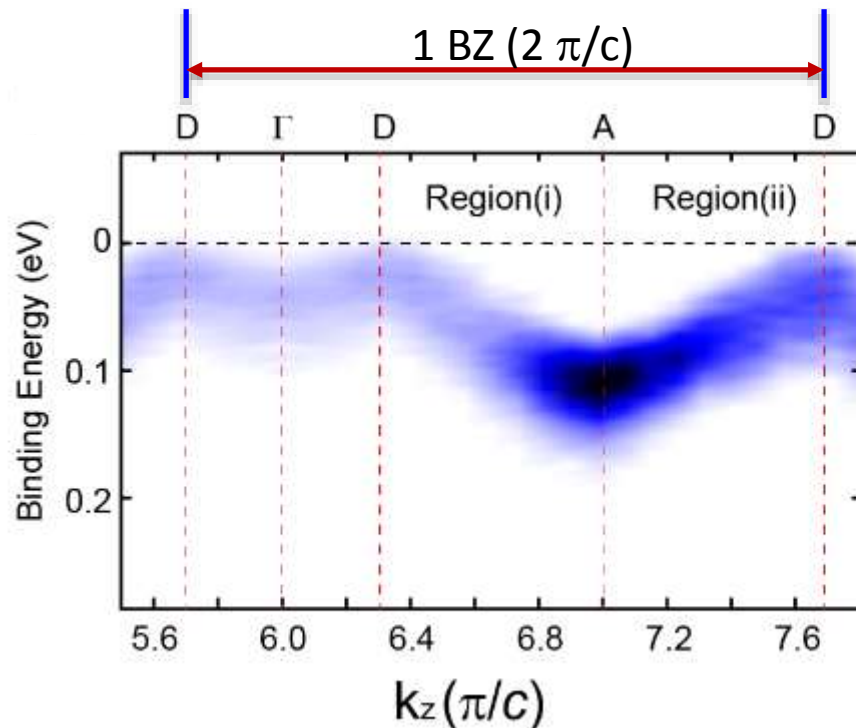
$$k_y = \frac{\sqrt{2m_e E_k}}{\hbar} \sin(\theta) \sin(\Phi) = k_y^V$$

$$k_z = \sqrt{\frac{2m_e^*}{\hbar^2} (E_k + V_0) - \frac{2m_e E_k}{\hbar^2} \sin^2 \theta} \neq k_z^V$$

Extracting k_z dispersions

$$I(k_z, E) \propto [|M_{f,i}^k|^2 \cdot A(k_z, E) \cdot f(E)] * R(\delta k_z, \delta E)$$

$$\delta k_z \approx 0.08 \text{ kBZ}$$



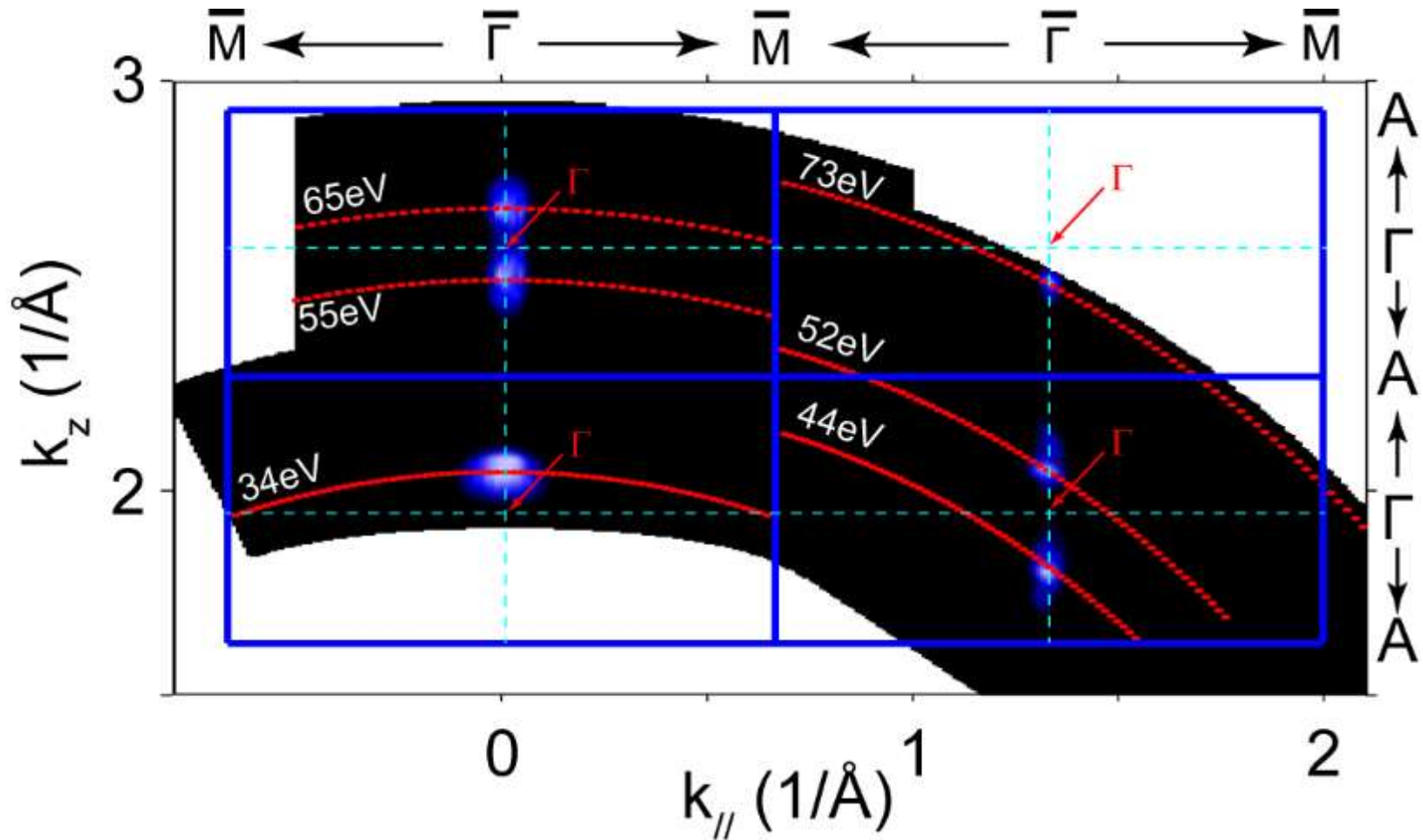
$|M_{f,i}^k|$: Photoemission matrix element
 $A(k, E)$ Spectrum function

$$f(E) = (e^{\frac{E}{k_B T}} + 1)^{-1}$$

$$R(\delta k, \delta E) = e^{\left\{ -\frac{1}{\sqrt{2}} \cdot \left(\left(\frac{K_z}{\delta K_z} \right)^2 + \left(\frac{E}{\delta E} \right)^2 \right) \right\}}$$

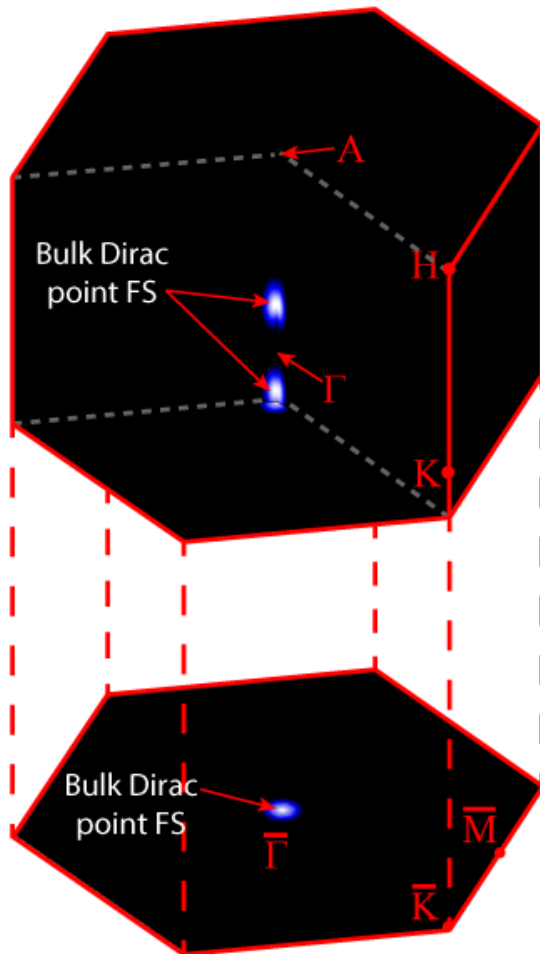
Extracting k_z dispersions

Multiple BZ mapping along k_z

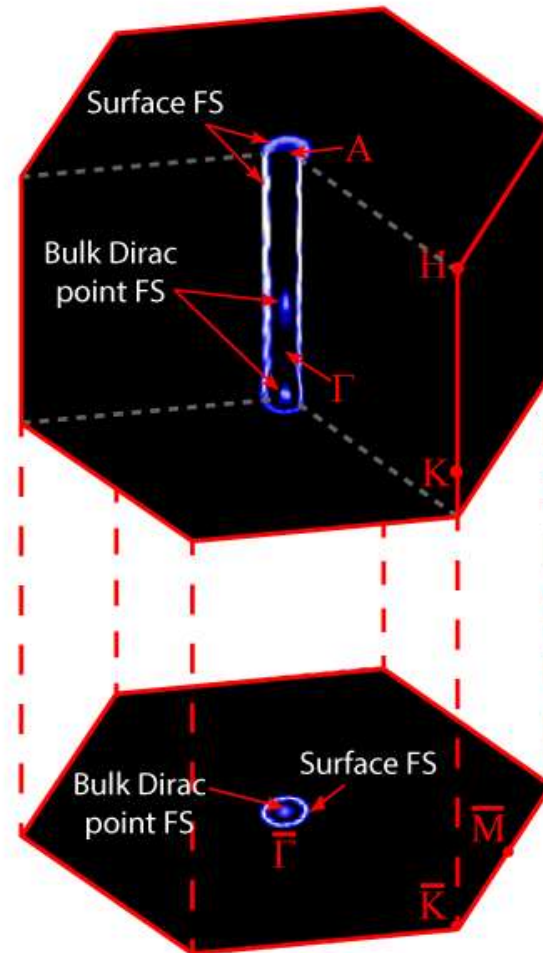


Complete 3D Fermi-surface mapping

Pristine surface

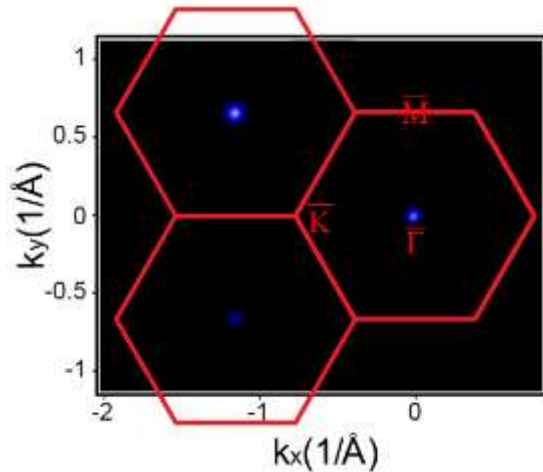


Surface with Na -vacancies



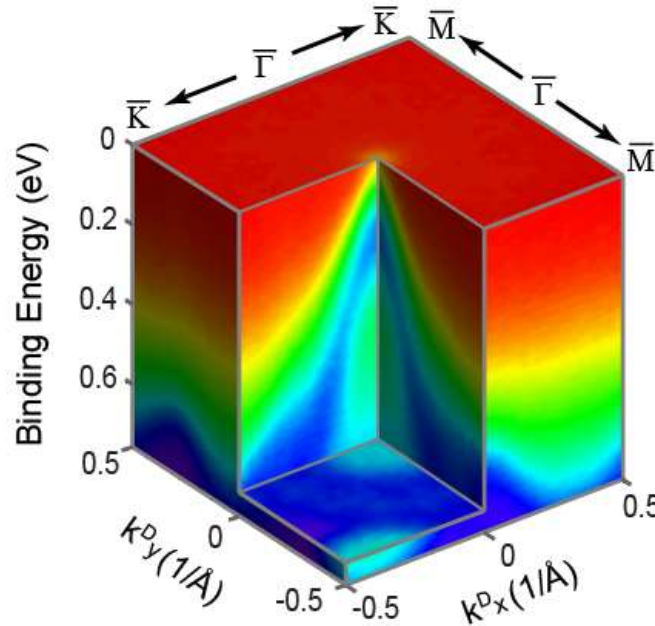
Projections to (k_x, k_y, E) space

Fermi-surface



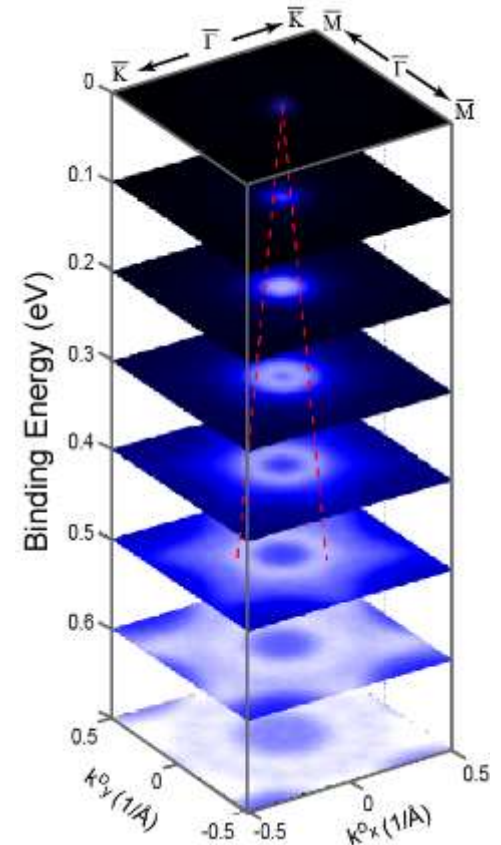
$$\begin{aligned} V_x &= 2.75 \text{ eV}\cdot\text{\AA} & \text{or} \\ V_y &= 2.39 \text{ eV}\cdot\text{\AA} & \text{or} \end{aligned}$$

Band dispersion



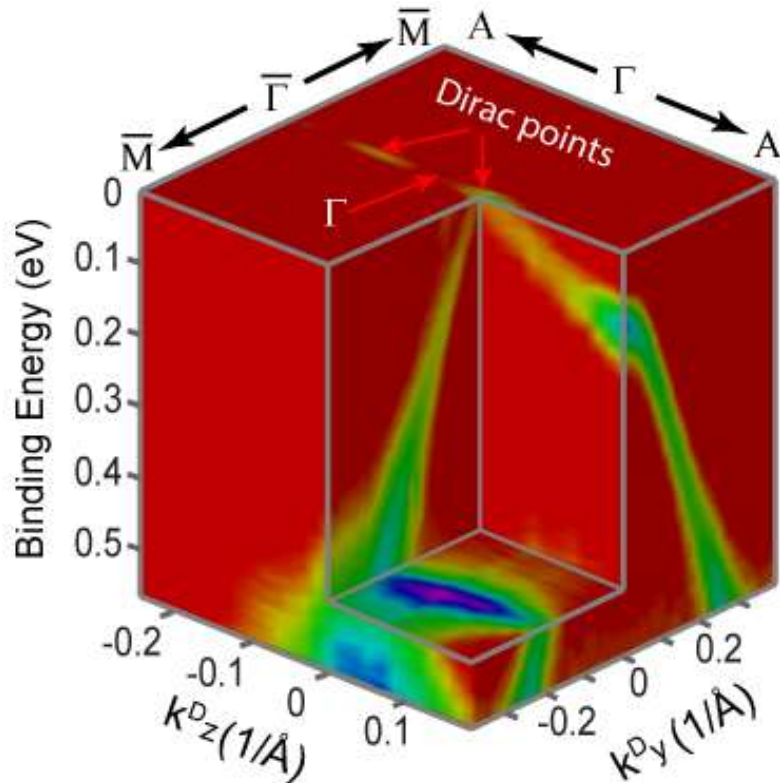
$$\begin{aligned} &4.17 \times 10^5 \text{ m/s} \\ &3.63 \times 10^5 \text{ m/s} \end{aligned}$$

Constant energy contours

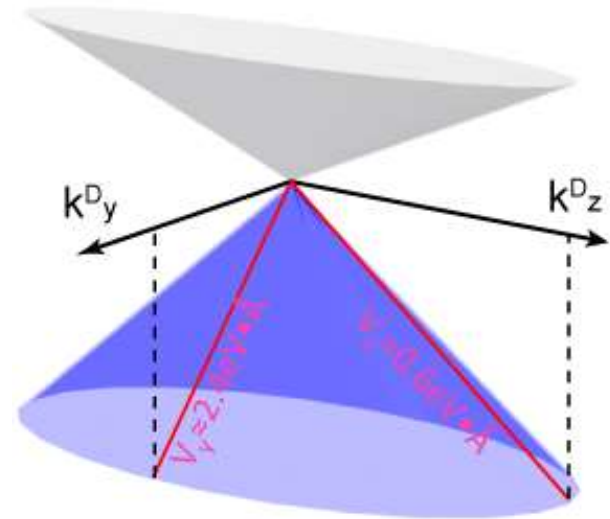


Projection to (k_y , k_z , E) space

Band dispersions



Strong anisotropy



$$V_x = 2.75 \text{ eV} \cdot \text{\AA} \quad \text{or}$$

$$4.17 \times 10^5 \text{ m/s}$$

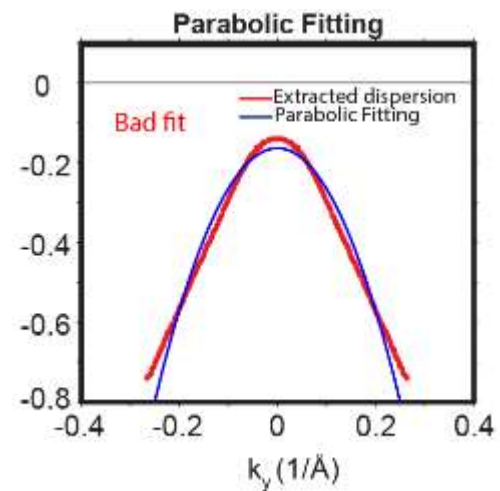
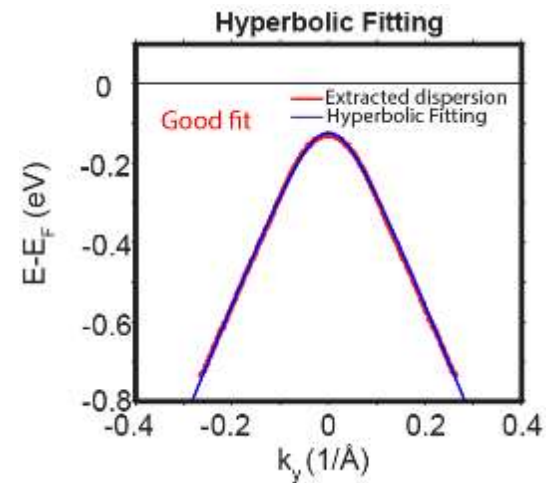
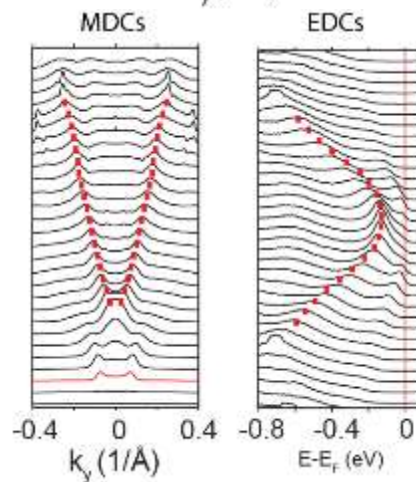
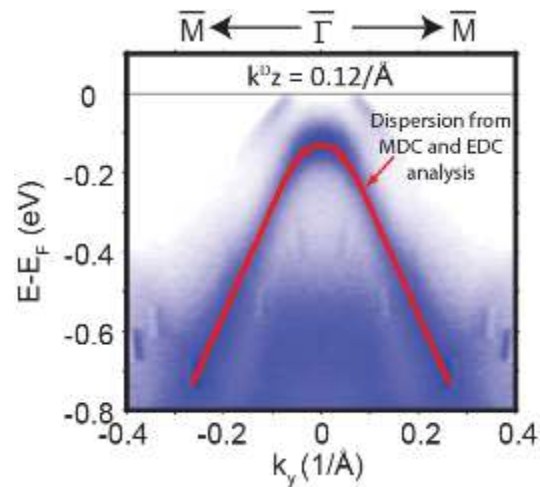
$$V_y = 2.39 \text{ eV} \cdot \text{\AA} \quad \text{or}$$

$$3.63 \times 10^5 \text{ m/s}$$

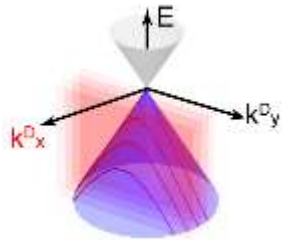
$$V_z = 0.6 \text{ eV} \cdot \text{\AA} \quad \text{or}$$

$$0.95 \times 10^5 \text{ m/s}$$

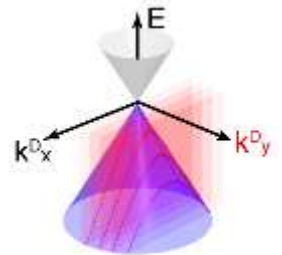
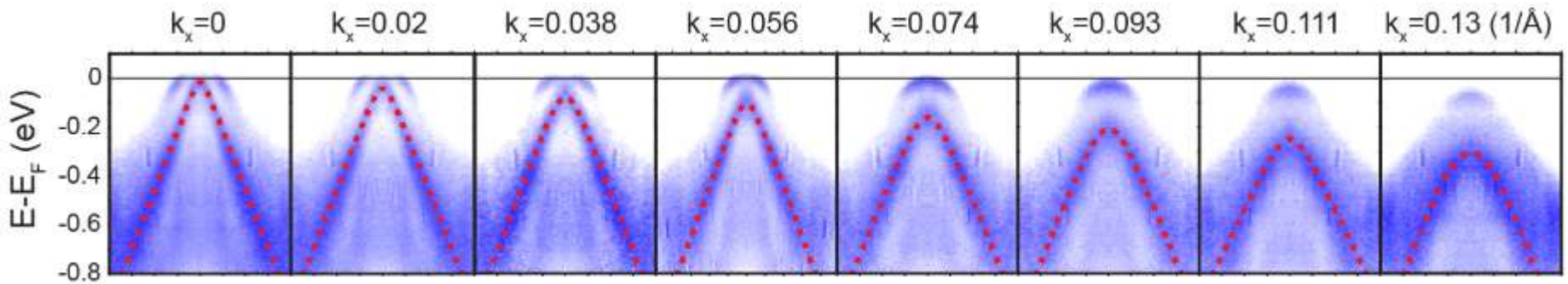
Unusual hyperbolic dispersion



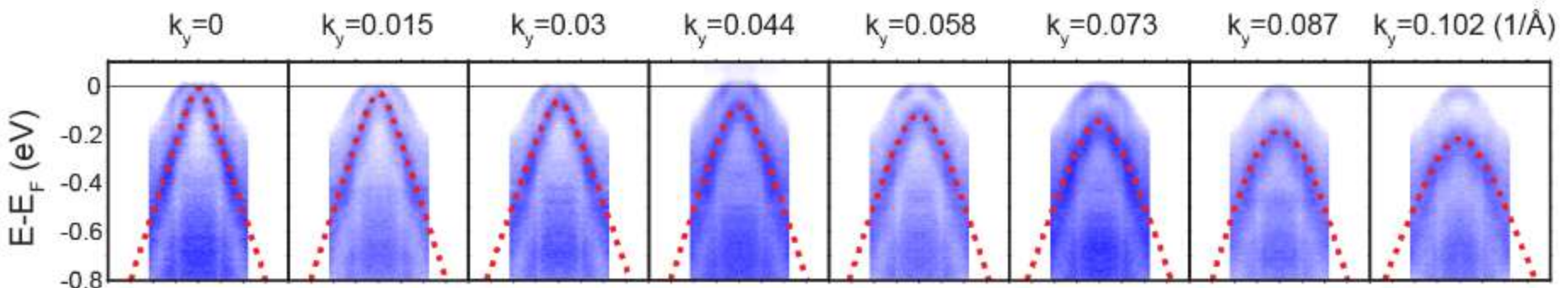
Dispersions at different k_x , k_y values



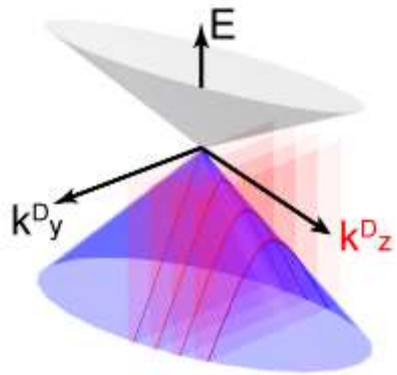
$$V_x = 2.75 \text{ eV}\cdot\text{\AA} \text{ or } 4.17 \times 10^5 \text{ m/s}$$



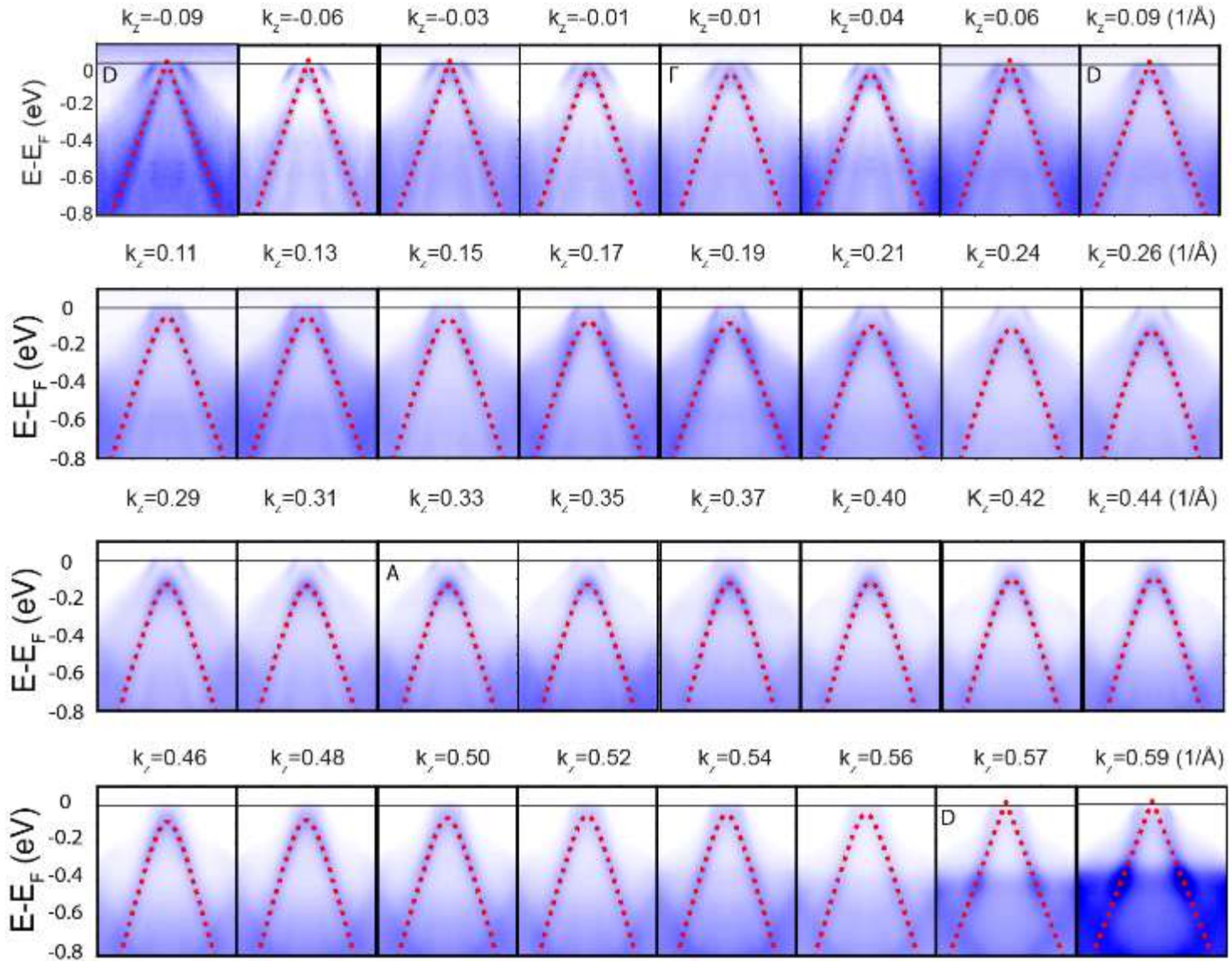
$$V_y = 2.39 \text{ eV}\cdot\text{\AA} \text{ or } 3.63 \times 10^5 \text{ m/s}$$



Dispersions at different k_z values

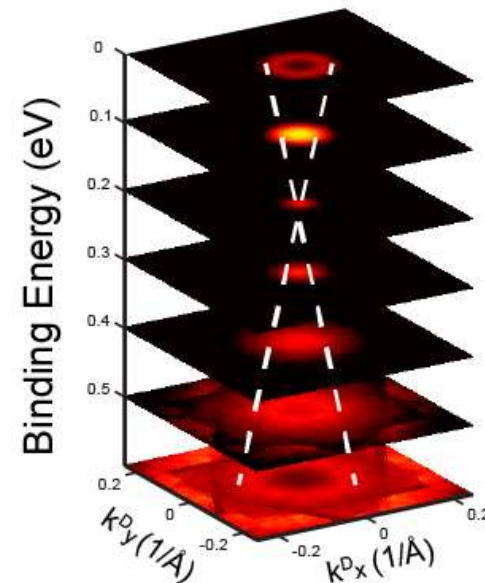
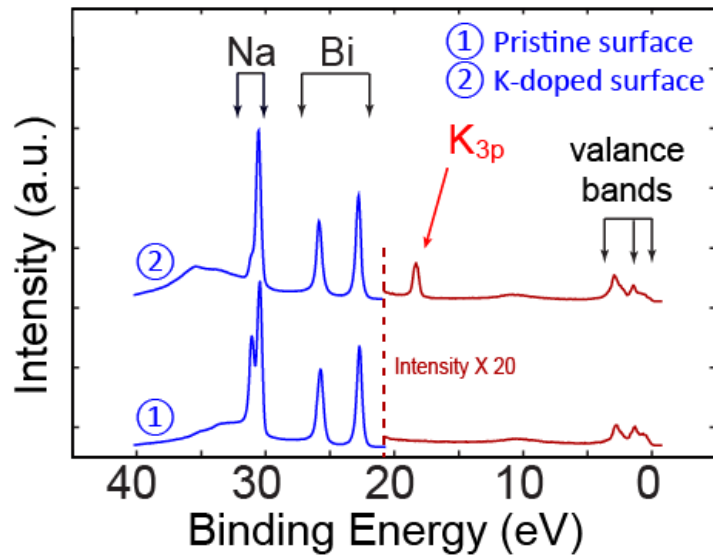
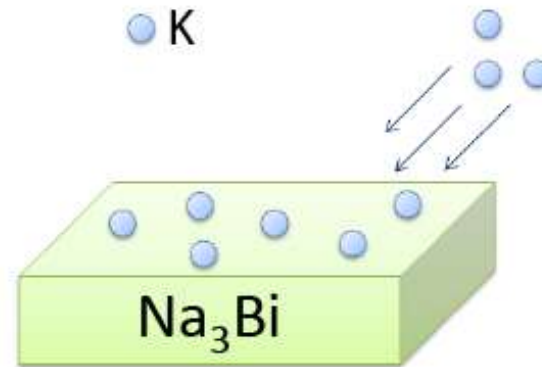


$V_z = 0.6 \text{ eV} \cdot \text{\AA}$
or $0.95 \times 10^5 \text{ m/s}$



Observing the Dirac point and upper cone

In-situ K-doping

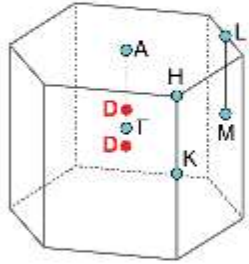


Protection of the crystalline symmetry

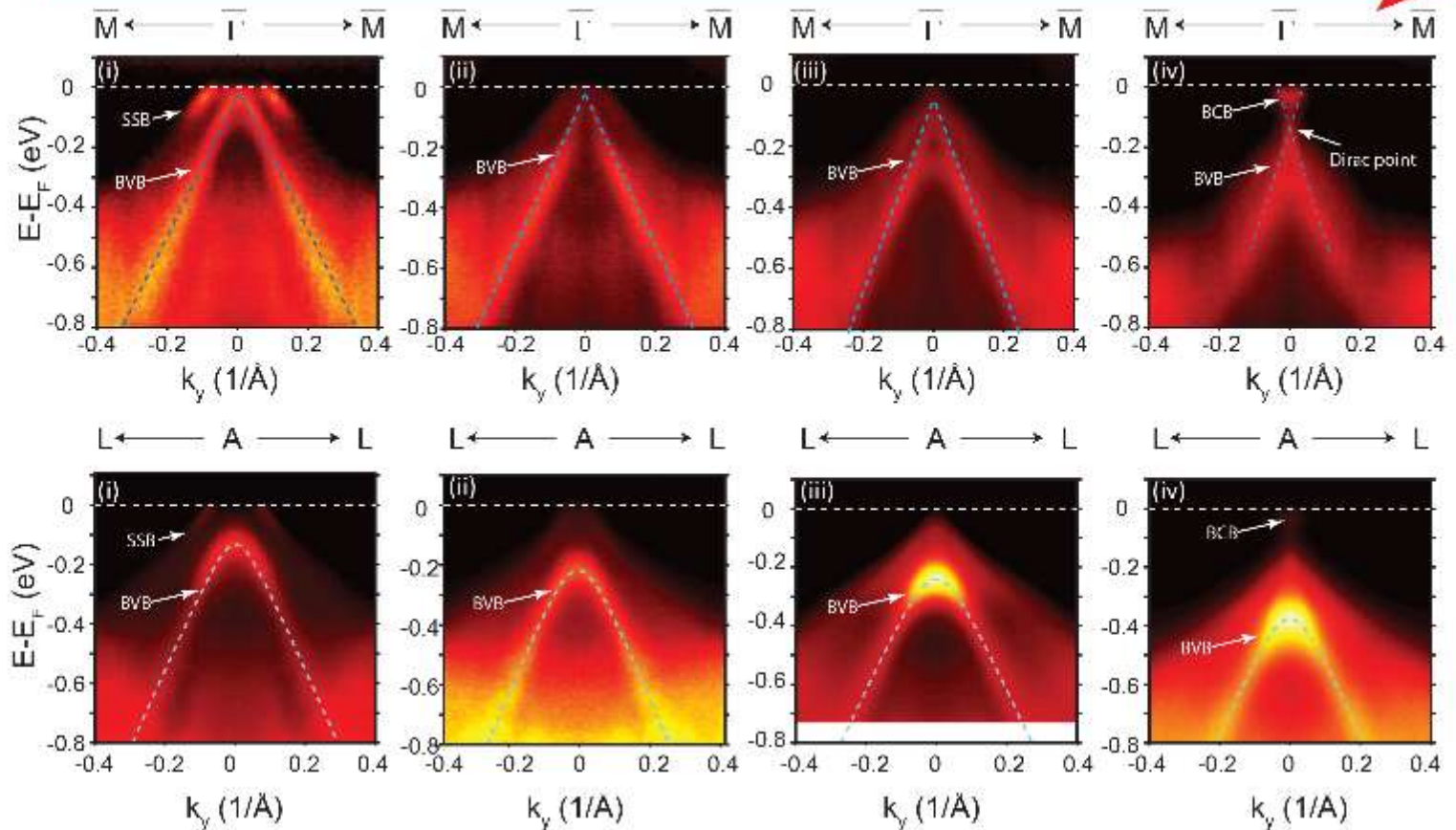
Disrupted surface state but intact bulk

Potassium Dosage

$k_z = -0.09/\text{\AA}$
(Cut across the
bulk Dirac point)

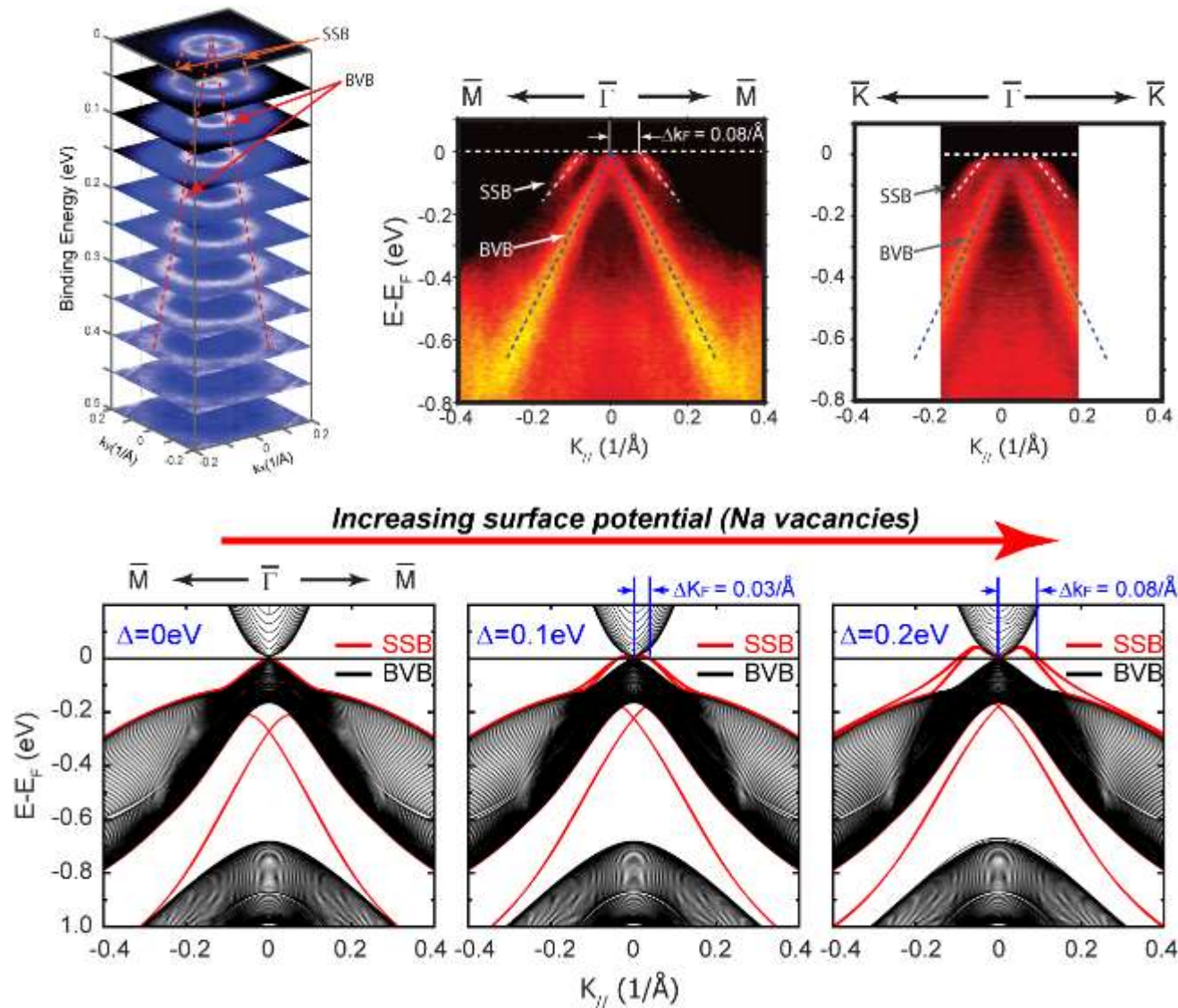


$k_z = 0.327/\text{\AA}$
(Cut across the "A"
point at the top
of the BZ)



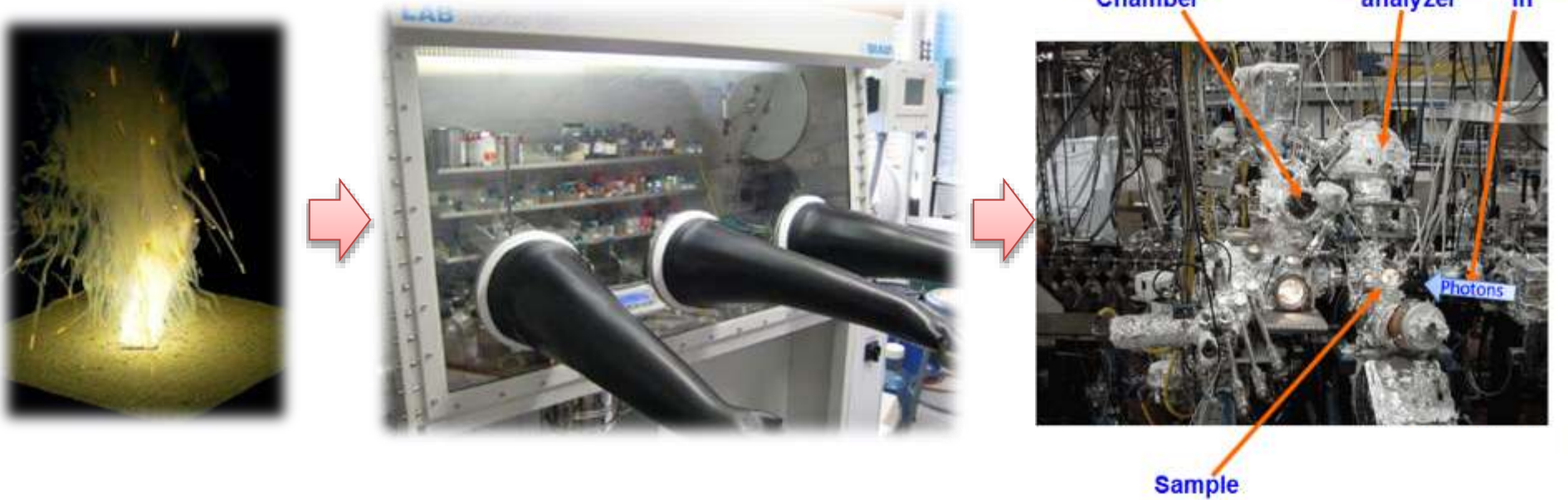
Emergence of the surface state

Results of the Na vacancies



The problem of Na_3Bi

Too reactive in ambient environment ...

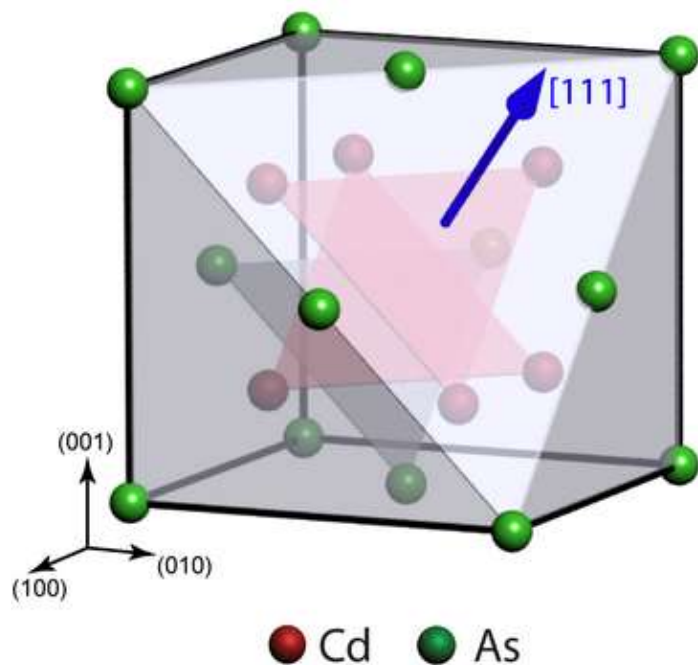


Hard to handle and used in functional devices

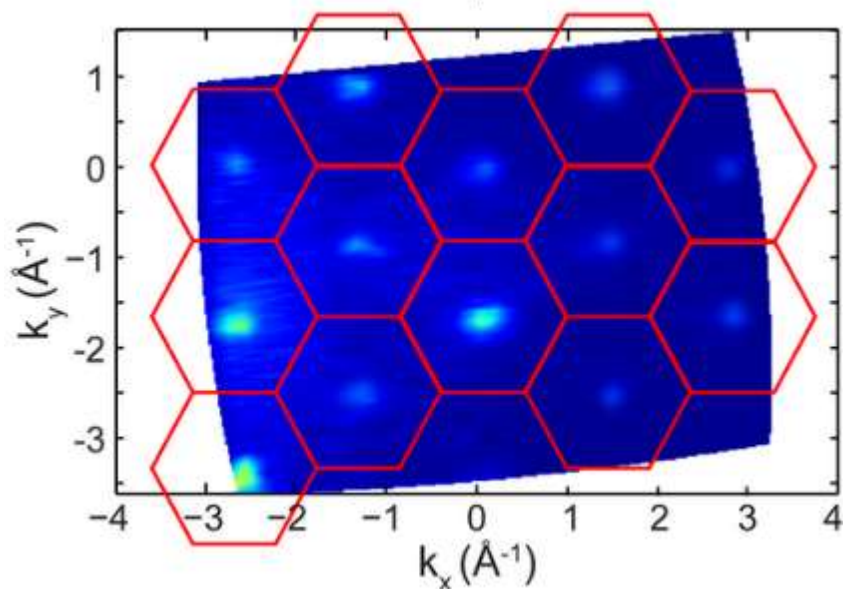
A stable 3D TDS, Cd_3As_2

Z. K. Liu. *et. al.*, Nature Materials, 13, 677 (2014)

Crystal structure



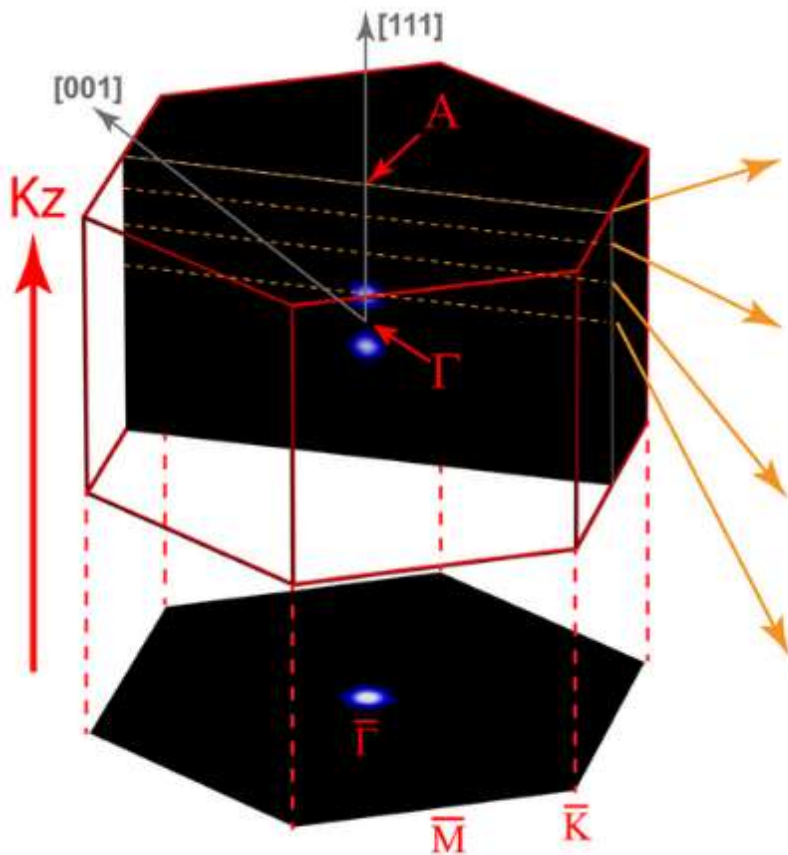
Brillouin Zone



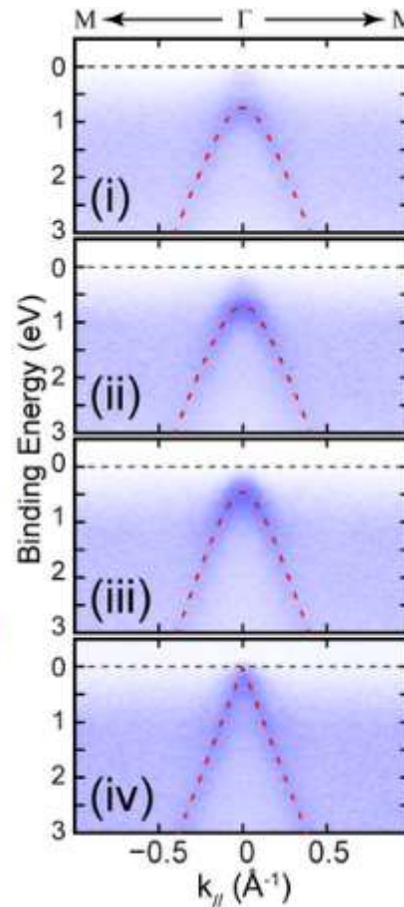
A stable 3D TDS, Cd_3As_2

Z. K. Liu. *et. al.*, Nature Materials, 13, 677 (2014)

3D Brillouin Zone

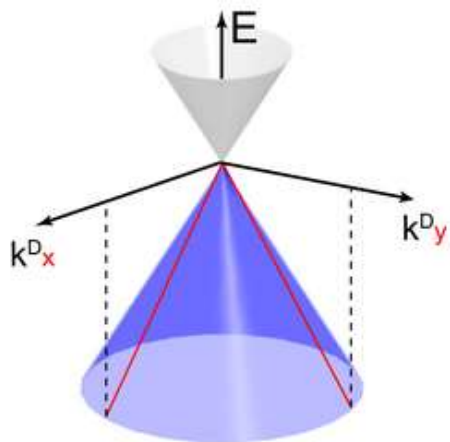
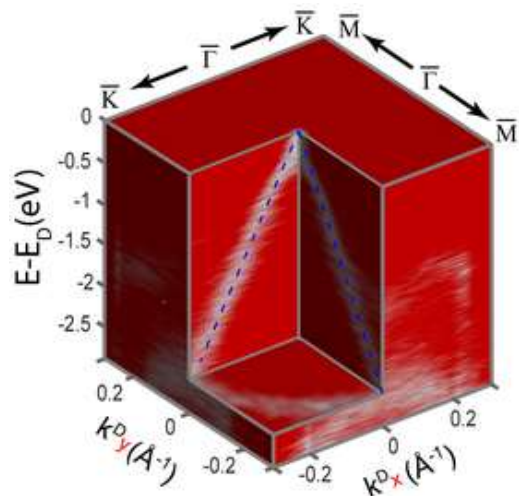


Dispersion at different k_z

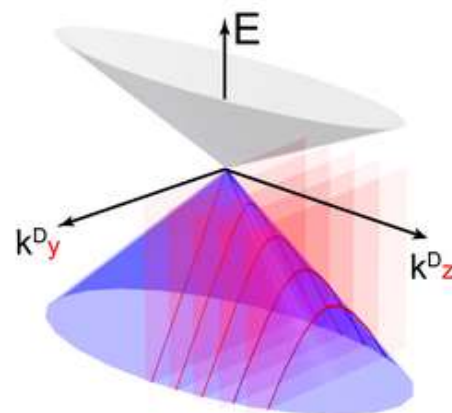
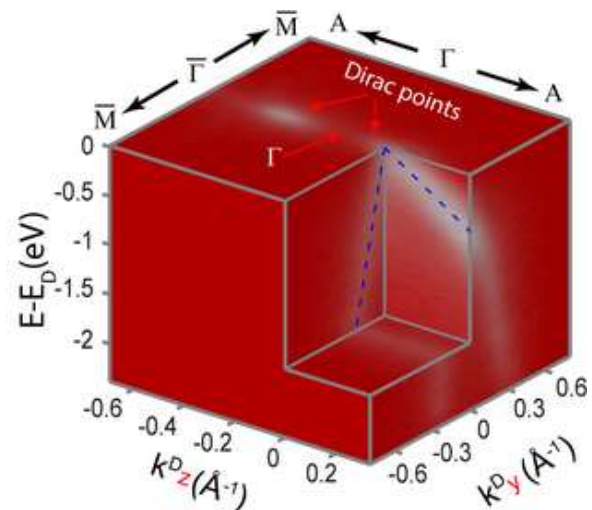


A stable 3D TDS, Cd_3As_2

Projection to (K_x, k_y, E)



Projection to (K_y, k_z, E)



Can we find other topological matter?

Topologically **trivial** world



Topologically **non-trivial** world



What's next?